

## **Total Dose Radiation Test Report**

### **MSK5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

November 25, 2008 (MSK5810RH – 1<sup>st</sup> Test)  
Updated on December 24, 2008  
March 21, 2009 (MSK5822RH – 1<sup>st</sup> Test)  
March 26, 2009 (MSK5810RH – 2<sup>nd</sup> Test)  
September 3, 2009 (MSK5810RH – 3<sup>rd</sup> Test)  
November 6, 2009 (MSK5810RH – 4<sup>th</sup> Test)  
May 14, 2010 (MSK5810RH – 5<sup>th</sup> Test)  
September 17, 2010 (MSK5810RH – 6<sup>th</sup> Test)  
December 10, 2010 (MSK5810RH – 7<sup>th</sup> Test)  
April 1, 2011 (MSK5810RH – 8<sup>th</sup> Test)  
July 8, 2011 (MSK5810RH – 9<sup>th</sup> Test)  
June 14, 2013 (MSK5810RH – 10<sup>th</sup> Test, IC Wafer Lot: WD0051441#9  
Transistor Wafer Lot: CJ302831#13)  
June 14, 2013 (MSK5810RH – 11<sup>th</sup> Test, IC Wafer Lot: WD0051441#9  
Transistor Wafer Lot: CJ302831#21)  
November 6, 2013 (MSK5810RH – 12<sup>th</sup> Test, IC Wafer Lot: W10809524.1 #8  
Transistor Wafer Lot: CJ302831RC#20)  
August 28, 2015 (MSK5810RH – 13<sup>th</sup> Test, IC Wafer Lot: WP005144.1  
Transistor Wafer Lot: P741F1002 #21)  
November 8, 2016 (MSK5810RH – 14<sup>th</sup> Test, IC Wafer Lot: WP005144.1 #9  
Transistor Wafer Lot: PF01F1005 #6)  
March 29, 2017 (MSK5810RH – 15<sup>th</sup> Test, IC Wafer Lot: WP005144.1 #8  
Transistor Wafer Lot: PF01F1005 #6)  
September 15, 2017 (MSK5810RH – 16<sup>th</sup> Test, IC Wafer Lot: W10809524.1 #8  
Transistor Wafer Lot: DL153631 #3)  
January 12, 2018 (MSK5810RH – 17<sup>th</sup> Test, IC Wafer Lot: WP005144.1 #8  
Transistor Wafer Lot: P741F1002 #21)  
August 22, 2018 (MSK5810RH – 18<sup>th</sup> Test, IC Wafer Lot: WP005144.1 #8  
Transistor Wafer Lot: PG31F100K Wf#17)

N. Kresse  
J. Joy

Anaren, Inc. – MSK Products

## **I. Introduction:**

The total dose radiation test plan for the MSK5810RH series was developed to qualify the devices as Radiation Hardened to 300 Krad(Si). The testing was performed beyond 300 Krad(Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a Cobalt 60 radiation source. The dose rate was determined to be 117.4 Rad(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 160 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation, the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as one control device, at each total dose level. All electrical tests were completed within one hour of irradiation. Each subsequent dose was performed within two hours of the previous irradiation.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting Anaren Inc. – MSK Products.

## **V. Summary:**

Based on the test data recorded during radiation testing and statistical analysis, Feedback Voltage, Shutdown Threshold, Shutdown Hysteresis and Output Current Limit exhibited shift due to irradiation, however all performance curves stayed within specification beyond 300 Krad(Si) TID.

MSK5810RH Biased/Unbiased Dose Rate Schedule
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Dosimetry Equipment
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Bruker Biospin # 0162
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Irradiation Date
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8/22/18
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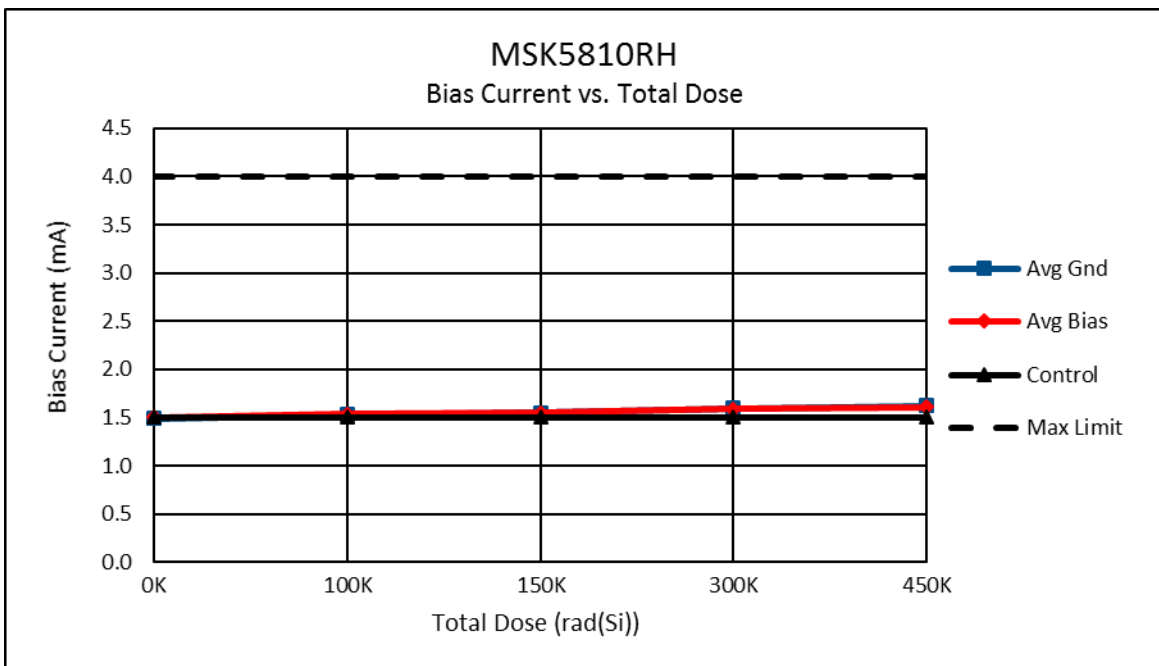
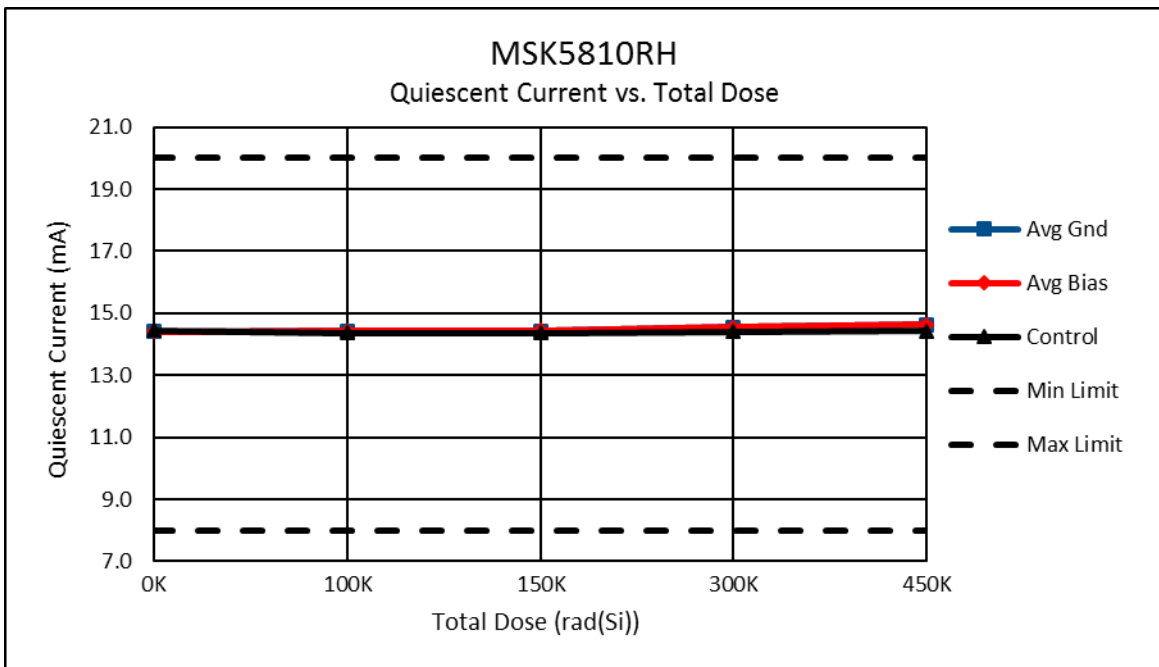
Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
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7:19	51,500	154,500
21:56	154,500	309,000
21:56	154,500	463,500

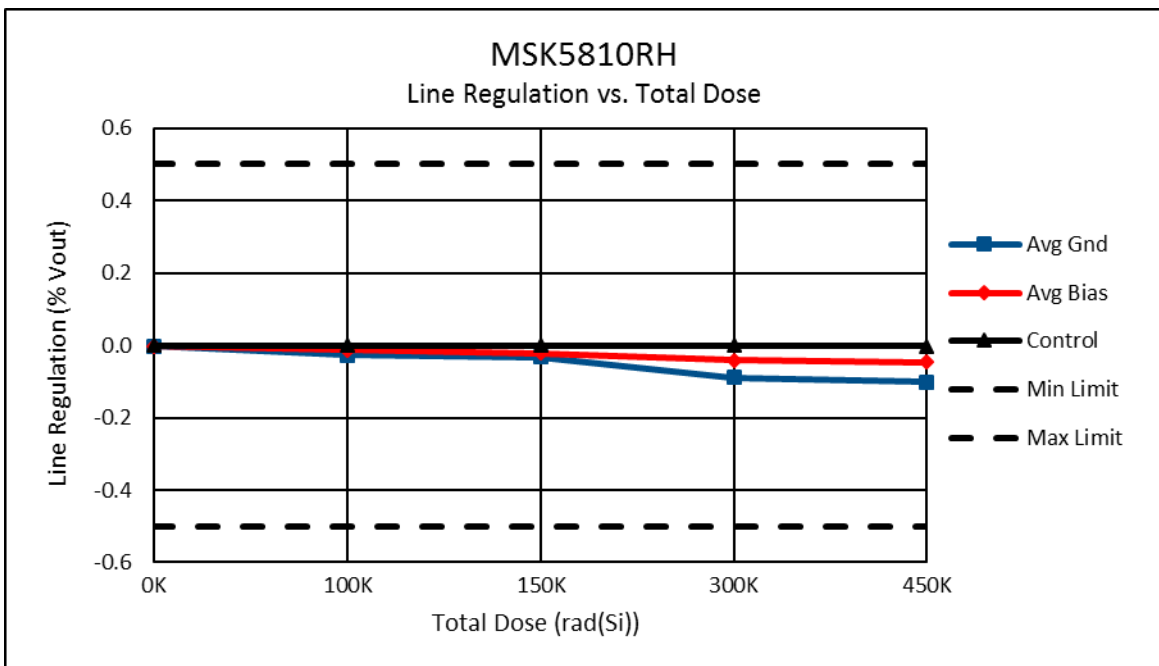
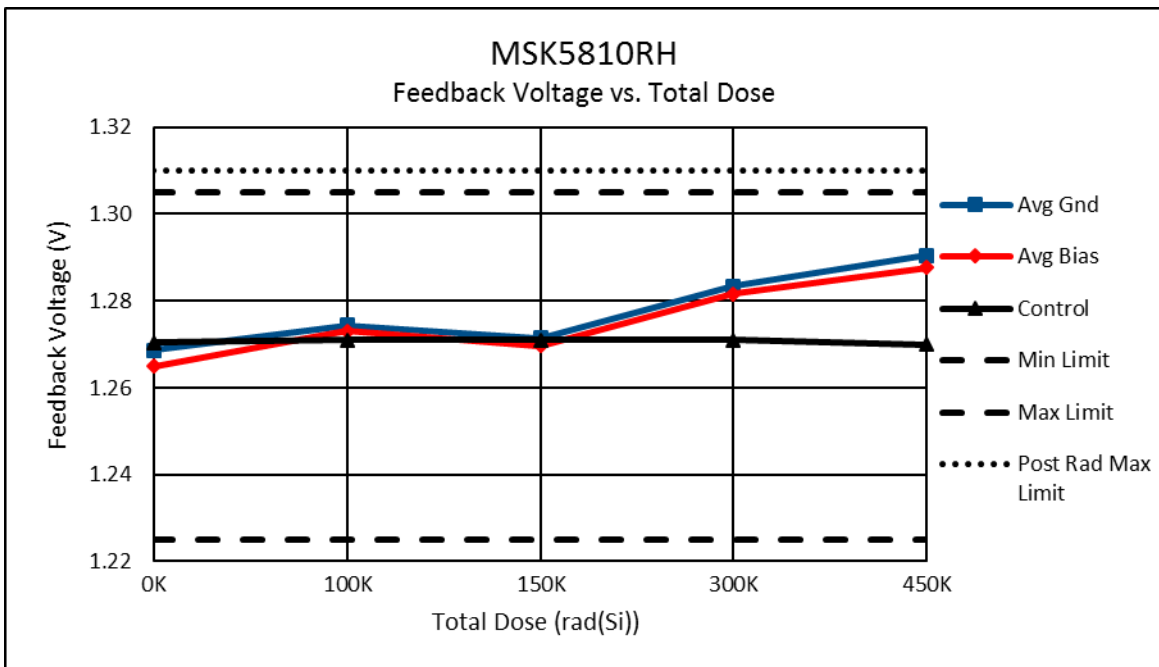
Biased S/N – 0027, 0028, 0029, 0030, 0031
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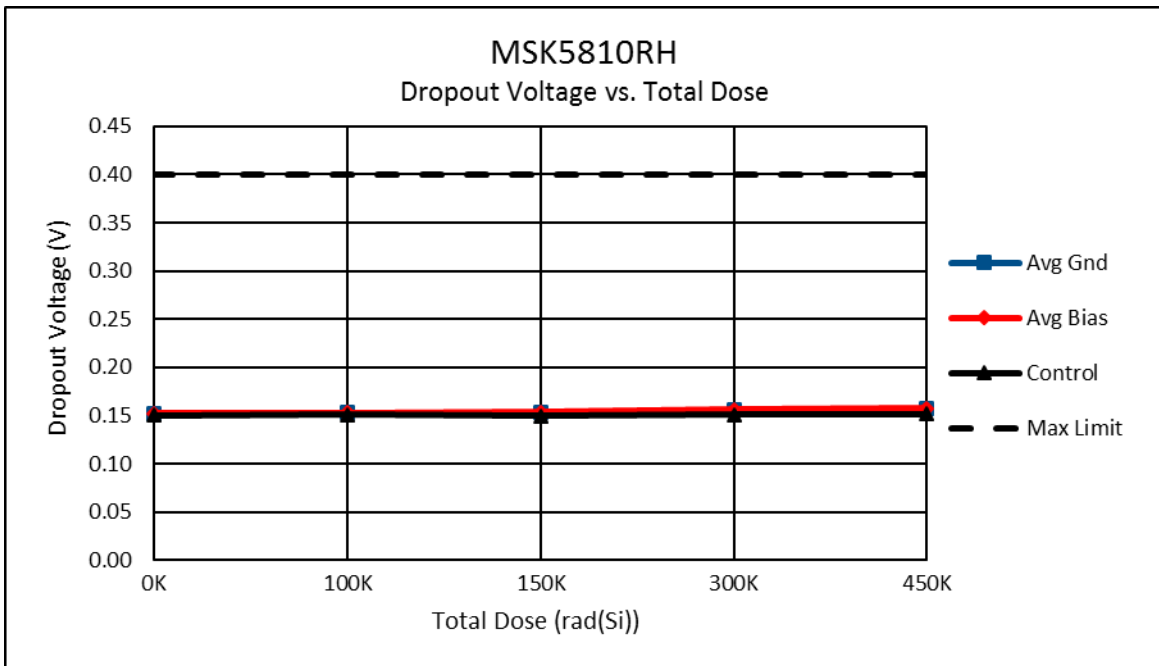
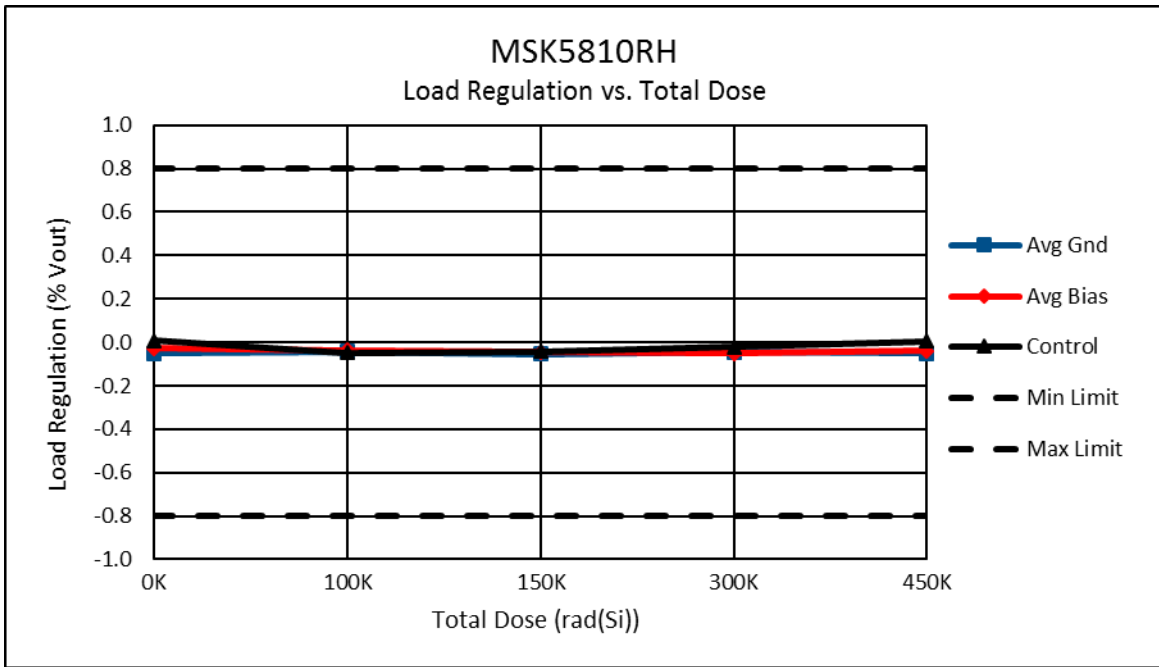
Unbiased S/N – 0032, 0033, 0034, 0035, 0036
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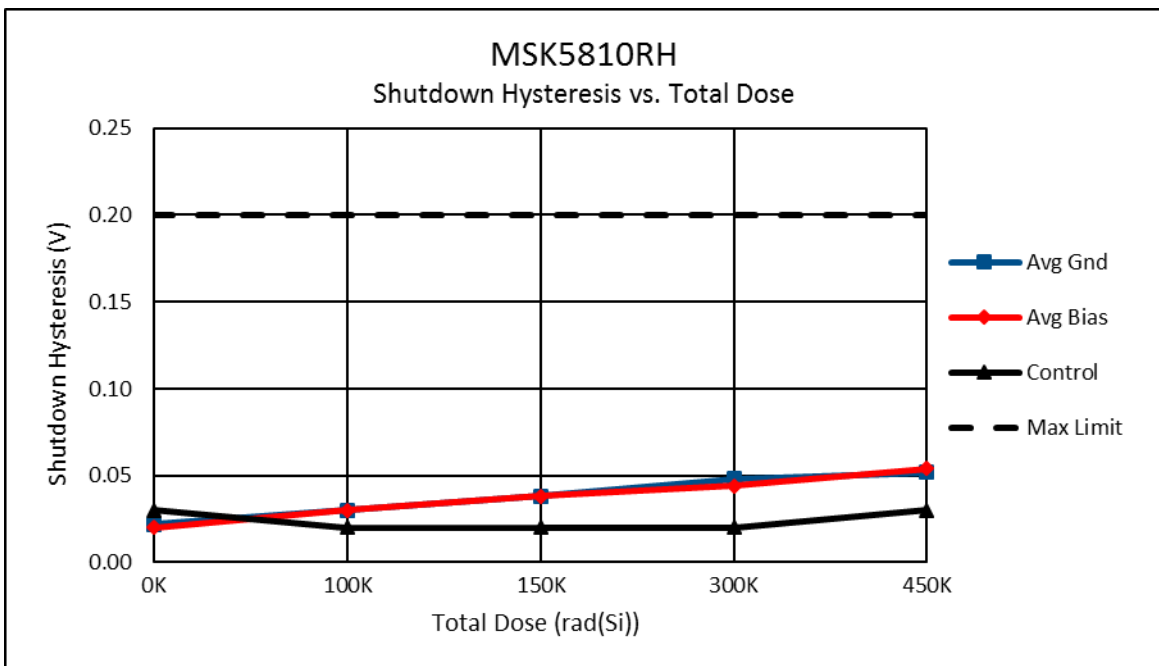
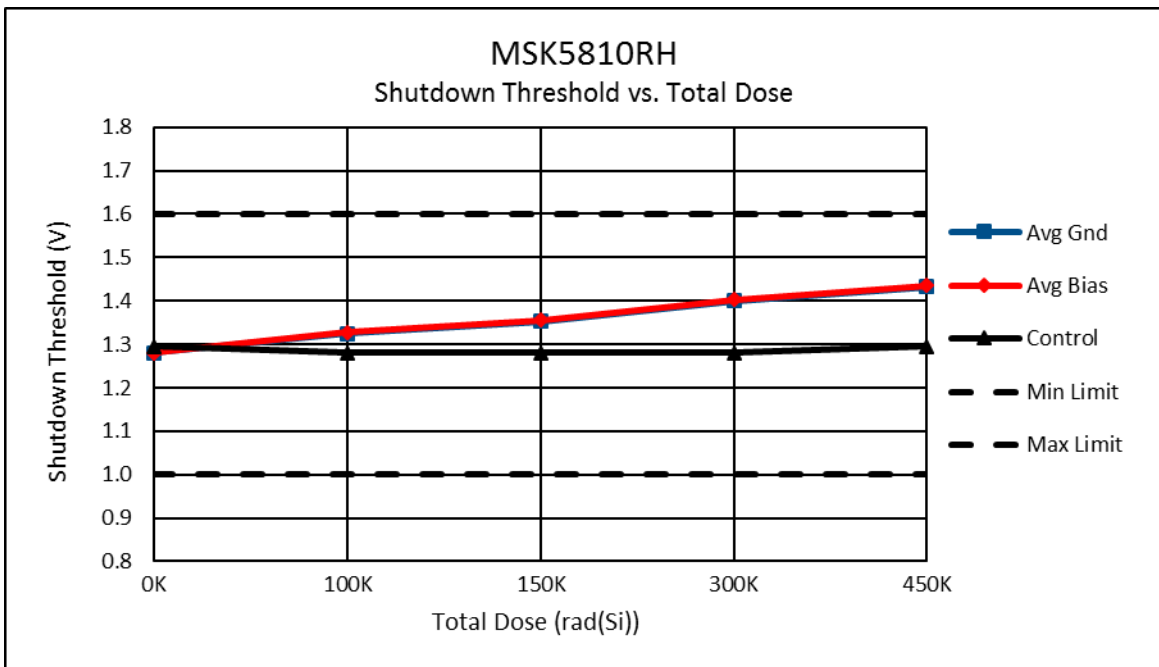
Table 1

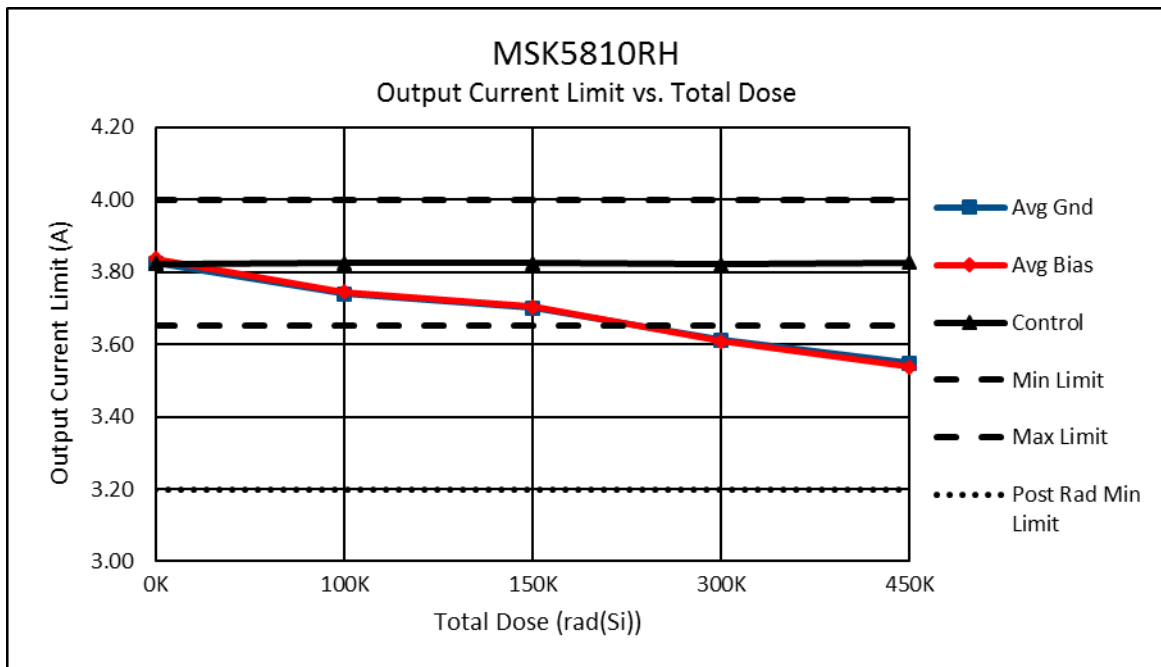
**Dose Time, Incremental Dose and Total Cumulative Dose**













## **Total Dose Radiation Test Report**

### **MSK 5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

November 25, 2008 (MSK 5810RH – 1<sup>st</sup> Test)  
Updated on December 24, 2008  
March 21, 2009 (MSK 5822RH – 1<sup>st</sup> Test)  
March 26, 2009 (MSK 5810RH – 2<sup>nd</sup> Test)  
September 3, 2009 (MSK 5810RH – 3<sup>rd</sup> Test)  
November 6, 2009 (MSK 5810RH – 4<sup>th</sup> Test)  
May 14, 2010 (MSK 5810RH – 5<sup>th</sup> Test)  
September 17, 2010 (MSK 5810RH – 6<sup>th</sup> Test)  
December 10, 2010 (MSK 5810RH – 7<sup>th</sup> Test)  
April 1, 2011 (MSK5810RH – 8<sup>th</sup> Test)  
July 8, 2011 (MSK5810RH – 9<sup>th</sup> Test)  
June 14, 2013 (MSK5810RH – 10<sup>th</sup> Test, IC Wafer Lot: WD0051441#9  
Transistor Wafer Lot: CJ302831#13)  
June 14, 2013 (MSK5810RH – 11<sup>th</sup> Test, IC Wafer Lot: WD0051441#9  
Transistor Wafer Lot: CJ302831#21)  
November 6, 2013 (MSK5810RH – 12<sup>th</sup> Test, IC Wafer Lot: W10809524.1 #8  
Transistor Wafer Lot: CJ302831RC#20)  
August 28, 2015 (MSK5810RH – 13<sup>th</sup> Test, IC Wafer Lot: WP005144.1  
Transistor Wafer Lot: P741F1002 #21)  
November 8, 2016 (MSK5810RH – 14<sup>th</sup> Test, IC Wafer Lot: WP005144.1 #9  
Transistor Wafer Lot: PF01F1005 #6)  
March 29, 2017 (MSK5810RH – 15<sup>th</sup> Test, IC Wafer Lot: WP005144.1 #8  
Transistor Wafer Lot: PF01F1005 #6)  
September 15, 2017 (MSK5810RH – 16<sup>th</sup> Test, IC Wafer Lot: W10809524.1 #8  
Transistor Wafer Lot: DL153631 #3)  
January 12, 2018 (MSK5810RH – 17<sup>th</sup> Test, IC Wafer Lot: WP005144.1 #8  
Transistor Wafer Lot: P741F1002 #21)

B. Horton  
N. Kresse  
J. Joy

Anaren, Inc. – MSK Products

## **I. Introduction:**

The total dose radiation test plan for the MSK5810RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a Cobalt 60 radiation source. The dose rate was determined to be 126.7 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 160 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, two control devices were tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation, the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as two control devices, at each total dose level. The time to complete electrical tests exceeded 1 hour at the 100krad(Si) and 150krad(Si) dose levels due to test equipment malfunctions. Electrical tests were completed within one hour of irradiation at 300krad(Si) and 450krad(Si). Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field at all test points.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting Anaren Inc. – MSK Products.

## **V. Summary:**

Based on the test data recorded during radiation testing and statistical analysis, Feedback Voltage, Shutdown Threshold, Shutdown Hysteresis and Output Current Limit exhibited shift due to irradiation, however all performance curves stayed within specification beyond 300 Krad(Si) TID.

MSK5810RH Biased/Unbiased Dose Rate Schedule
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Dosimetry Equipment
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Bruker Biospin # 0162
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Irradiation Date
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1-12-17
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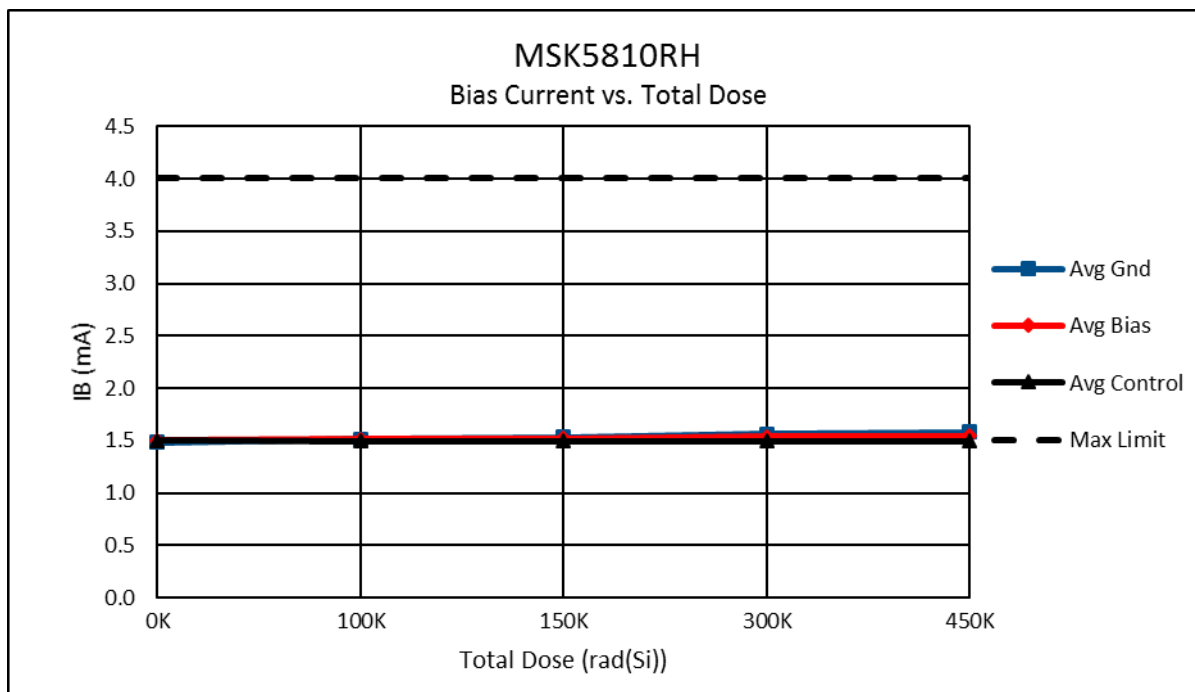
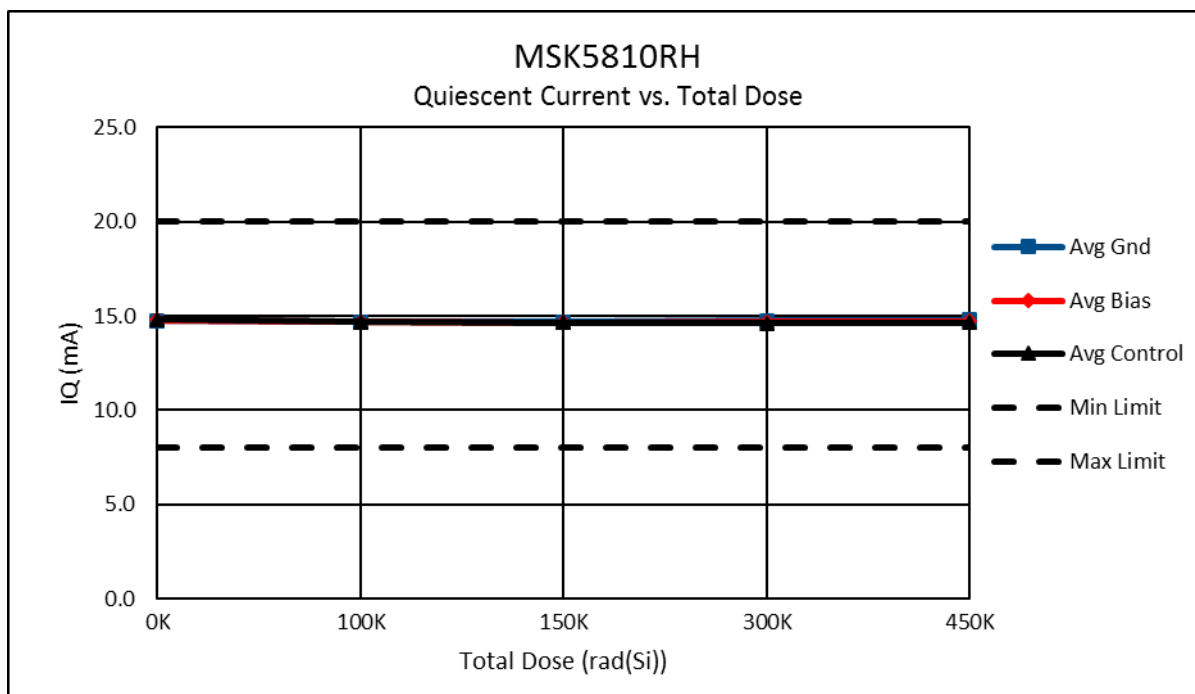
Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
13:33	103,00	103,000
6:46	51,500	154,500
20:19	154,500	309,000
20:19	154,500	463,500

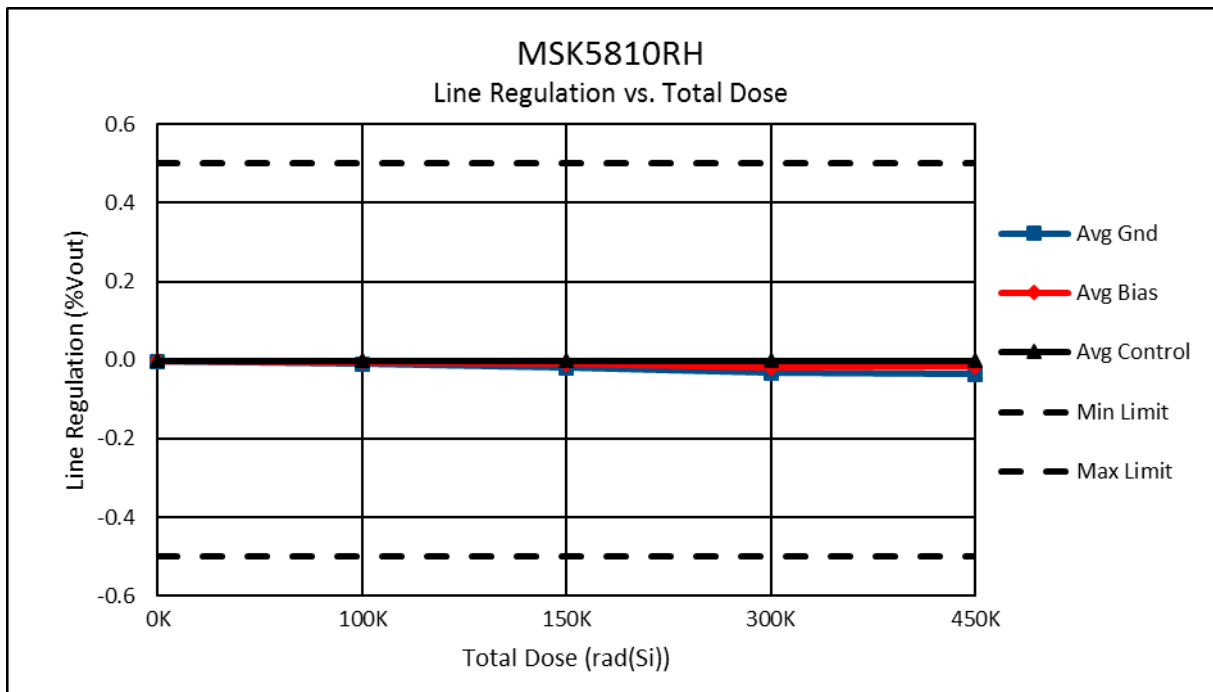
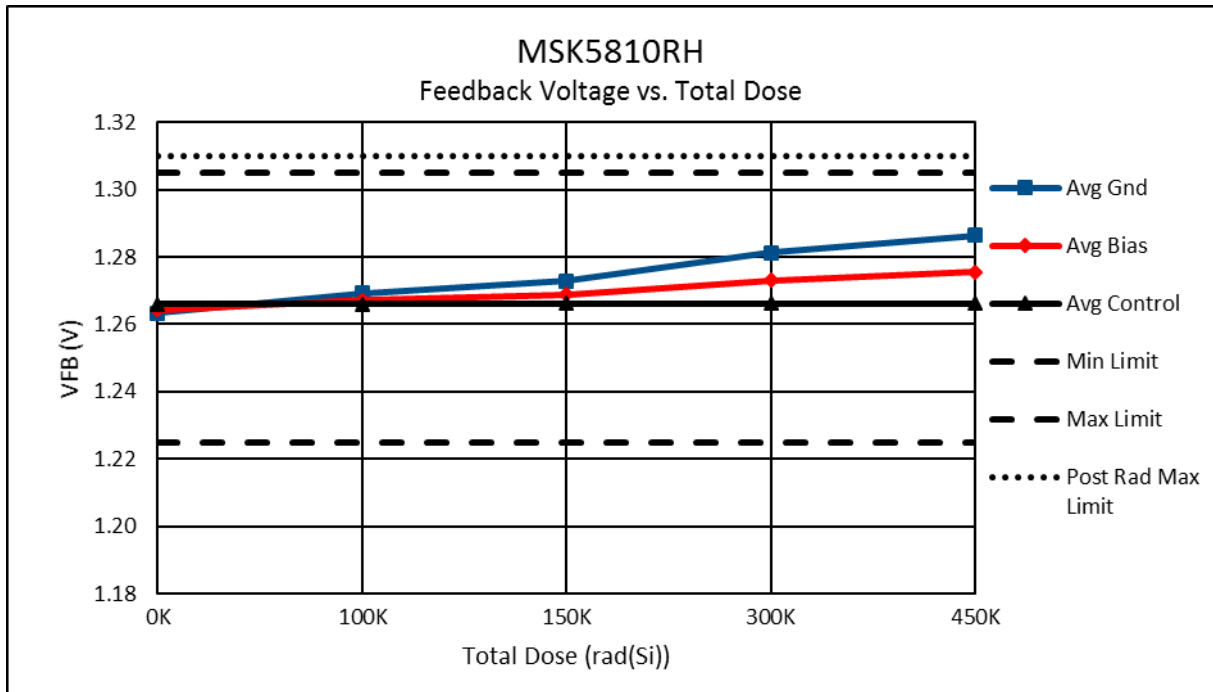
Biased S/N – 0020, 0021, 0022, 0023, 0024
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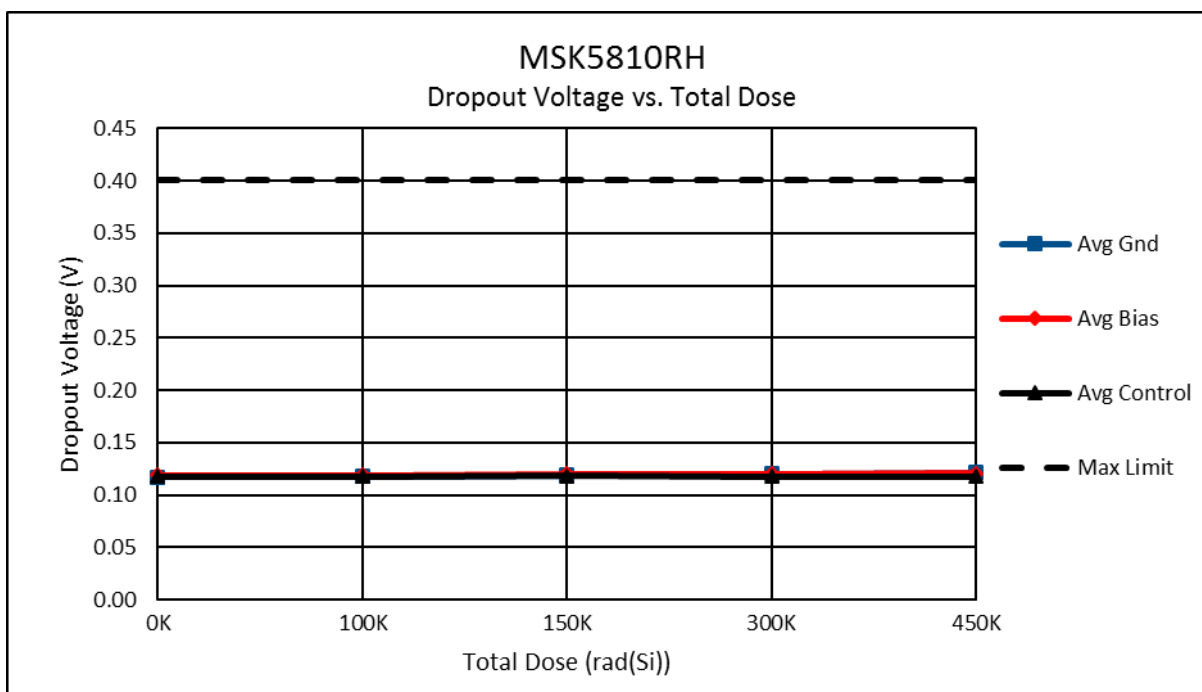
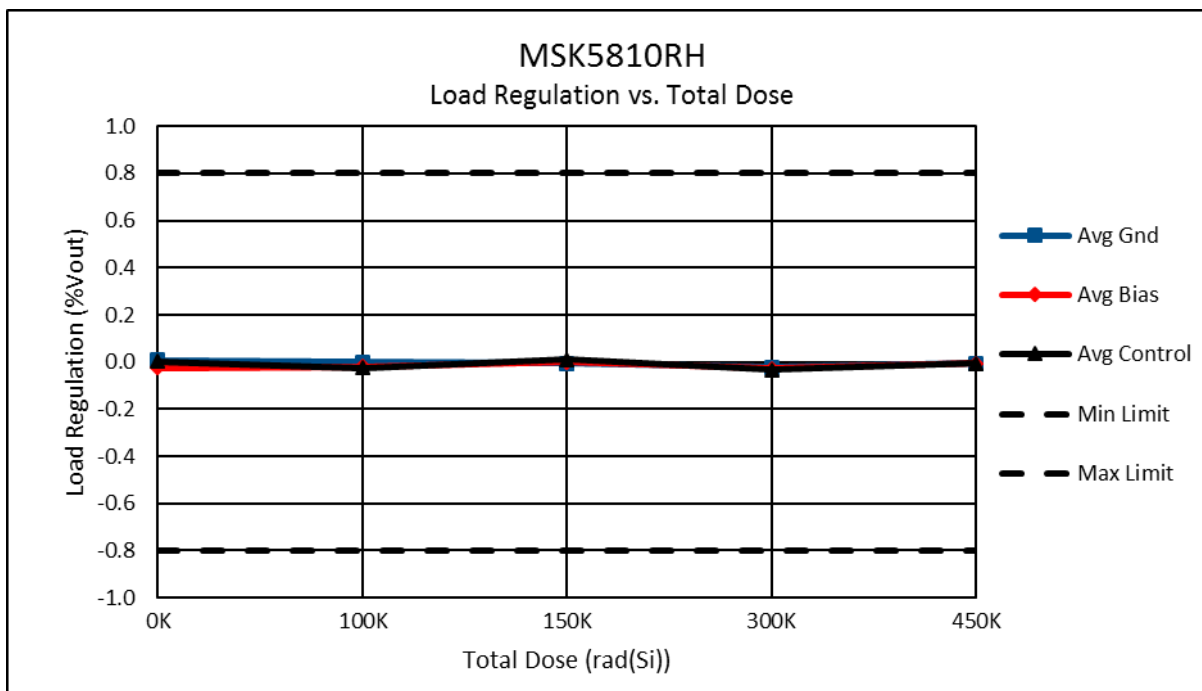
Unbiased S/N – 0015, 0016, 0017, 0018, 0019
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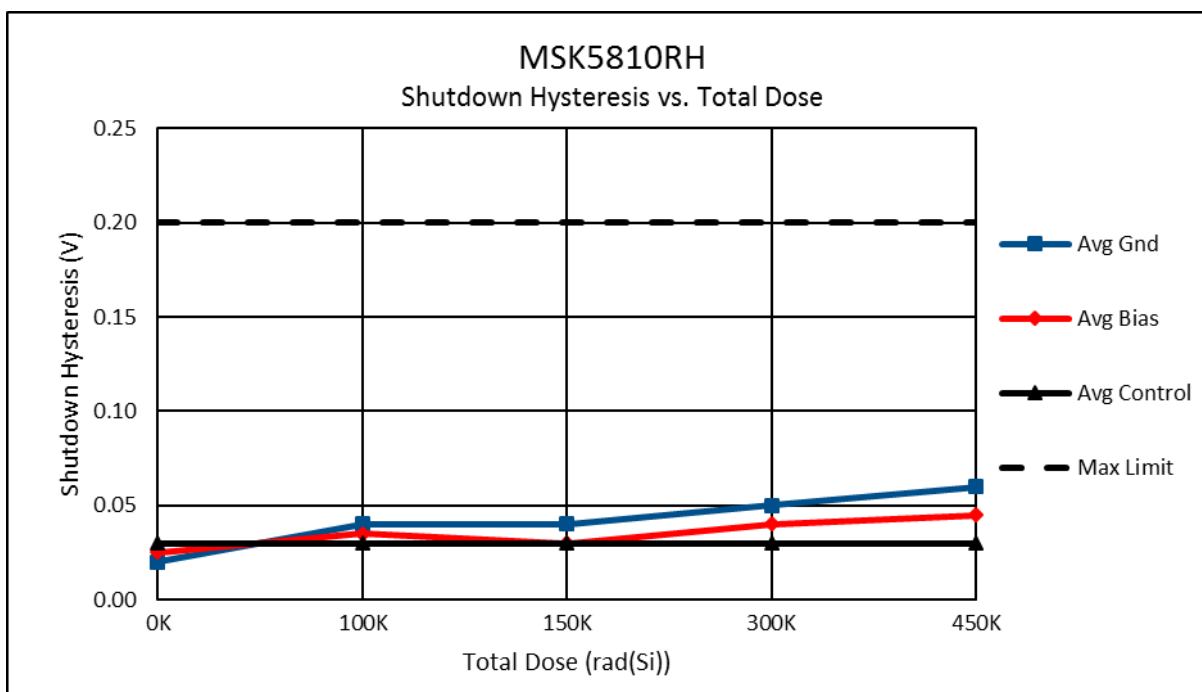
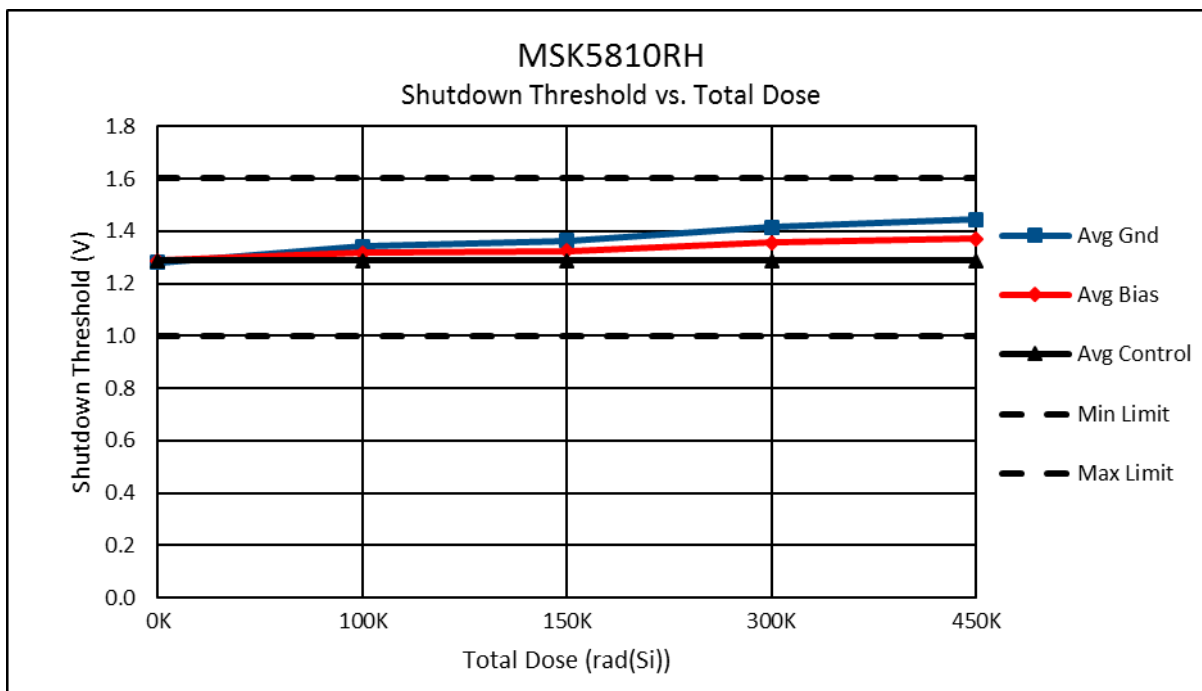
Table 1

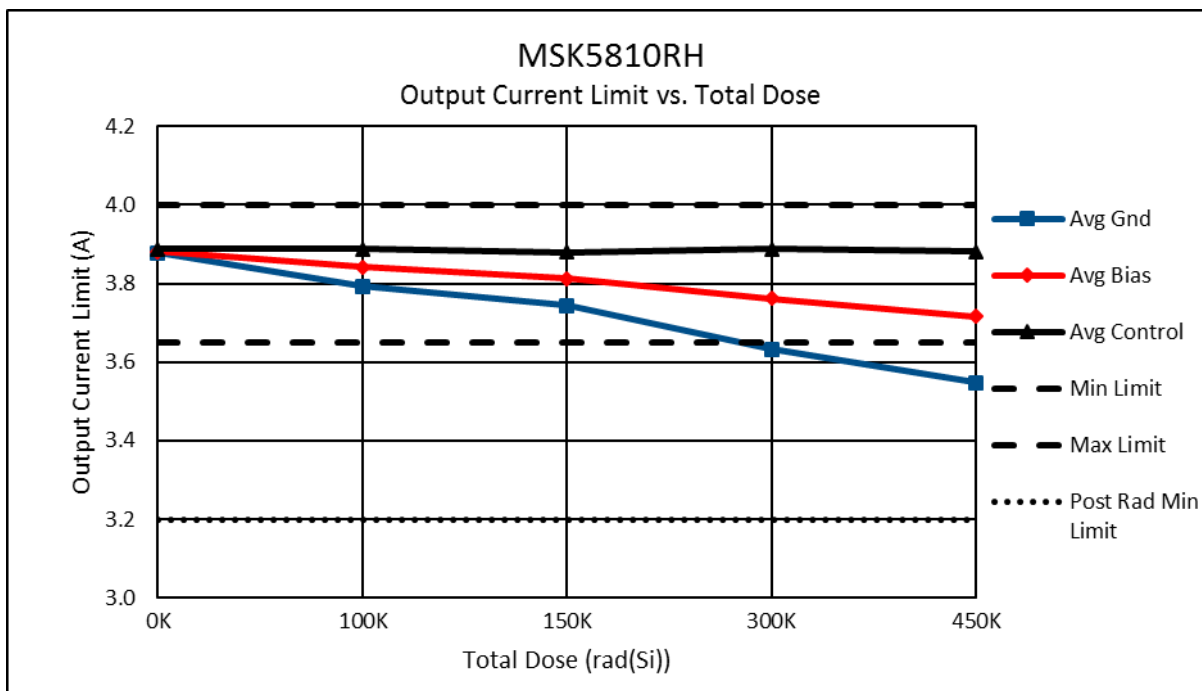
**Dose Time, Incremental Dose and Total Cumulative Dose**













## **Total Dose Radiation Test Report**

### **MSK 5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

November 25, 2008 (MSK 5810RH – 1<sup>st</sup> Test)  
Updated on December 24, 2008  
March 21, 2009 (MSK 5822RH – 1<sup>st</sup> Test)  
March 26, 2009 (MSK 5810RH – 2<sup>nd</sup> Test)  
September 3, 2009 (MSK 5810RH – 3<sup>rd</sup> Test)  
November 6, 2009 (MSK 5810RH – 4<sup>th</sup> Test)  
May 14, 2010 (MSK 5810RH – 5<sup>th</sup> Test)  
September 17, 2010 (MSK 5810RH – 6<sup>th</sup> Test)  
December 10, 2010 (MSK 5810RH – 7<sup>th</sup> Test)  
April 1, 2011 (MSK5810RH – 8<sup>th</sup> Test)  
July 8, 2011 (MSK5810RH – 9<sup>th</sup> Test)  
June 14, 2013 (MSK5810RH – 10<sup>th</sup> Test, IC Wafer Lot: WD0051441#9  
Transistor Wafer Lot: CJ302831#13)  
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Transistor Wafer Lot: CJ302831#21)  
November 6, 2013 (MSK5810RH – 12<sup>th</sup> Test, IC Wafer Lot: W10809524.1 #8  
Transistor Wafer Lot: CJ302831RC#20)  
August 28, 2015 (MSK5810RH – 13<sup>th</sup> Test, IC Wafer Lot: WP005144.1  
Transistor Wafer Lot: P741F1002 #21)  
November 8, 2016 (MSK5810RH – 14<sup>th</sup> Test, IC Wafer Lot: WP005144.1 #9  
Transistor Wafer Lot: PF01F1005 #6)  
March 29, 2017 (MSK5810RH – 15<sup>th</sup> Test, IC Wafer Lot: WP005144.1 #8  
Transistor Wafer Lot: PF01F1005 #6)  
September 15, 2017 (MSK5810RH – 16<sup>th</sup> Test, IC Wafer Lot: W10809524.1 #8  
Transistor Wafer Lot: DL153631 #3)

N. Kresse  
C. Salce  
A. Olesh

Anaren, Inc. – MSK Products

## **I. Introduction:**

The total dose radiation test plan for the MSK5810RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a Cobalt 60 radiation source. The dose rate was determined to be 141 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 160 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, two control devices were tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation, the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as two control devices, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting Anaren Inc. – MSK Products.

## **V. Summary:**

Based on the test data recorded during radiation testing and statistical analysis, Feedback Voltage, Shutdown Threshold, Shutdown Hysteresis and Output Current Limit exhibited shift due to irradiation, however all performance curves stayed within specification beyond 300 Krad(Si) TID.

MSK5810RH Biased/Unbiased Dose Rate Schedule
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Dosimetry Equipment
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Bruker Biospin # 0162
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Irradiation Date
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9/15/17
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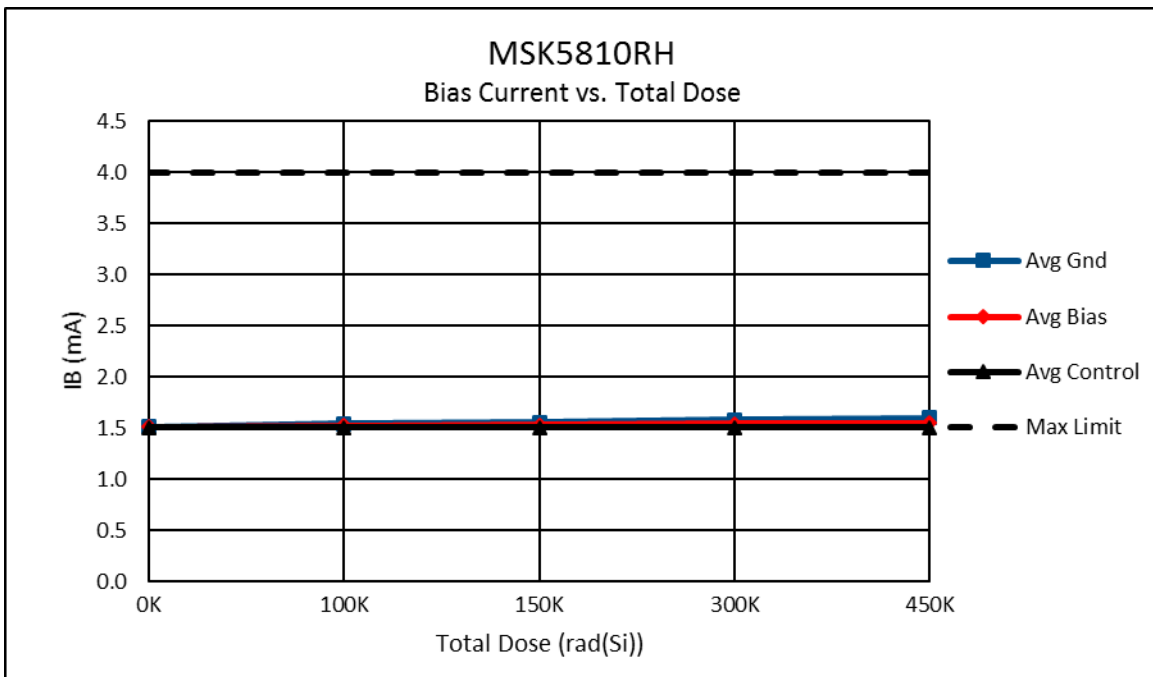
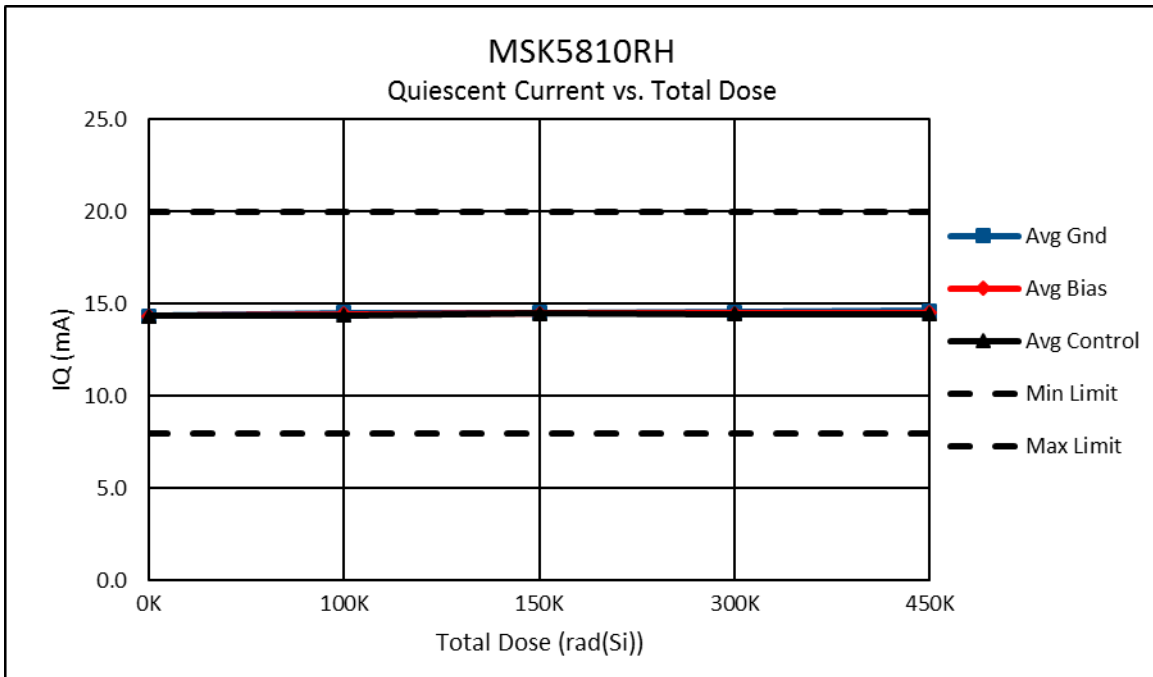
Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
12:10	103,000	103,000
6:05	51,500	154,500
18:16	154,500	309,000
18:16	154,500	463,500

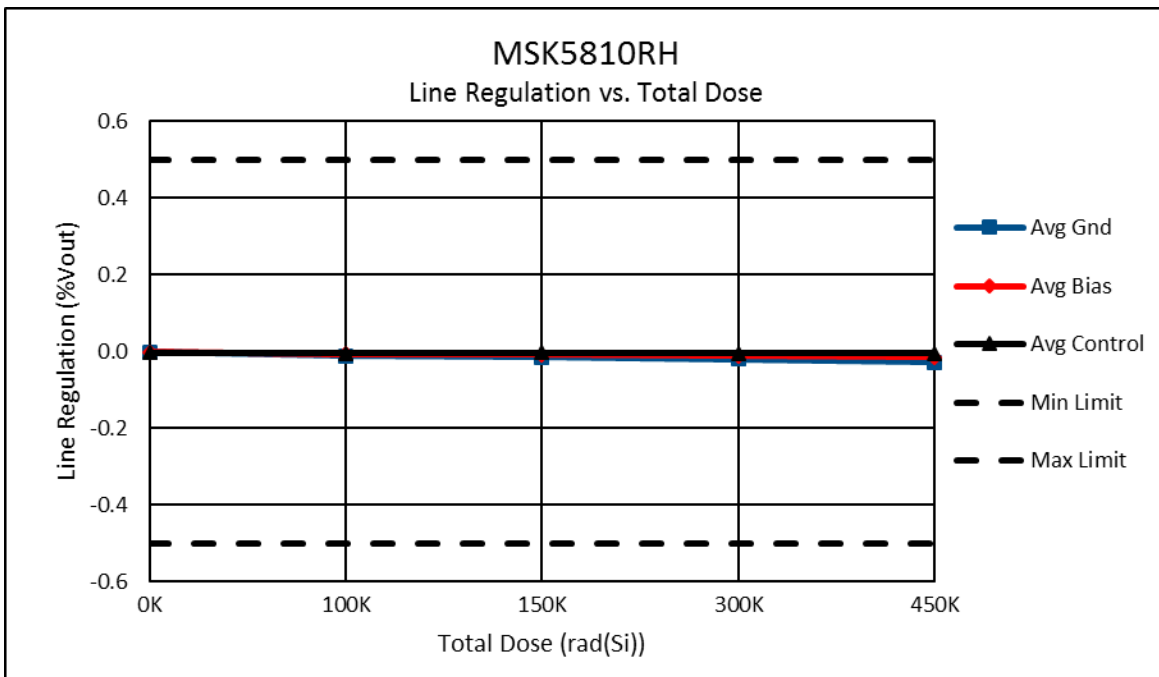
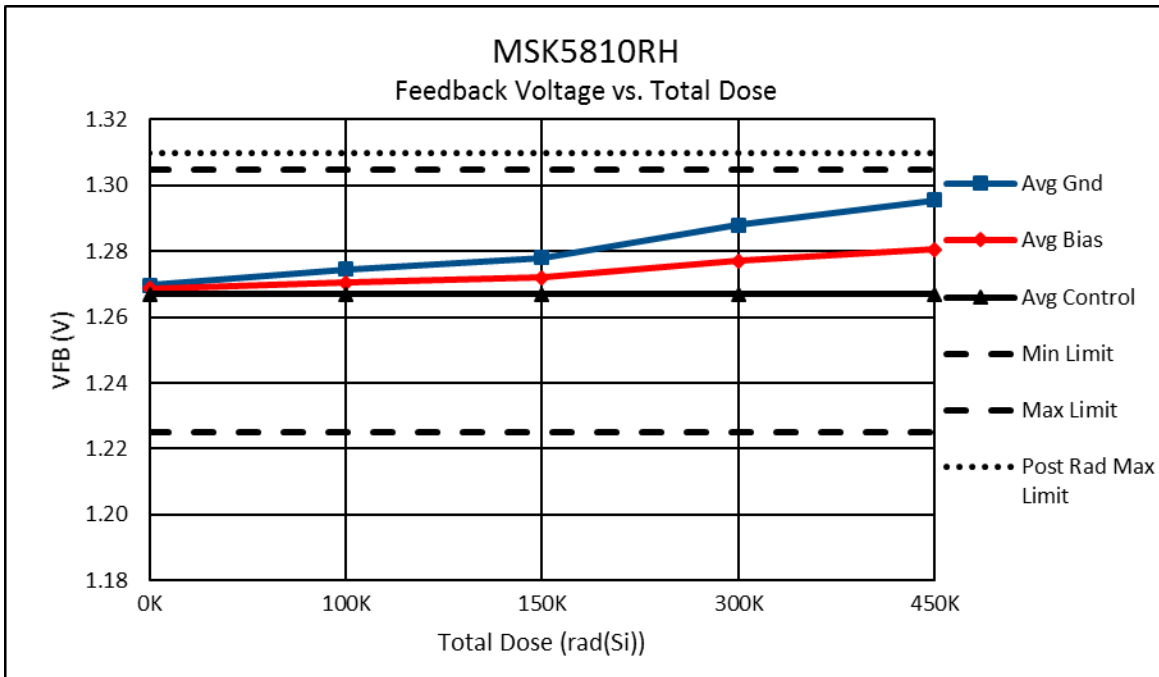
Biased S/N – 1458, 1459, 1460, 1461, 1462
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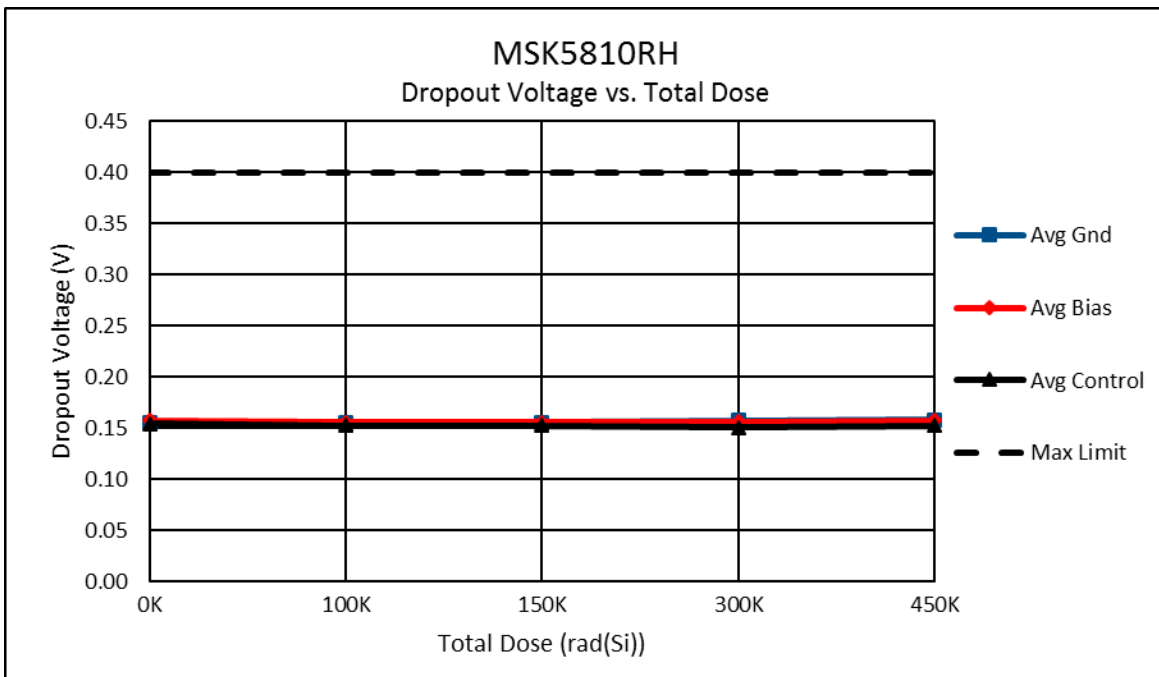
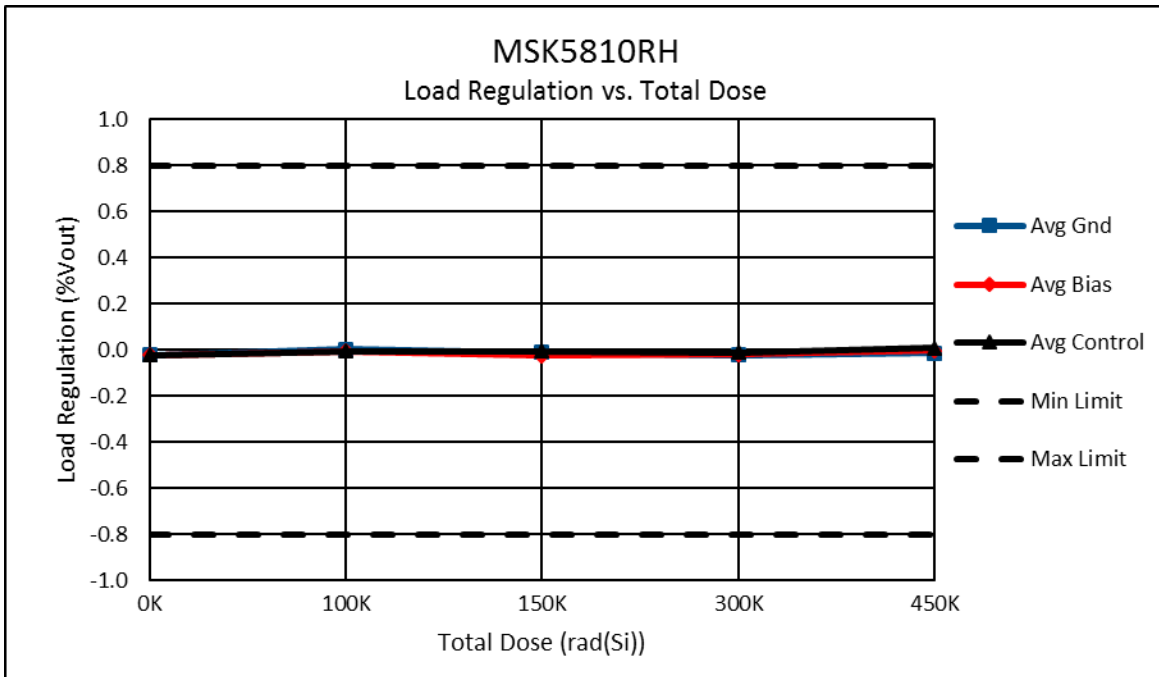
Unbiased S/N – 1463, 1464, 1465, 1466, 1467
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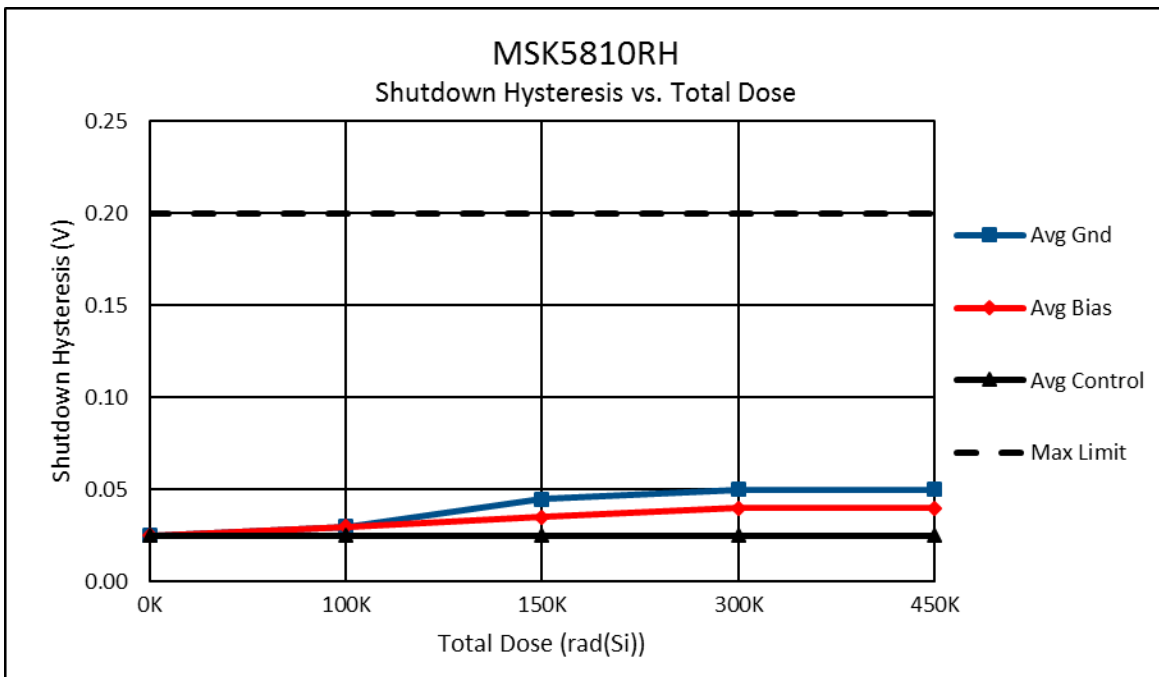
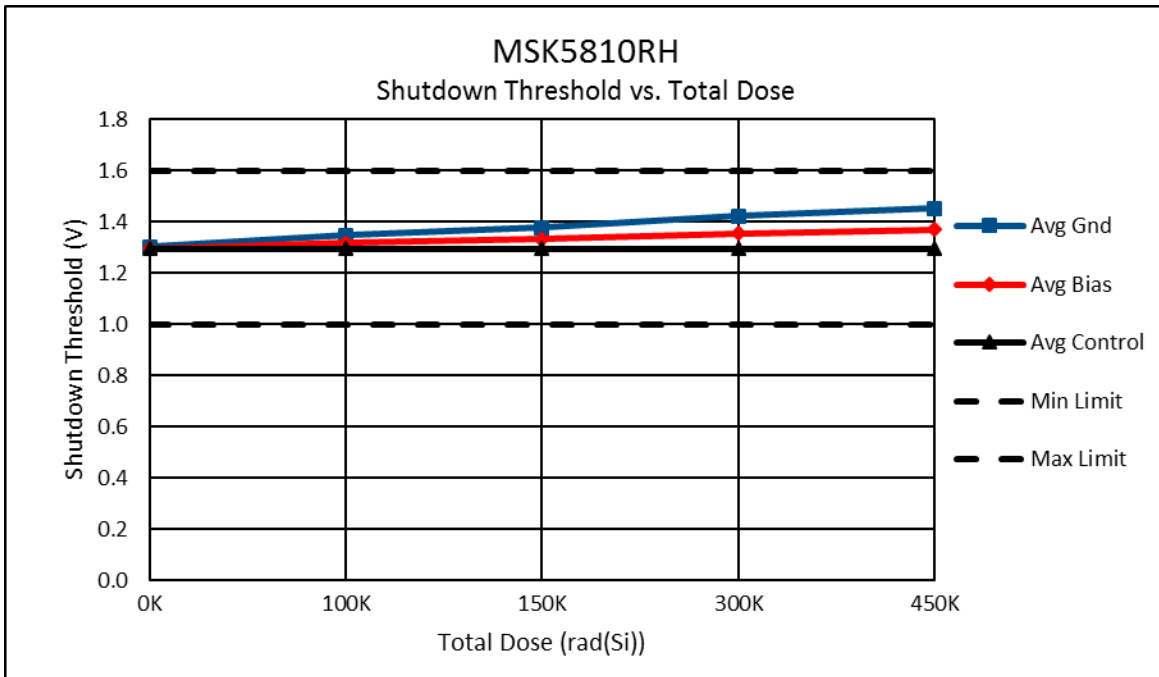
Table 1

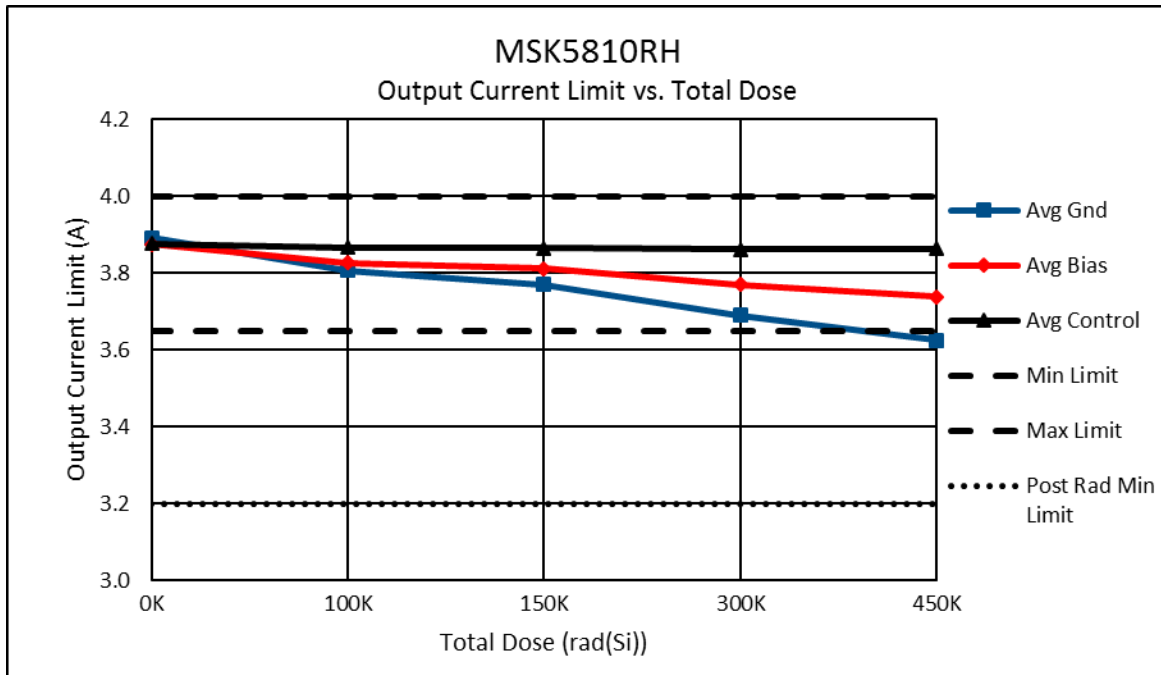
**Dose Time, Incremental Dose and Total Cumulative Dose**













## **Total Dose Radiation Test Report**

### **MSK 5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

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Updated on December 24, 2008  
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June 14, 2013 (MSK5810RH – 10<sup>th</sup> Test, IC Wafer Lot: WD0051441#9  
Transistor Wafer Lot: CJ302831#13)  
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Transistor Wafer Lot: P741F1002 #21)  
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Transistor Wafer Lot: PF01F1005 #6)  
March 29, 2017 (MSK5810RH – 15<sup>th</sup> Test, IC Wafer Lot: WP005144.1 #8  
Transistor Wafer Lot: PF01F1005 #6)

B. Horton  
P. Dinneen  
N. Kresse

MSK Products – Anaren Inc.

## **I. Introduction:**

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK 5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 151 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, two control devices were tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation, the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting Anaren Inc. – MSK Products.

## **V. Summary:**

Based on the test data recorded during radiation testing and statistical analysis, Feedback Voltage, Shutdown Threshold, and Shutdown Hysteresis exhibited shift due to irradiation, however all performance curves stayed within specification beyond 300 Krad(Si) TID.

A Line Regulation data point was an outlier at 300 Krad(Si) but was within family at 100 Krad(Si) and 450 Krad(Si). We can conclude that this was a testing error and therefore removed the data point from the analysis.

MSK 5810RH Biased/Unbiased Dose Rate Schedule
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Dosimetry Equipment
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Bruker Biospin # 0162
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Irradiation Date
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3/29/17
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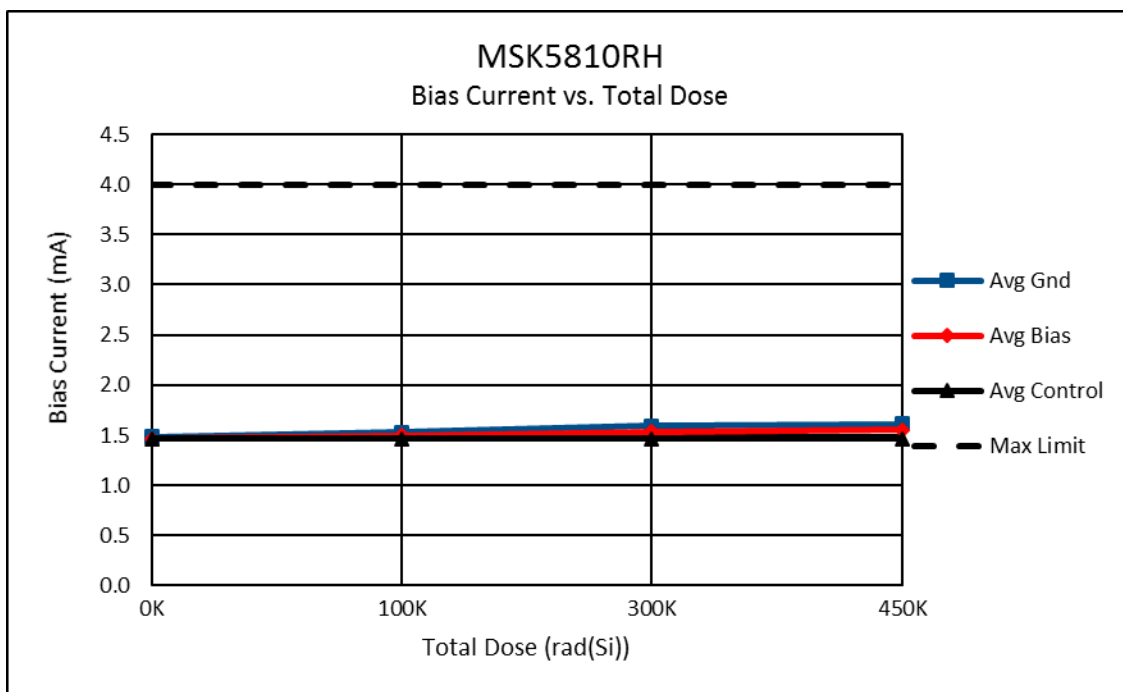
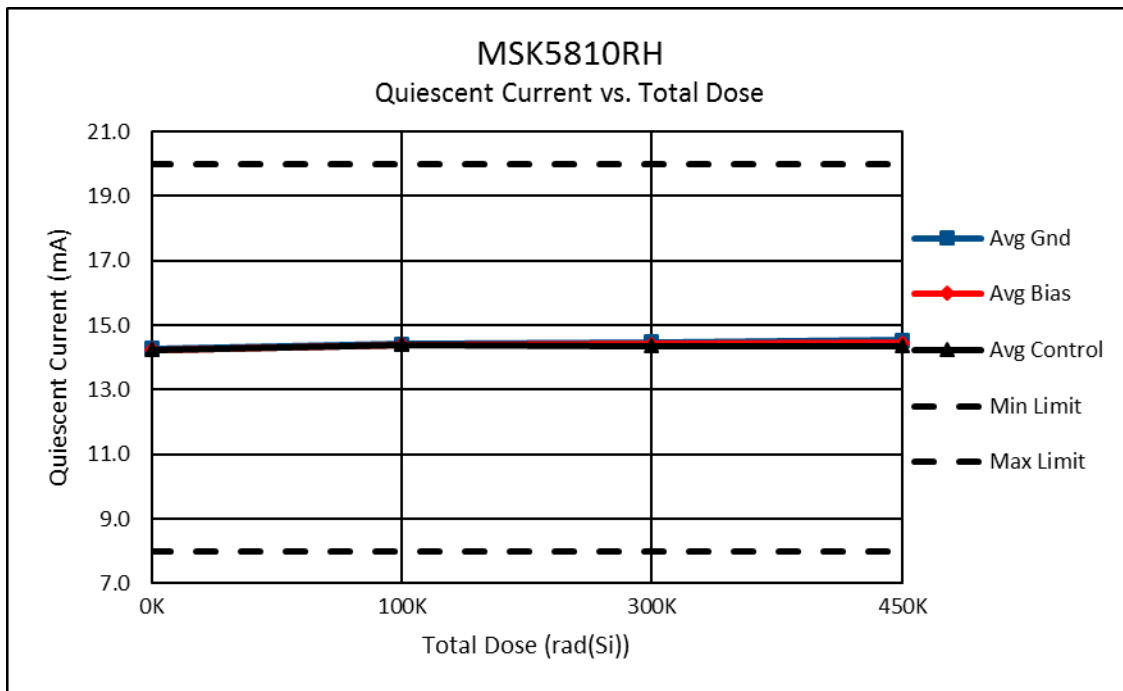
Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
11:23	103,000	100,300
22:46	206,000	309,000
17:05	154,500	463,500

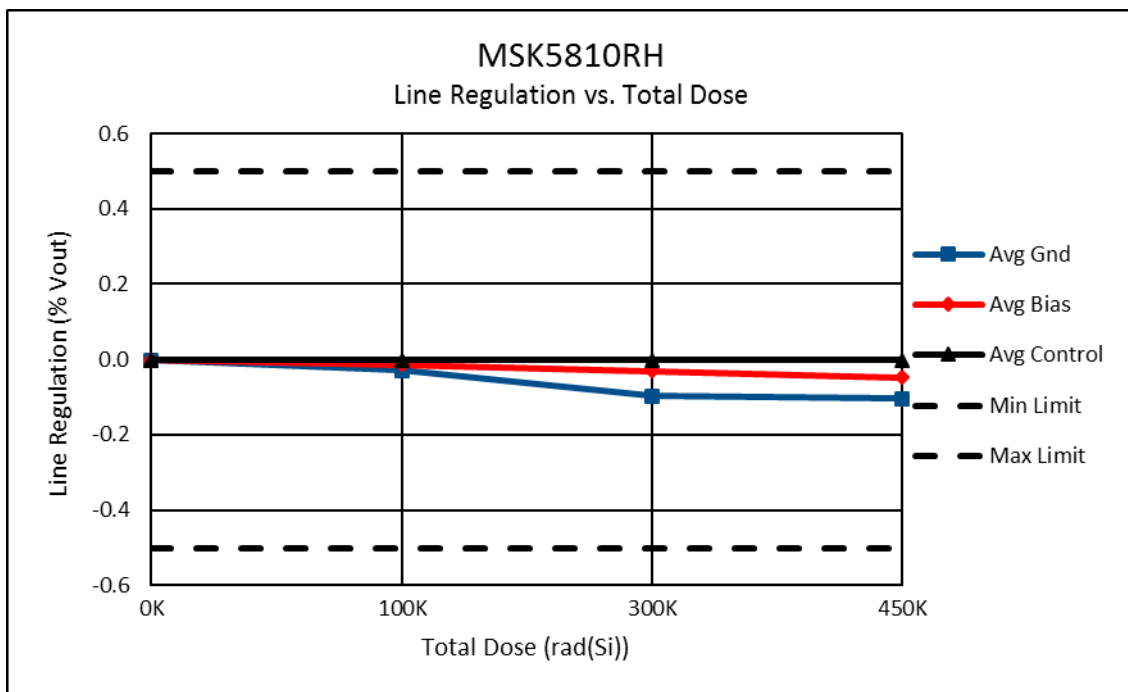
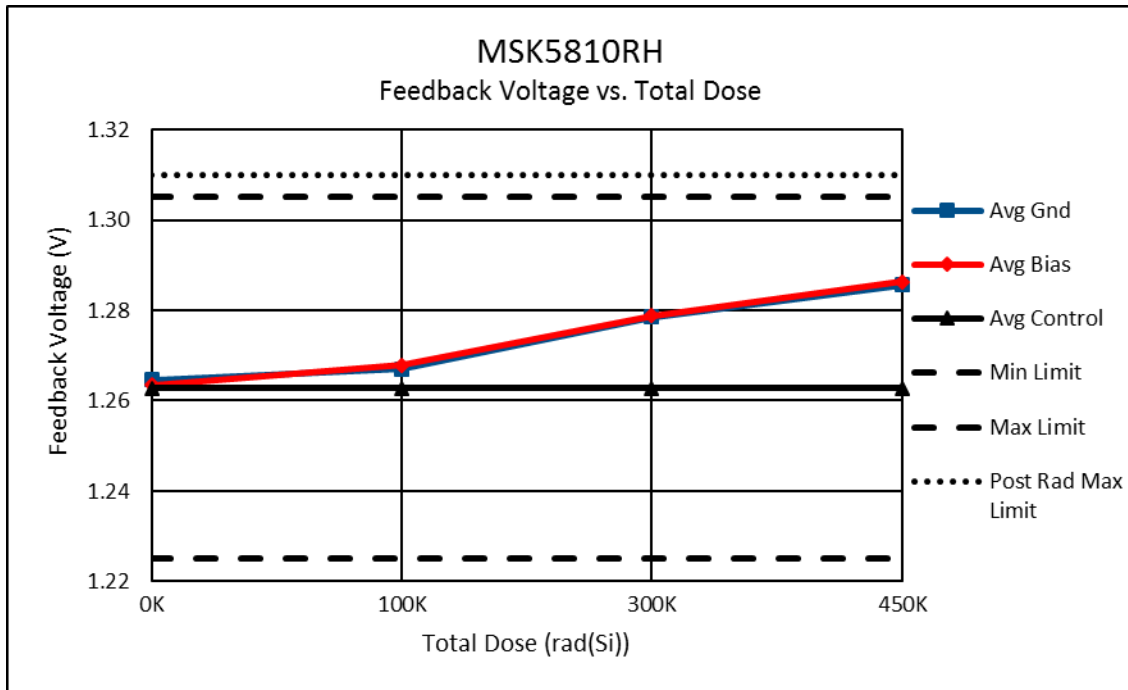
Biased S/N – 1366, 1367, 1368, 1369, 1370
-------------------------------------------

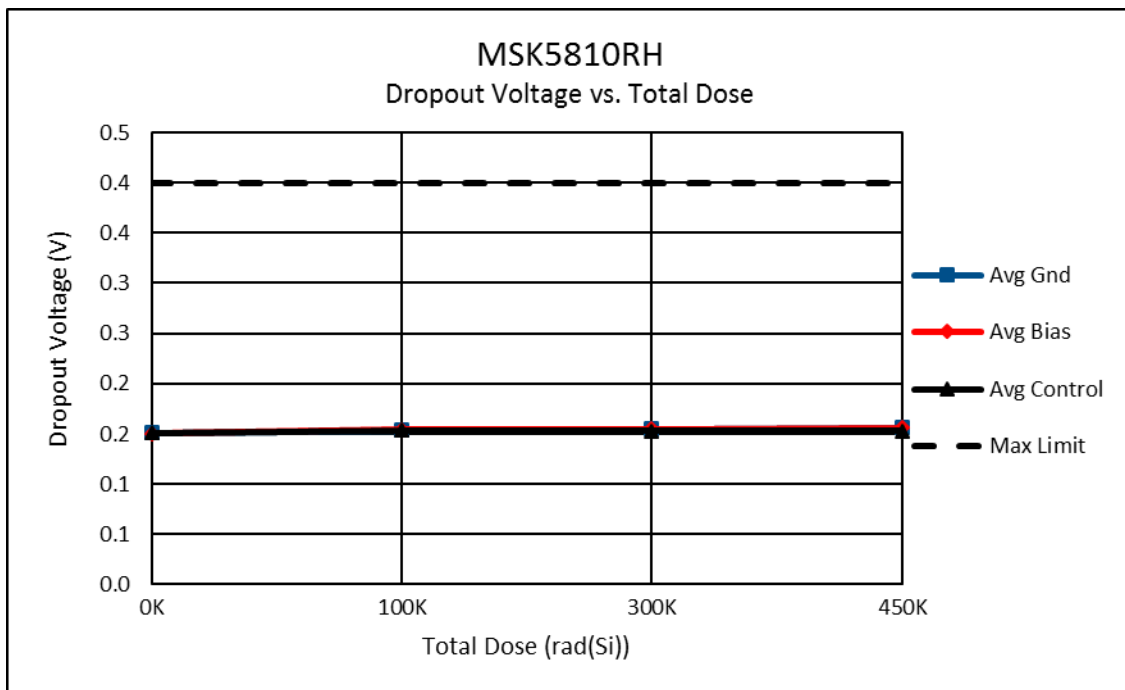
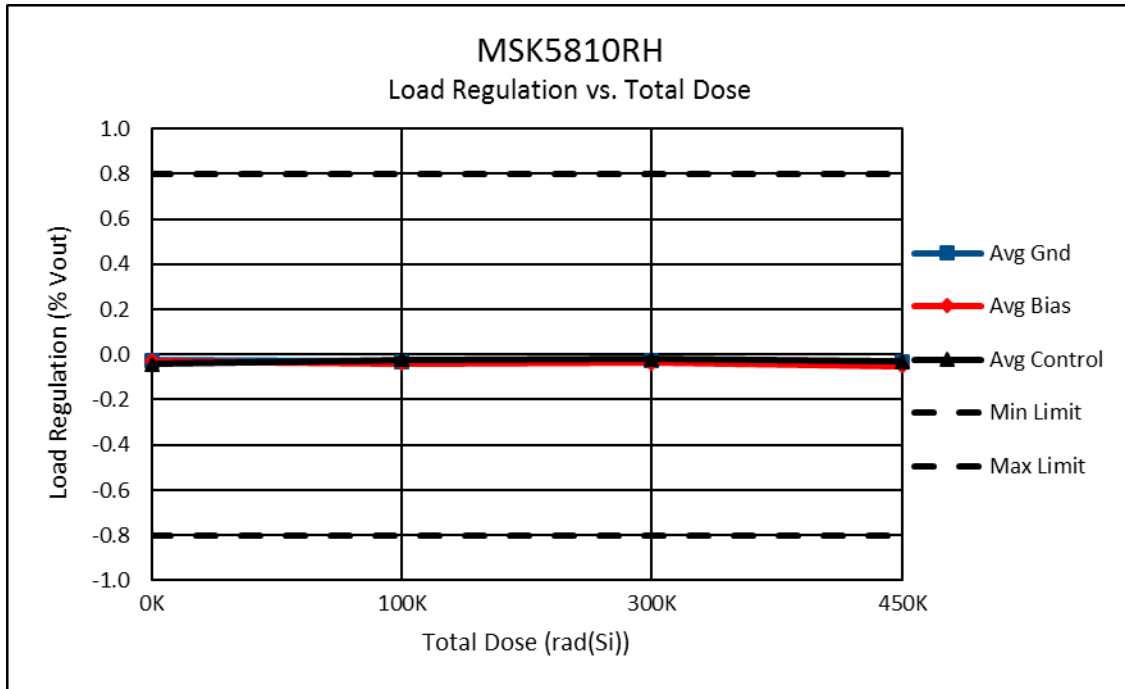
Unbiased S/N – 1371, 1372, 1373, 1374, 1375
---------------------------------------------

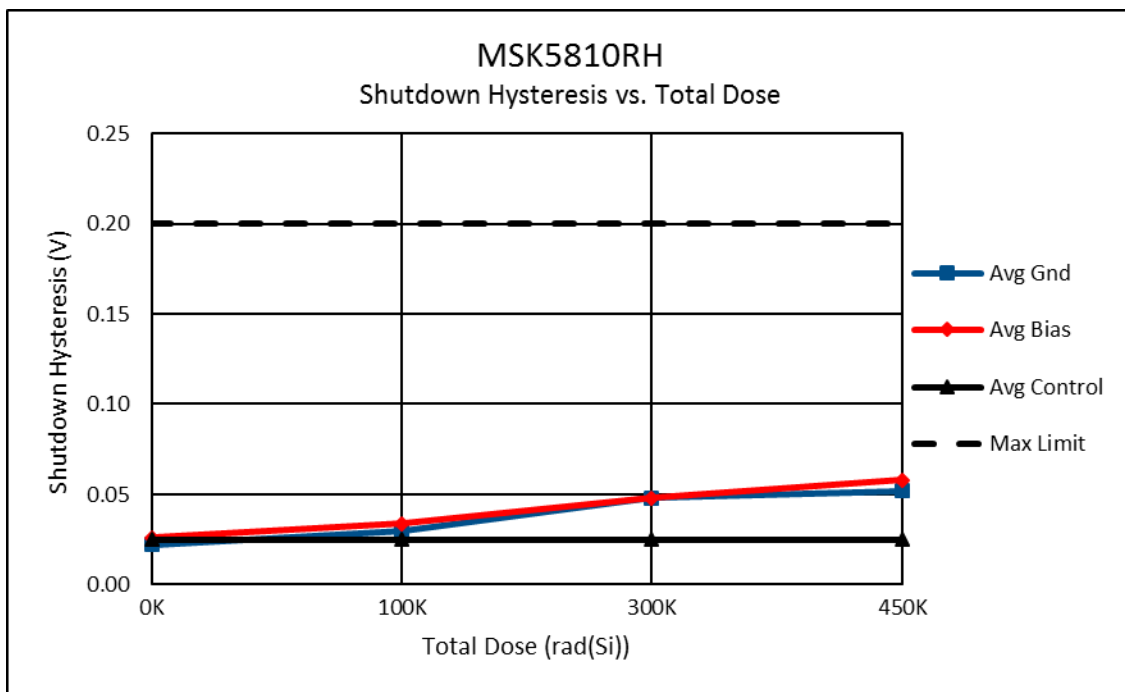
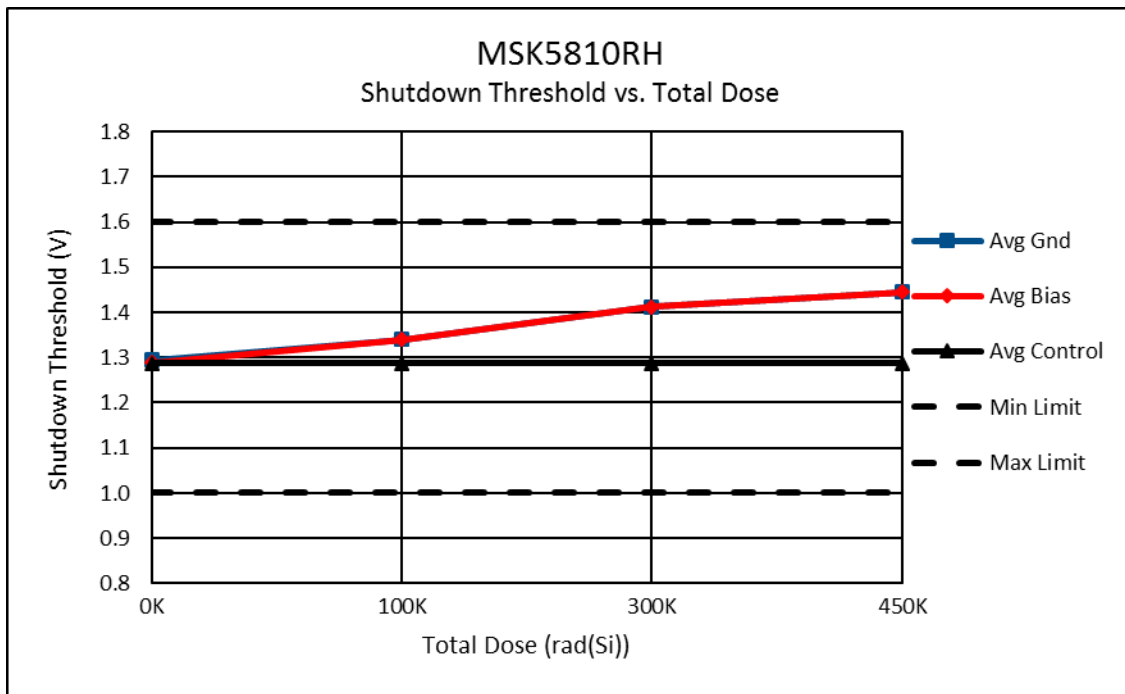
Table 1

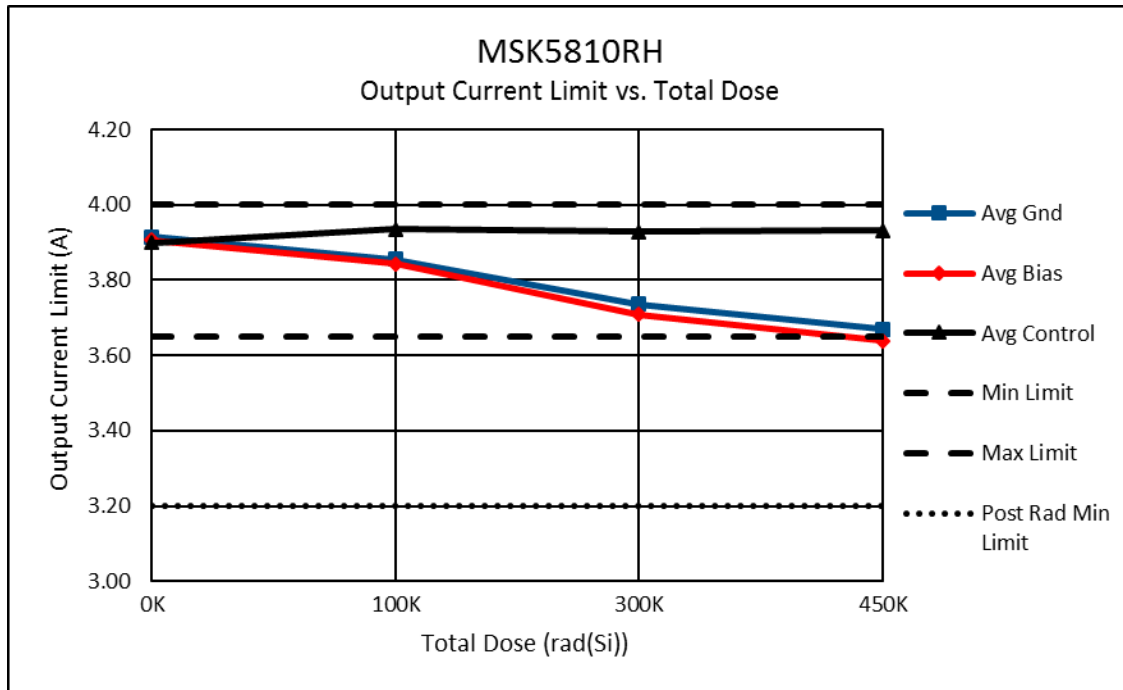
**Dose Time, Incremental Dose and Total Cumulative Dose**













## **Total Dose Radiation Test Report**

### **MSK 5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

November 25, 2008 (MSK 5810RH – 1<sup>st</sup> Test)  
Updated on December 24, 2008  
March 21, 2009 (MSK 5822RH – 1<sup>st</sup> Test)  
March 26, 2009 (MSK 5810RH – 2<sup>nd</sup> Test)  
September 3, 2009 (MSK 5810RH – 3<sup>rd</sup> Test)  
November 6, 2009 (MSK 5810RH – 4<sup>th</sup> Test)  
May 14, 2010 (MSK 5810RH – 5<sup>th</sup> Test)  
September 17, 2010 (MSK 5810RH – 6<sup>th</sup> Test)  
December 10, 2010 (MSK 5810RH – 7<sup>th</sup> Test)  
April 1, 2011 (MSK5810RH – 8<sup>th</sup> Test)  
July 8, 2011 (MSK5810RH – 9<sup>th</sup> Test)  
June 14, 2013 (MSK5810RH – 10<sup>th</sup> Test, IC Wafer Lot: WD0051441#9  
Transistor Wafer Lot: CJ302831#13)  
June 14, 2013 (MSK5810RH – 11<sup>th</sup> Test, IC Wafer Lot: WD0051441#9  
Transistor Wafer Lot: CJ302831#21)  
November 6, 2013 (MSK5810RH – 12<sup>th</sup> Test, IC Wafer Lot: W10809524.1 #8  
Transistor Wafer Lot: CJ302831RC#20)  
August 28, 2015 (MSK5810RH – 13<sup>th</sup> Test, IC Wafer Lot: WP005144.1  
Transistor Wafer Lot: P741F1002 #21)  
November 8, 2016 (MSK5810RH – 14<sup>th</sup> Test, IC Wafer Lot: WP005144.1 #9  
Transistor Wafer Lot: PF01F1005 #6)

B. Horton  
F. Freytag  
J. Joy  
N. Kresse

MSK Products – Anaren Inc.

## **I. Introduction:**

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK 5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 158 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting Anaren Inc. – MSK Products.

## **V. Summary:**

Based on the test data recorded during radiation testing and statistical analysis, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID

MSK 5810RH Biased/Unbiased Dose Rate Schedule
--------------------------------------------------

Dosimetry Equipment
Bruker Biospin # 0162

Irradiation Date
11/8/16

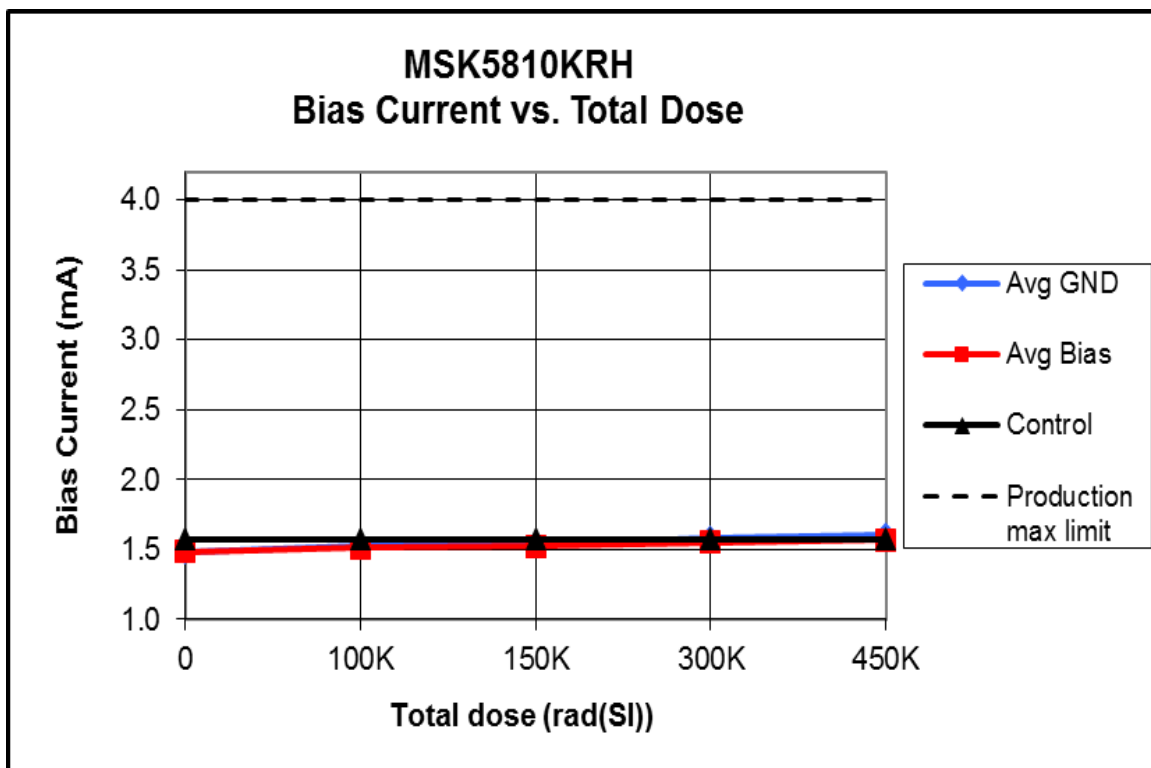
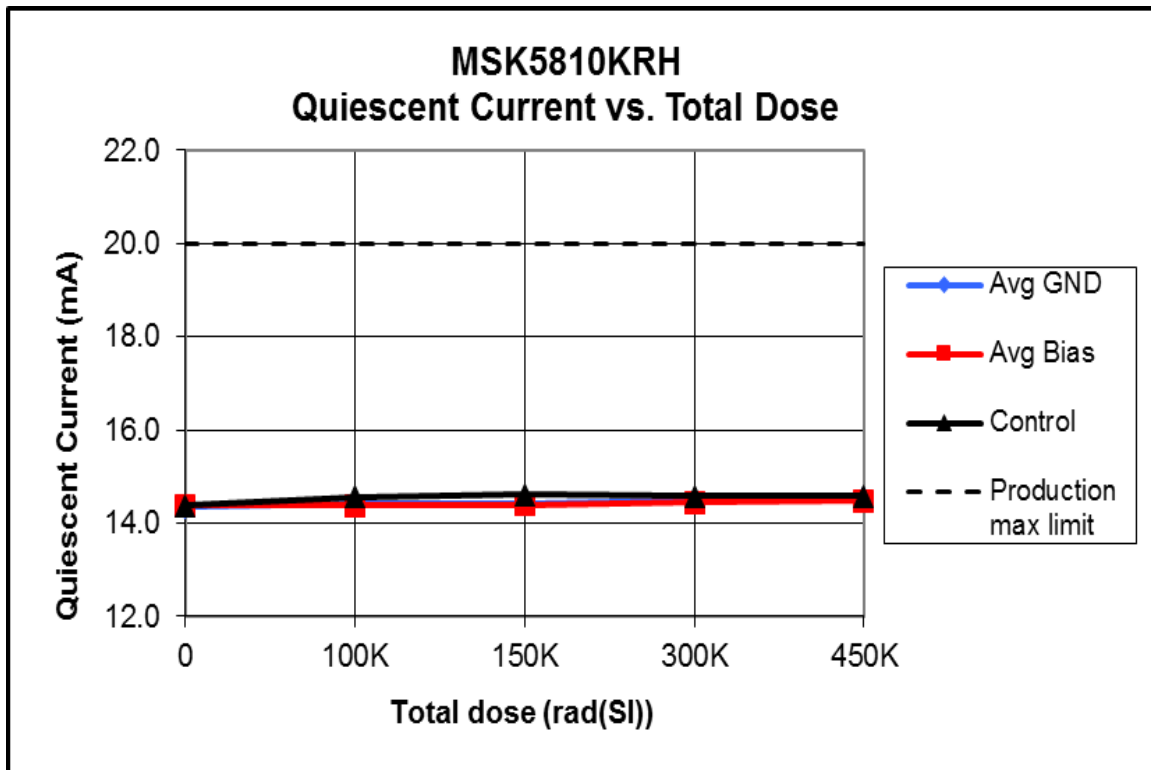
Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
0:10:35	100,300	100,300
0:05:17	50,100	150,400
0:15:52	150,400	300,800
0:15:52	150,400	451,200

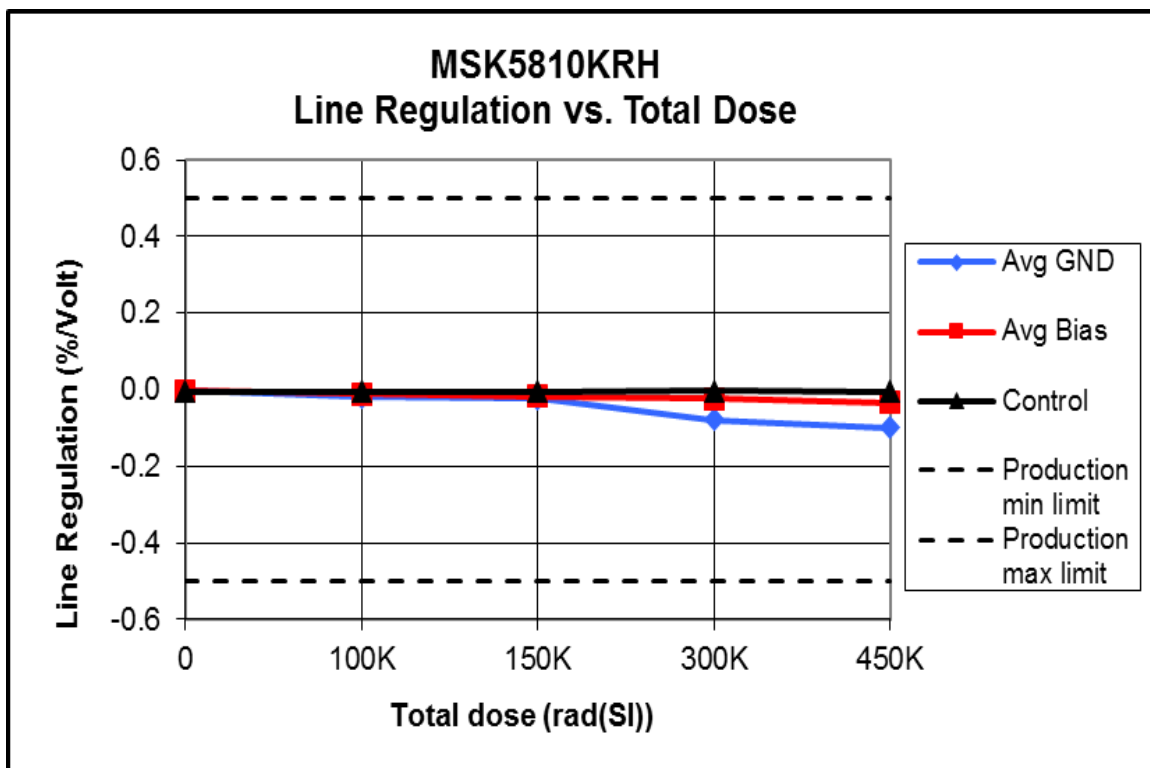
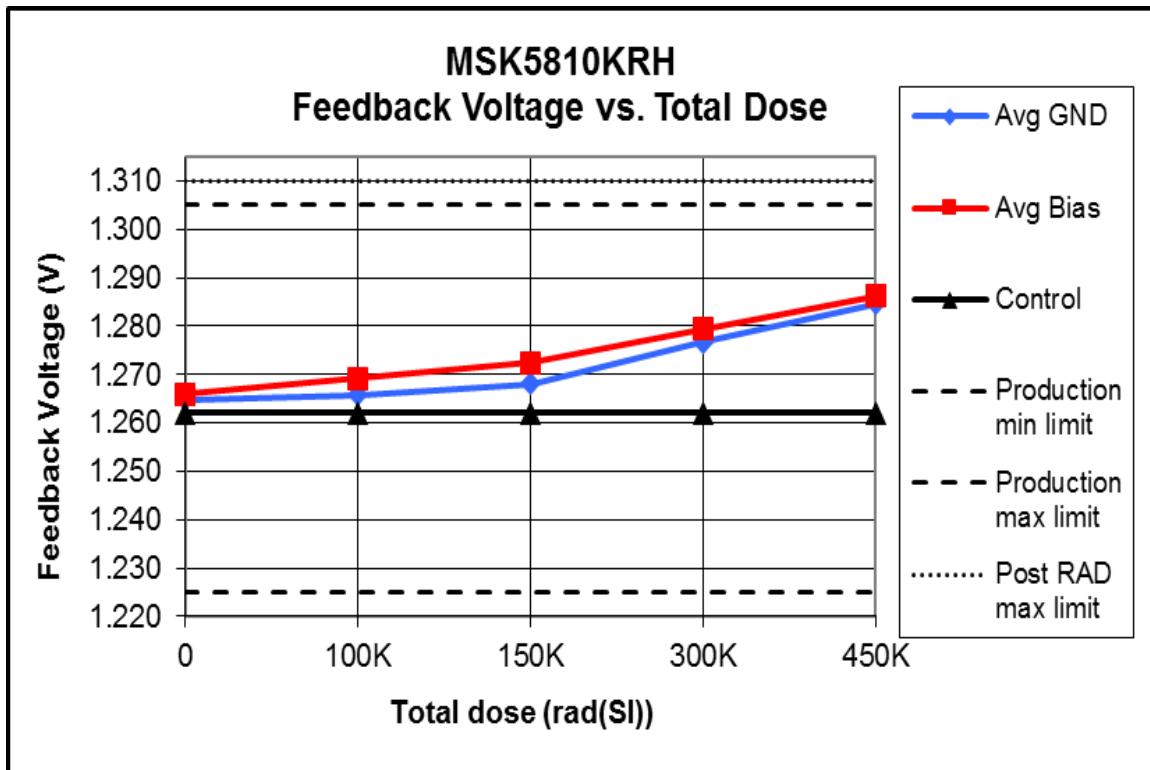
Biased S/N – 1344, 1345, 1346, 1347, 1348
-------------------------------------------

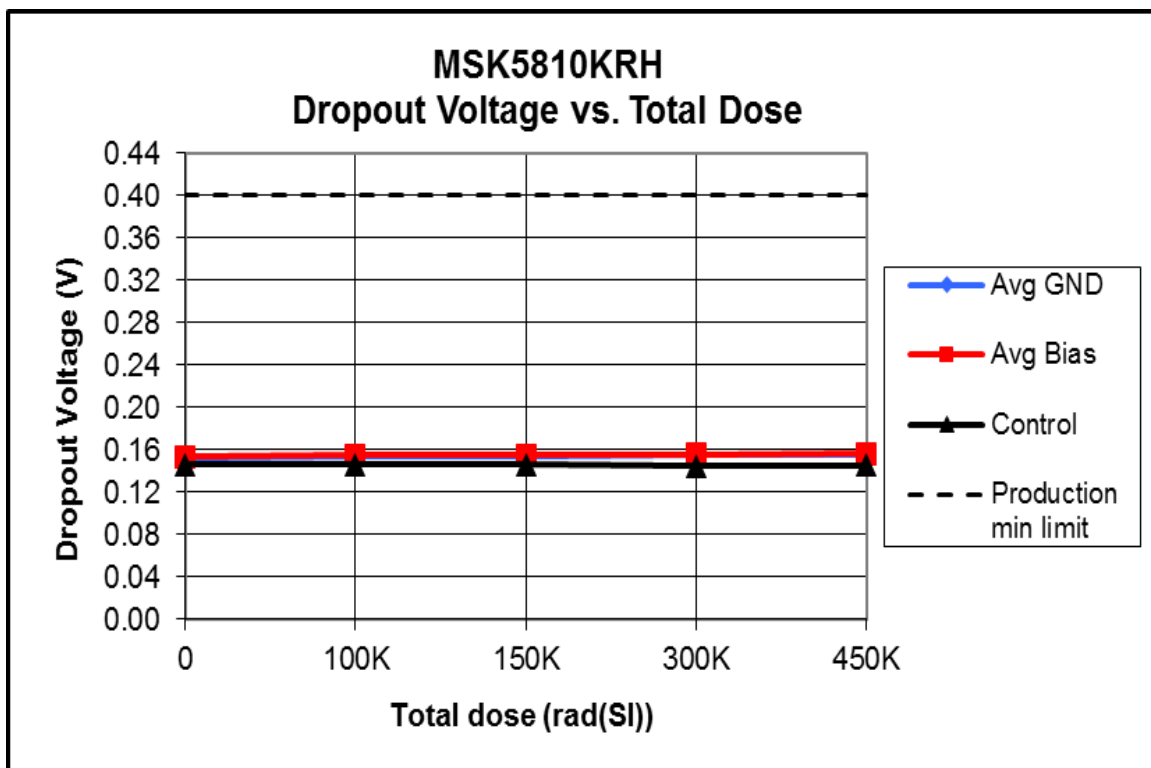
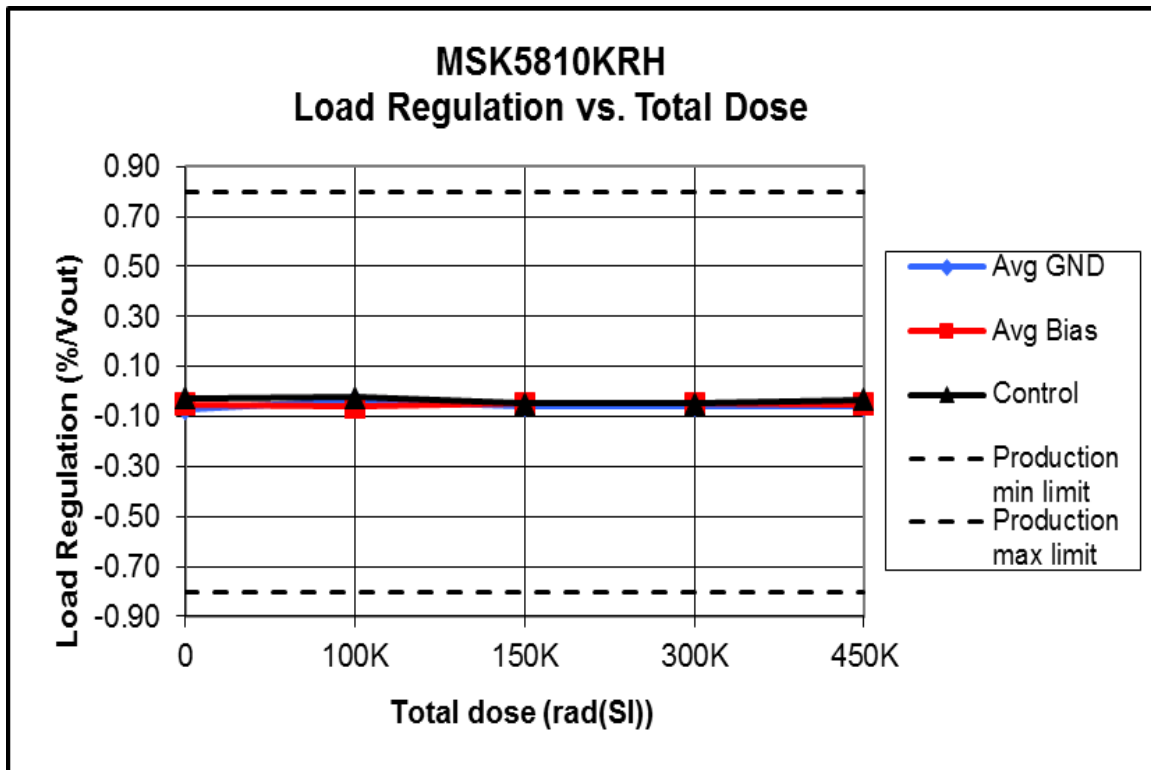
Unbiased S/N – 1349, 1350, 1351, 1352, 1353
---------------------------------------------

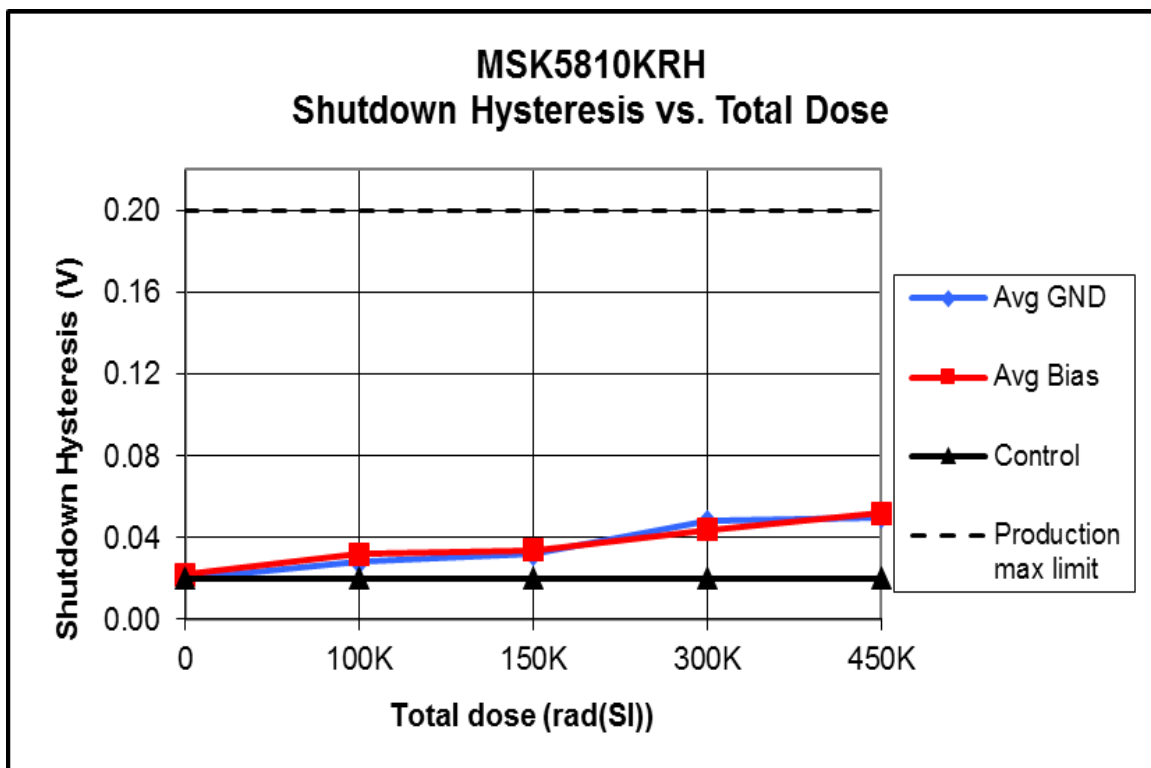
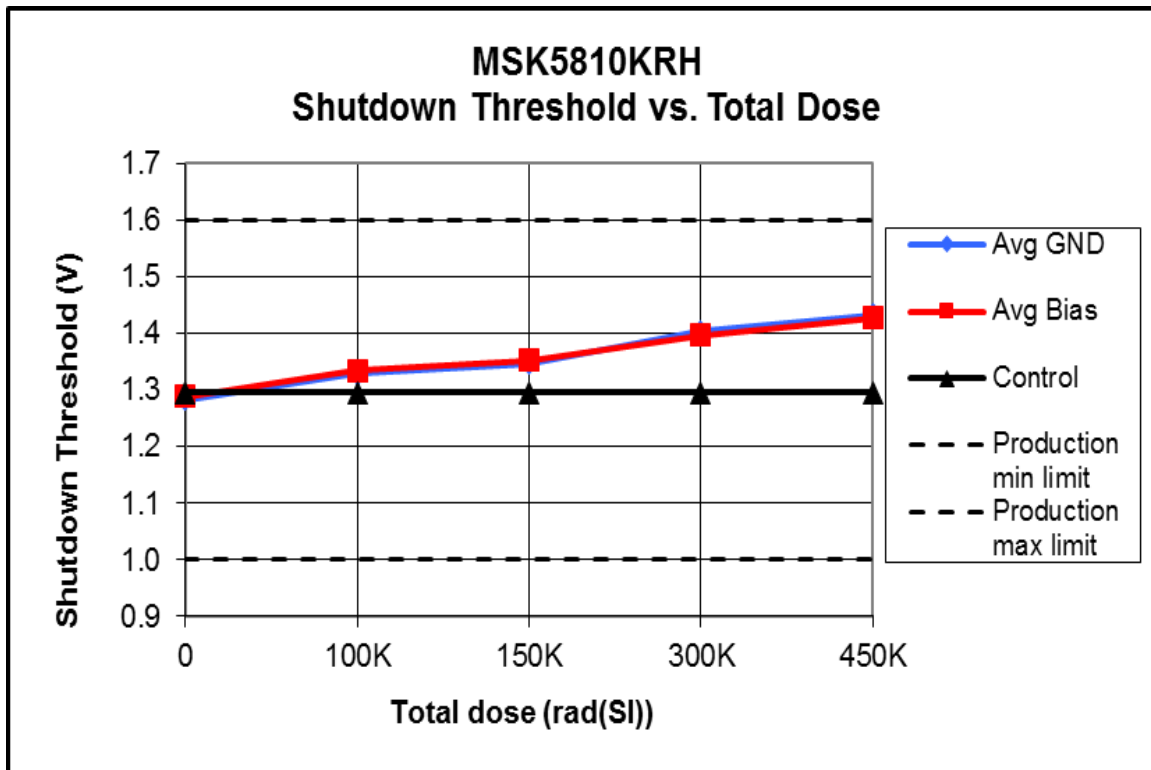
Table 1

**Dose Time, Incremental Dose and Total Cumulative Dose**

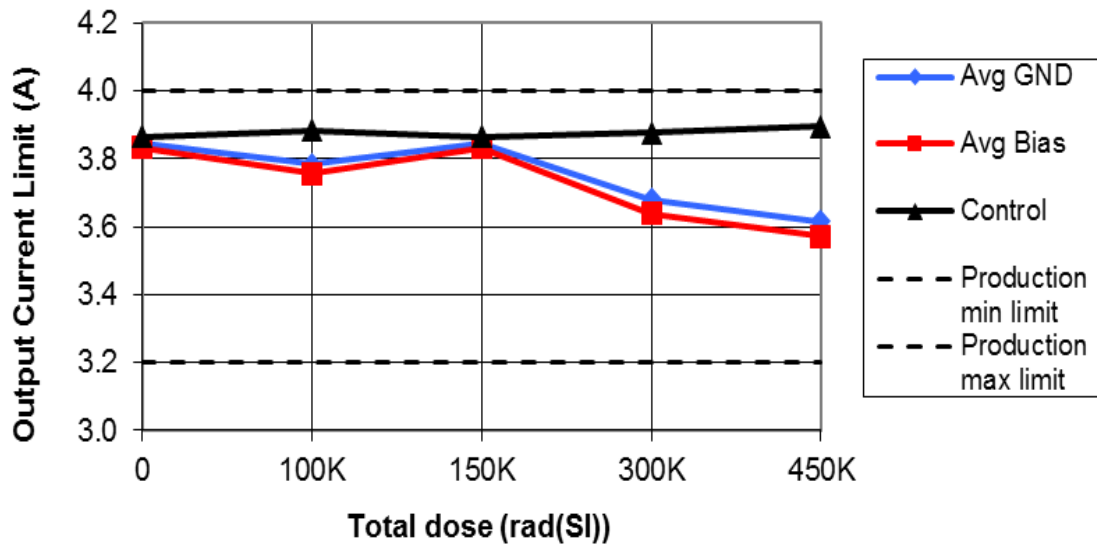








**MSK5810KRH**  
**Output Current Limit vs. Total Dose**





## **Total Dose Radiation Test Report**

### **MSK 5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK5827RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

November 25, 2008 (MSK5810RH – 1<sup>st</sup> Test)  
Updated on December 24, 2008  
March 21, 2009 (MSK5822RH – 1<sup>st</sup> Test)  
March 26, 2009 (MSK5810RH – 2<sup>nd</sup> Test)  
September 3, 2009 (MSK5810RH – 3<sup>rd</sup> Test)  
November 6, 2009 (MSK5810RH – 4<sup>th</sup> Test)  
May 14, 2010 (MSK5810RH – 5<sup>th</sup> Test)  
September 17, 2010 (MSK 5810RH – 6<sup>th</sup> Test)  
December 10, 2010 (MSK 5810RH – 7<sup>th</sup> Test)  
April 1, 2011 (MSK5810RH – 8<sup>th</sup> Test)  
July 8, 2011 (MSK5810RH – 9<sup>th</sup> Test)  
June 14, 2013 (MSK5810RH – 10<sup>th</sup> Test, IC Wafer Lot: WD0051441#9  
Transistor Wafer Lot: CJ302831#13)  
June 14, 2013 (MSK5810RH – 11<sup>th</sup> Test, IC Wafer Lot: WD0051441#9  
Transistor Wafer Lot: CJ302831#21)  
November 6, 2013 (MSK5810RH – 12<sup>th</sup> Test, IC Wafer Lot: W10809524.1 #8  
Transistor Wafer Lot: CJ302831RC#20)  
August 28, 2015 (MSK5810RH – 13<sup>th</sup> Test, IC Wafer Lot: WP005144.1  
Transistor Wafer Lot: P741F1002 #21)

B. Horton  
C. Salce

MSK Products, Anaren Inc.

## **I. Introduction:**

The total dose radiation test plan for the MSK5810RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 109 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting MSK.

## **V. Summary:**

Based on the test data recorded during radiation testing, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID

MSK 5810RH Biased/Unbiased Dose Rate Schedule
--------------------------------------------------

Dosimetry Equipment
Bruker Biospin # 0162

Irradiation Date
8/28/15

Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
15:45	103,005	103,005
07:53	51,557	154,562
23:38	154,562	309,124
23:38	154,562	463,686

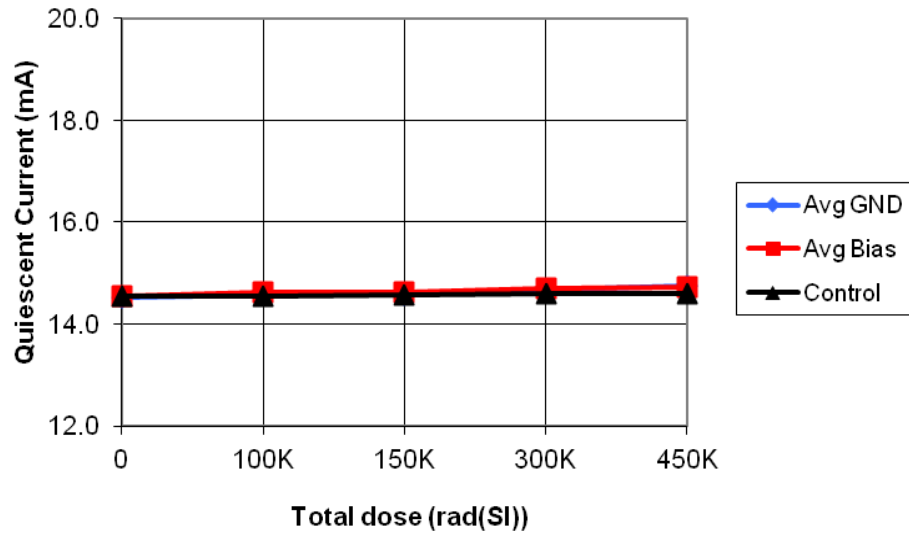
Biased S/N – 1228, 1229, 1230, 1232, 1233
-------------------------------------------

Unbiased S/N – 1234, 1235, 1236, 1237, 1238
---------------------------------------------

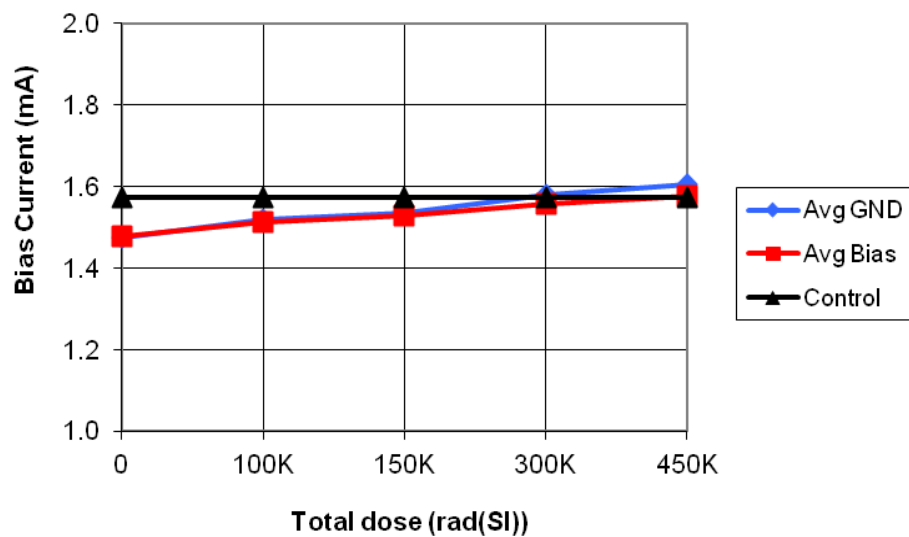
Table 1

**Dose Time, Incremental Dose and Total Cumulative Dose**

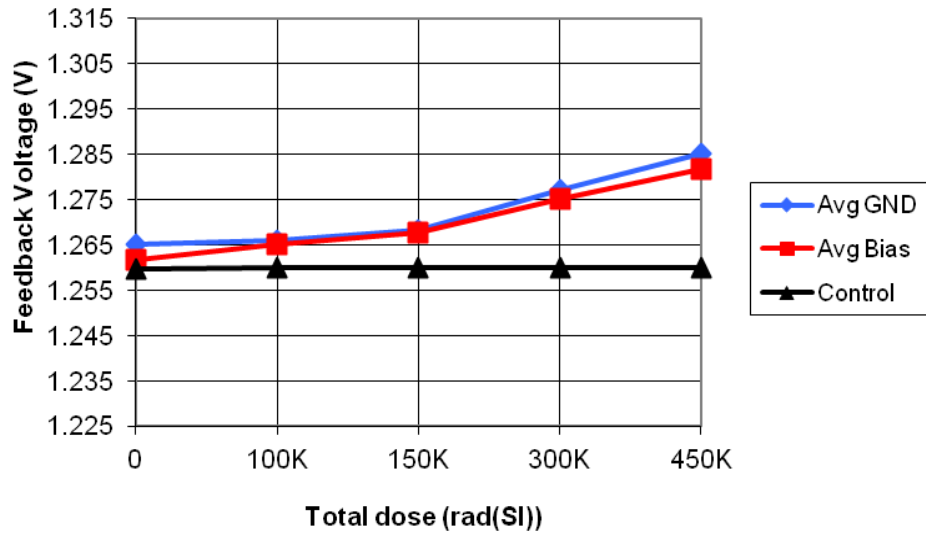
MSK5810KRH  
Quiescent Current vs. Total Dose



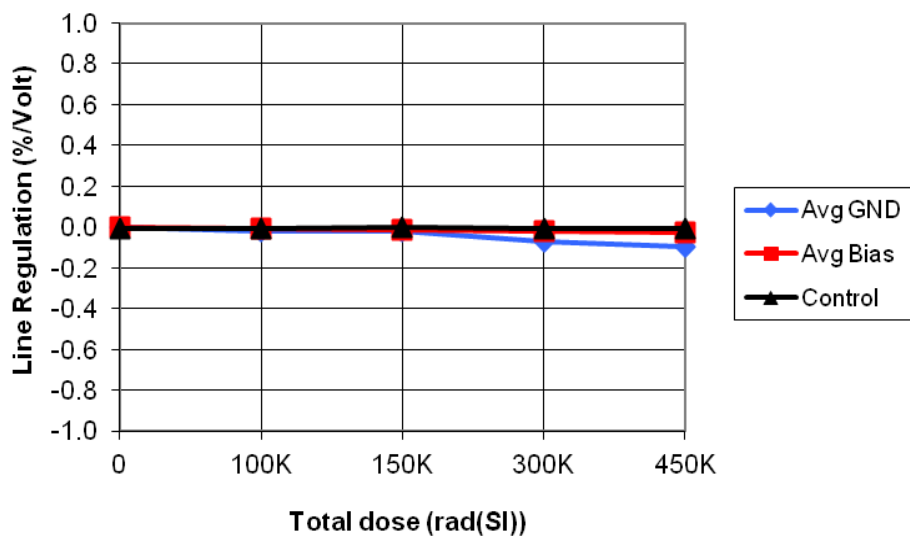
MSK5810KRH  
Bias Current vs. Total Dose



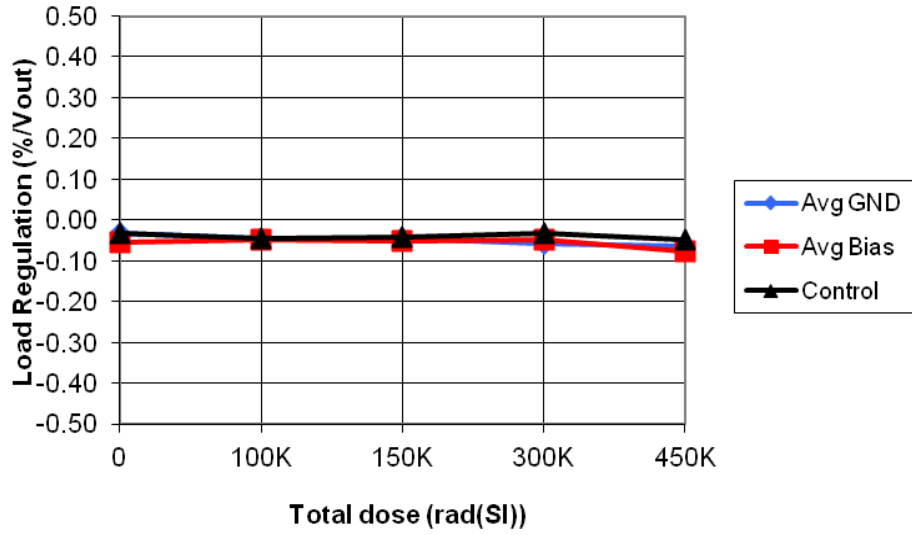
MSK5810KRH  
Feedback Voltage vs. Total Dose



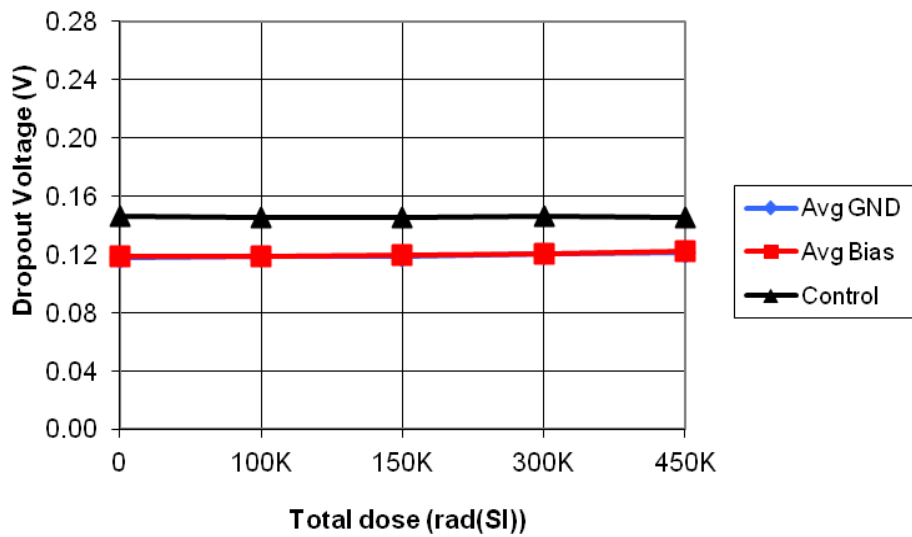
MSK5810KRH  
Line Regulation vs. Total Dose



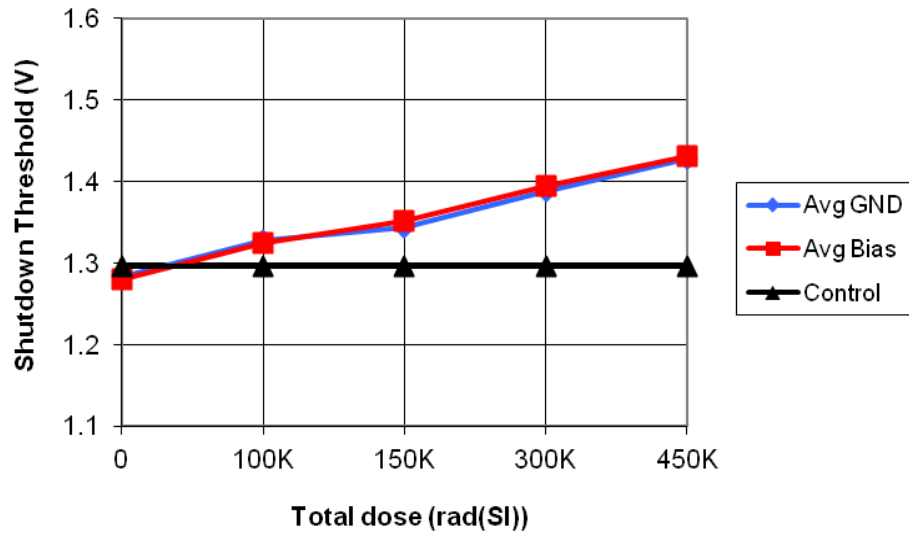
MSK5810KRH  
Load Regulation vs. Total Dose



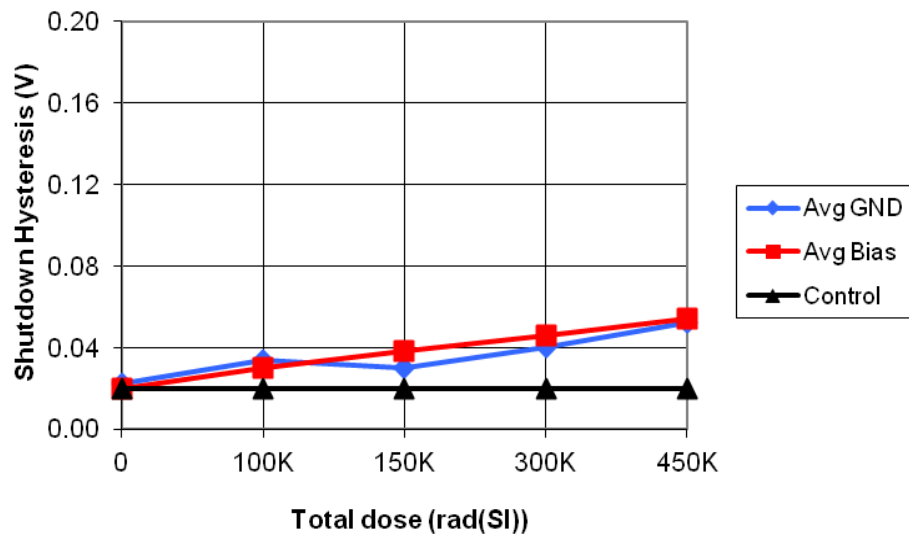
MSK5810KRH  
Dropout Voltage vs. Total Dose



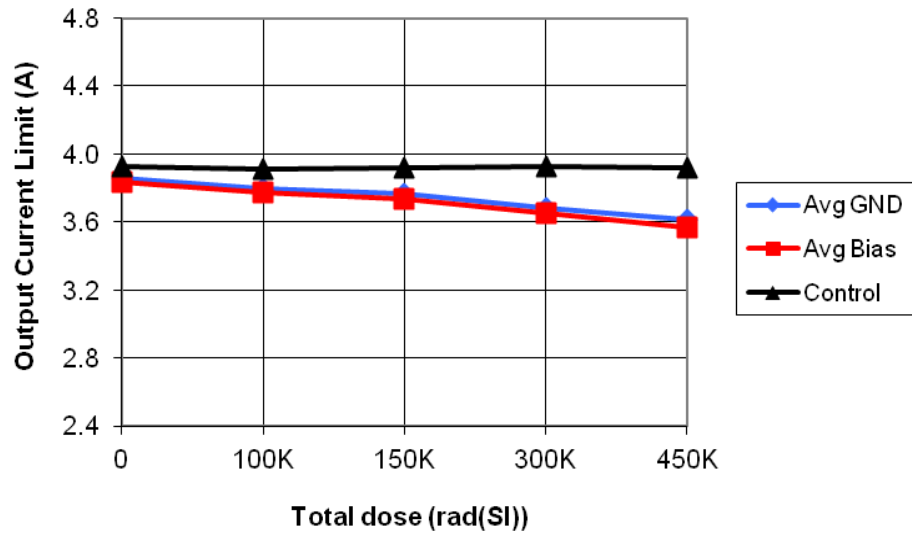
MSK5810KRH  
Shutdown Threshold vs. Total Dose



MSK5810KRH  
Shutdown Hysteresis vs. Total Dose



MSK5810KRH  
Output Current Limit vs. Total Dose





## **Total Dose Radiation Test Report**

### **MSK 5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

November 25, 2008 (MSK 5810RH – 1<sup>st</sup> Test)  
Updated on December 24, 2008  
March 21, 2009 (MSK 5822RH – 1<sup>st</sup> Test)  
March 26, 2009 (MSK 5810RH – 2<sup>nd</sup> Test)  
September 3, 2009 (MSK 5810RH – 3<sup>rd</sup> Test)  
November 6, 2009 (MSK 5810RH – 4<sup>th</sup> Test)  
May 14, 2010 (MSK 5810RH – 5<sup>th</sup> Test)  
September 17, 2010 (MSK 5810RH – 6<sup>th</sup> Test)  
December 10, 2010 (MSK 5810RH – 7<sup>th</sup> Test)  
April 1, 2011 (MSK5810RH – 8<sup>th</sup> Test)  
July 8, 2011 (MSK5810RH – 9<sup>th</sup> Test)  
June 14, 2013 (MSK5810RH – 10<sup>th</sup> Test, IC Wafer Lot: WD0051441#9  
Transistor Wafer Lot: CJ302831#13)  
June 14, 2013 (MSK5810RH – 11<sup>th</sup> Test, IC Wafer Lot: WD0051441#9  
Transistor Wafer Lot: CJ302831#21)  
November 6, 2013 (MSK5810RH – 12<sup>th</sup> Test, IC Wafer Lot: W10809524.1 #8  
Transistor Wafer Lot: CJ302831RC#20)

B. Horton  
R. Wakeman

M.S. Kennedy Corporation  
Liverpool, NY

## **I. Introduction:**

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK 5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 88 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

## **V. Summary:**

Based on the test data recorded during radiation testing, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID

MSK 5810RH Biased/Unbiased Dose Rate Schedule
--------------------------------------------------

Dosimetry Equipment
Bruker Biospin # 0162

Irradiation Date
11/6/13

Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
0:19:31	103,048	103,048
0:09:46	51,568	154,616
0:29:16	154,528	309,144
0:29:16	154,528	463,672

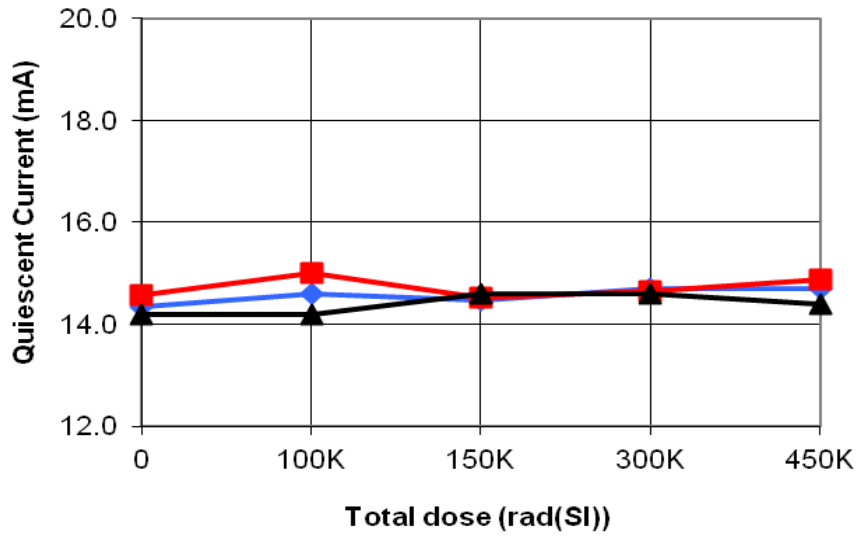
Biased S/N – 1072, 1073, 1075, 1076, 1077
-------------------------------------------

Unbiased S/N – 1078, 1079, 1080, 1081, 1082
---------------------------------------------

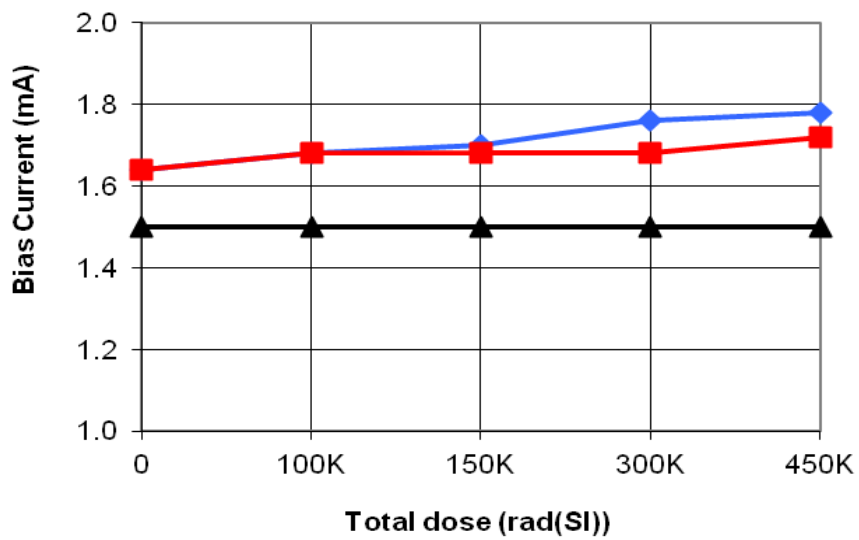
Table 1

**Dose Time, Incremental Dose and Total Cumulative Dose**

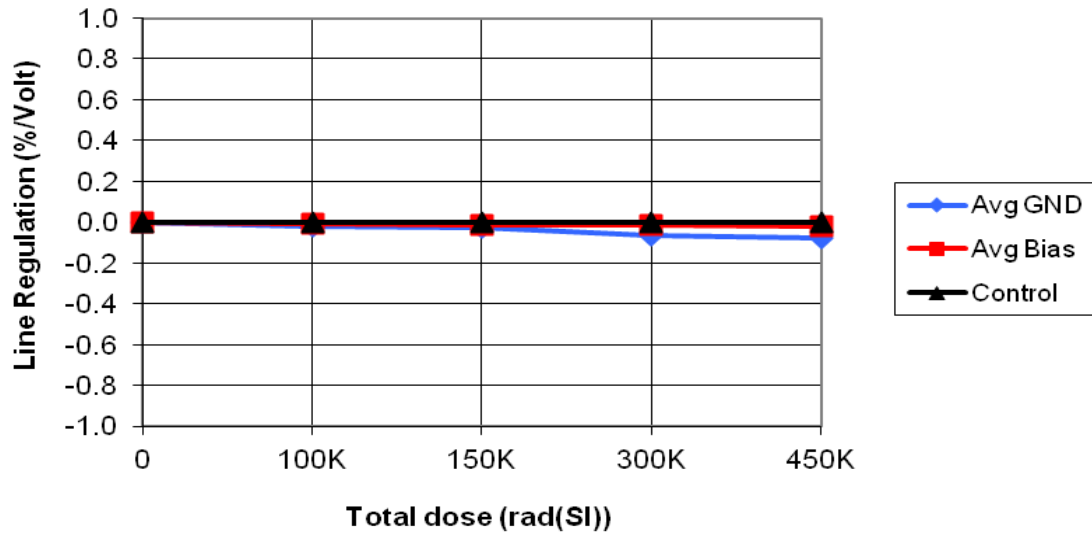
MSK5810KRH  
Quiescent Current vs. Total Dose



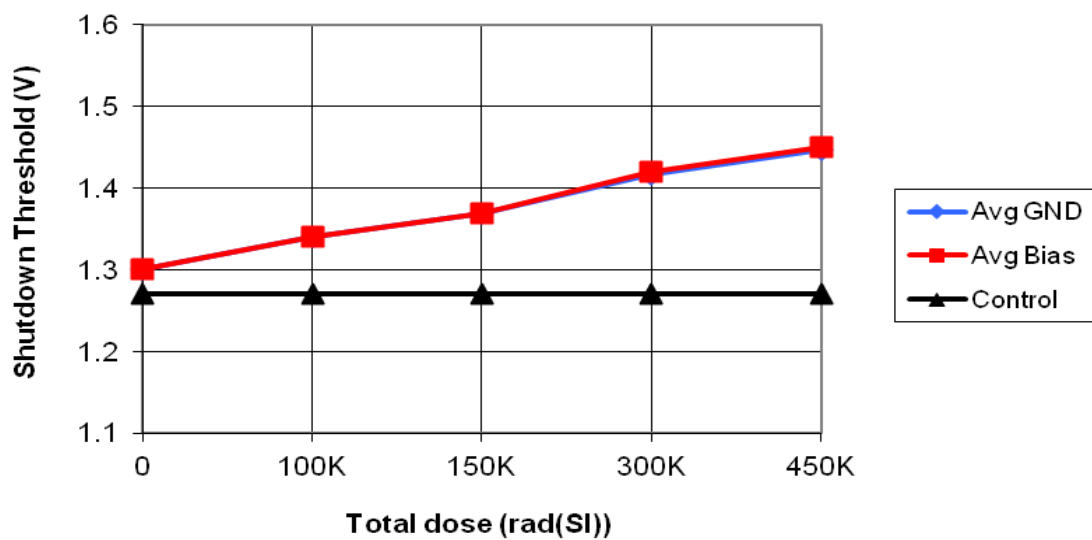
MSK5810KRH  
Bias Current vs. Total Dose



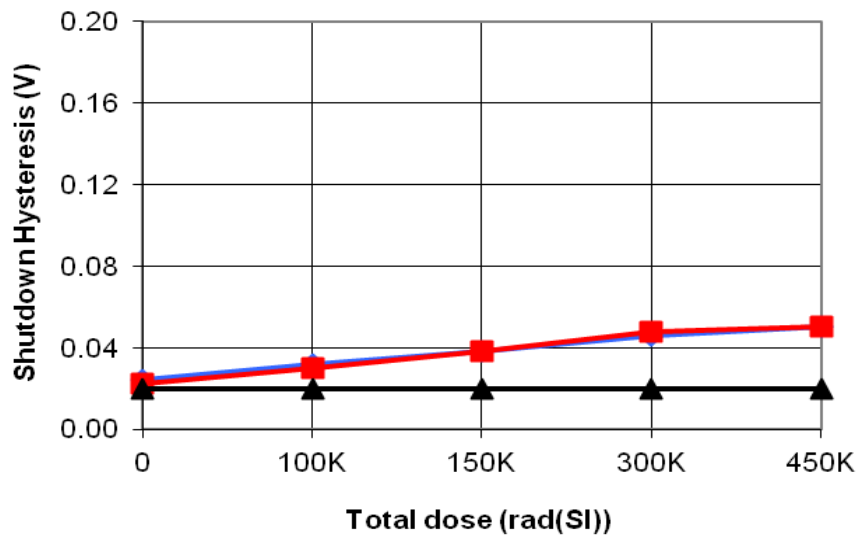
MSK5810KRH  
Line Regulation vs. Total Dose



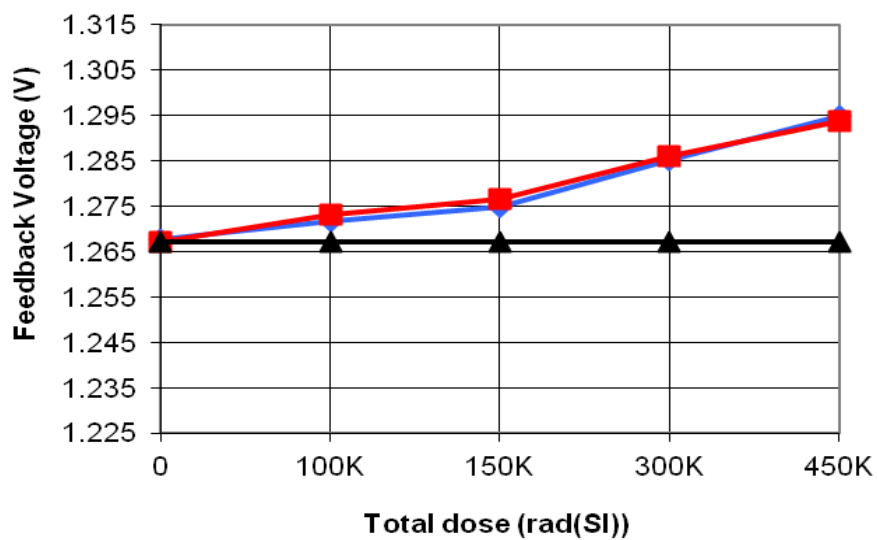
MSK5810KRH  
Shutdown Threshold vs. Total Dose



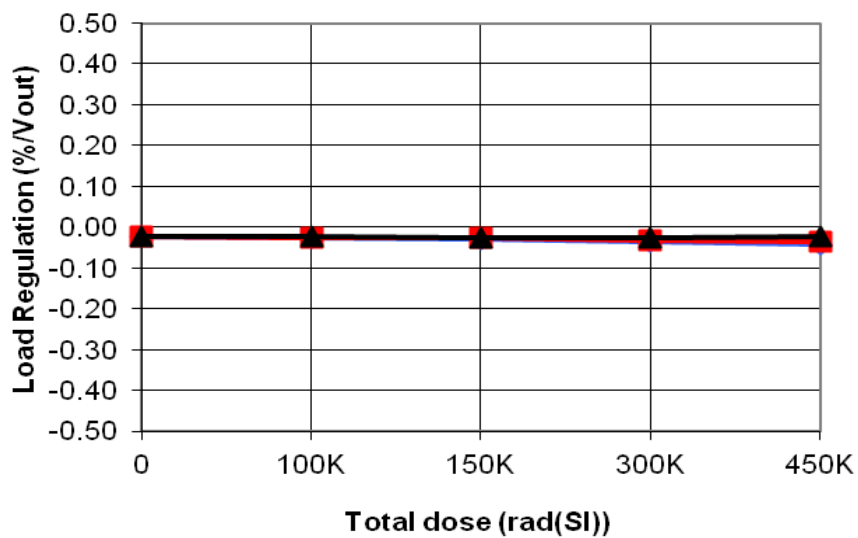
MSK5810KRH  
Shutdown Hysteresis vs. Total Dose



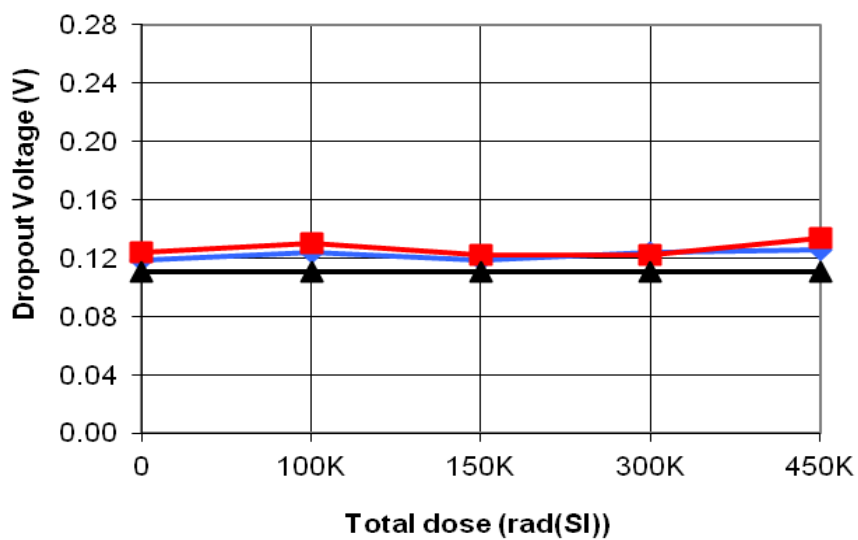
MSK5810KRH  
Feedback Voltage vs. Total Dose



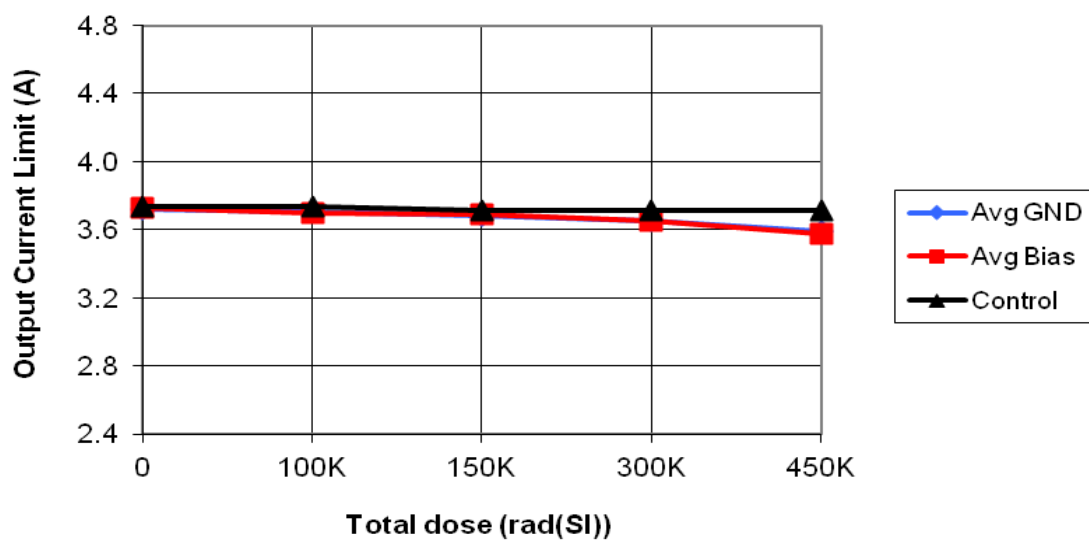
MSK5810KRH  
Load Regulation vs. Total Dose



MSK5810KRH  
Dropout Voltage vs. Total Dose



**MSK5810KRH**  
**Output Current Limit vs. Total Dose**





## **Total Dose Radiation Test Report**

### **MSK 5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

November 25, 2008 (MSK 5810RH – 1<sup>st</sup> Test)  
Updated on December 24, 2008  
March 21, 2009 (MSK 5822RH – 1<sup>st</sup> Test)  
March 26, 2009 (MSK 5810RH – 2<sup>nd</sup> Test)  
September 3, 2009 (MSK 5810RH – 3<sup>rd</sup> Test)  
November 6, 2009 (MSK 5810RH – 4<sup>th</sup> Test)  
May 14, 2010 (MSK 5810RH – 5<sup>th</sup> Test)  
September 17, 2010 (MSK 5810RH – 6<sup>th</sup> Test)  
December 10, 2010 (MSK 5810RH – 7<sup>th</sup> Test)  
April 1, 2011 (MSK5810RH – 8<sup>th</sup> Test)  
July 8, 2011 (MSK5810RH – 9<sup>th</sup> Test)  
June 14, 2013 (MSK5810RH – 10<sup>th</sup> Test, IC Wafer Lot: WD0051441#9  
Transistor Wafer Lot: CJ302831#13)  
June 14, 2013 (MSK5810RH – 10<sup>th</sup> Test, IC Wafer Lot: WD0051441#9  
Transistor Wafer Lot: CJ302831#21)

B. Horton  
C. Salce  
P. Dinneen

M.S. Kennedy Corporation  
Liverpool, NY

**I. Introduction:**

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK 5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

**II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 93 Rads(Si)/sec. The total dose schedule can be found in Table I.

**III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

**IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

**V. Summary:**

Based on the test data recorded during radiation testing, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID

MSK 5810RH Biased/Unbiased Dose Rate Schedule
--------------------------------------------------

Dosimetry Equipment
Bruker Biospin # 0162

Irradiation Date
6/14/13

Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
18:28	103,044	103,044
9:14	51,522	154,566
27:42	154,566	309,132
27:42	154,566	463,698

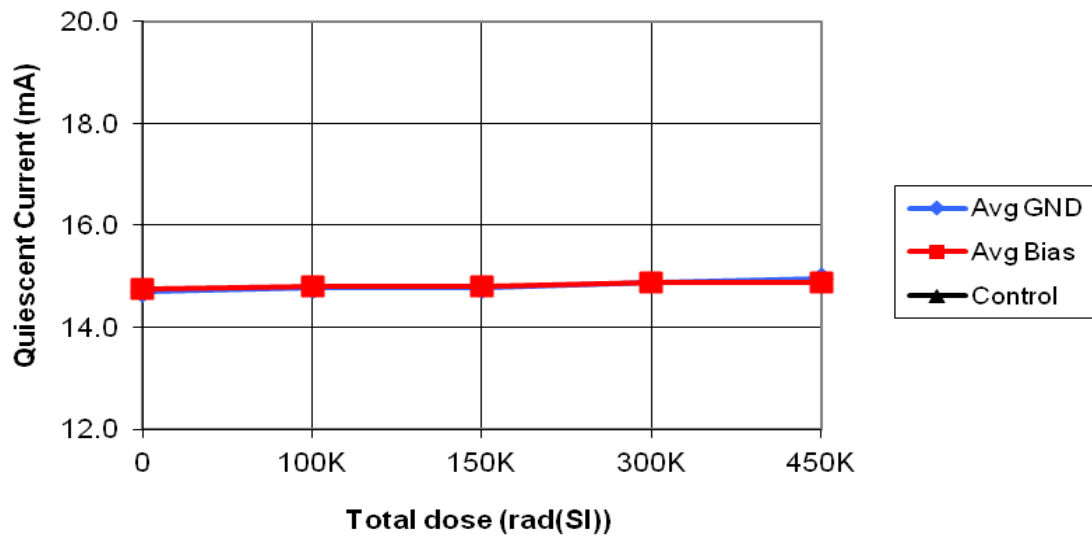
Biased S/N – 0991, 0992, 0993, 0994, 0995
-------------------------------------------

Unbiased S/N – 0996, 0997, 0998, 0999, 1000
---------------------------------------------

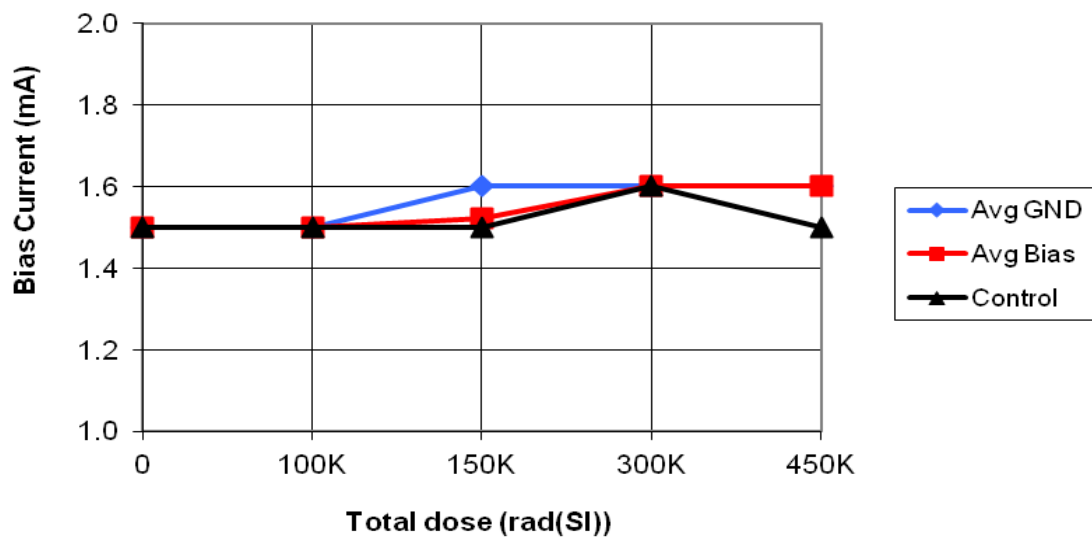
Table 1

**Dose Time, Incremental Dose and Total Cumulative Dose**

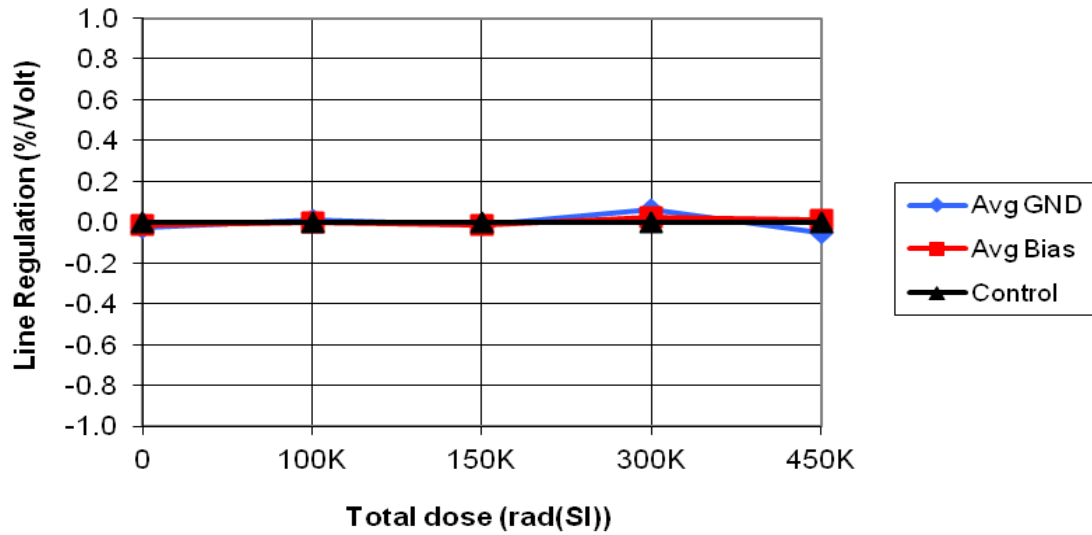
MSK5810KRH  
Quiescent Current vs. Total Dose



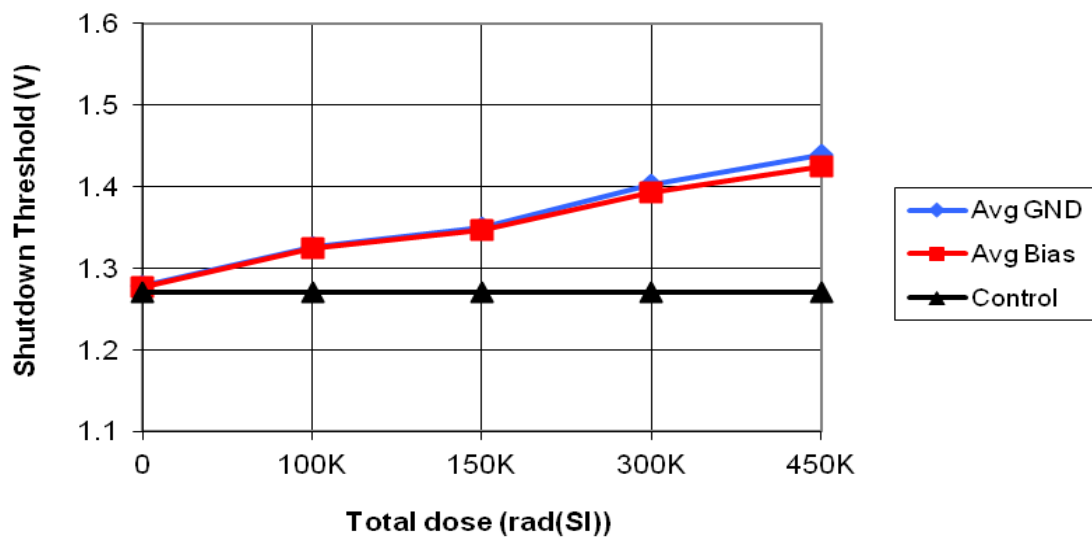
MSK5810KRH  
Bias Current vs. Total Dose



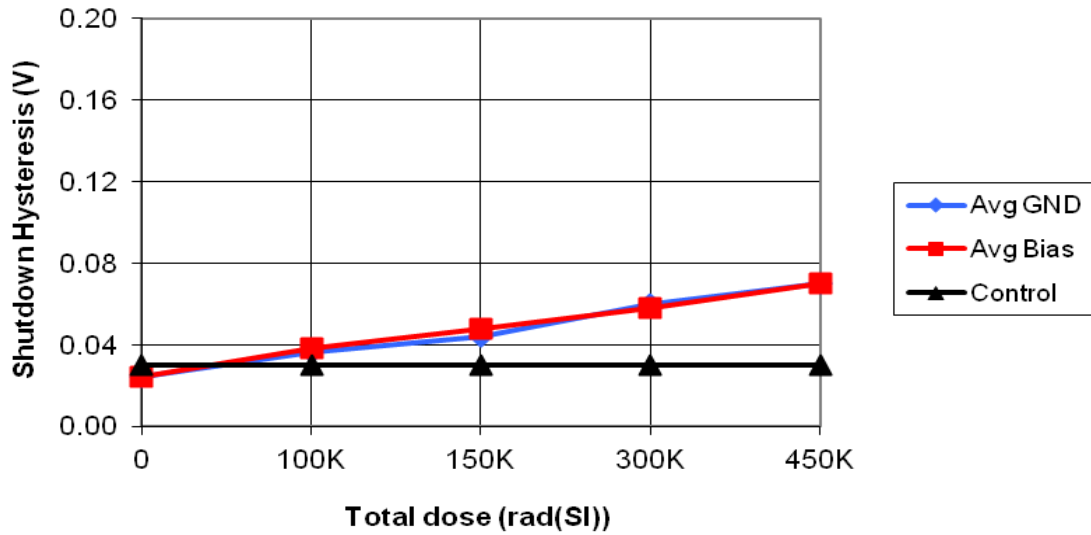
MSK5810KRH  
Line Regulation vs. Total Dose



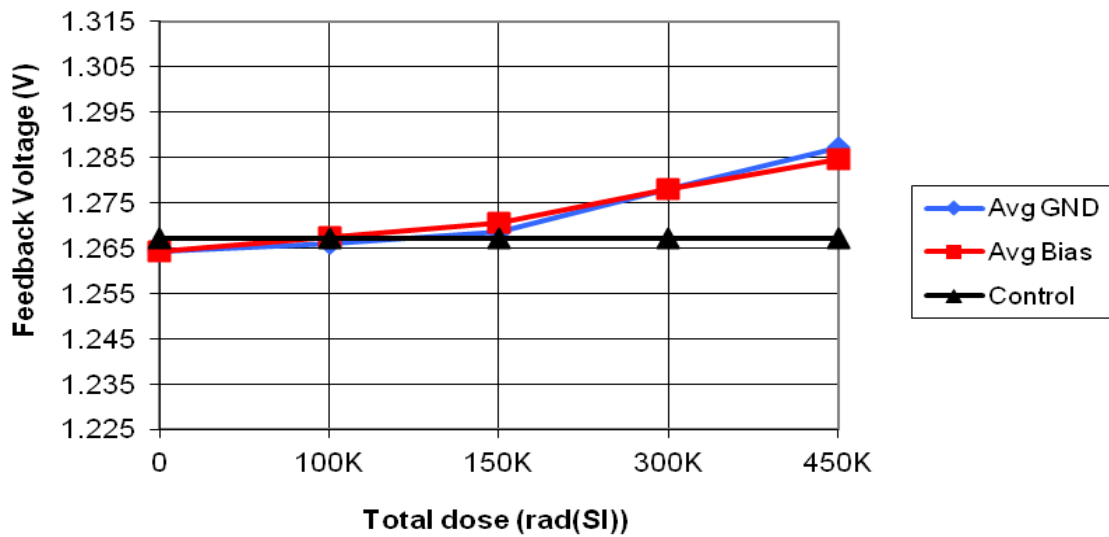
MSK5810KRH  
Shutdown Threshold vs. Total Dose



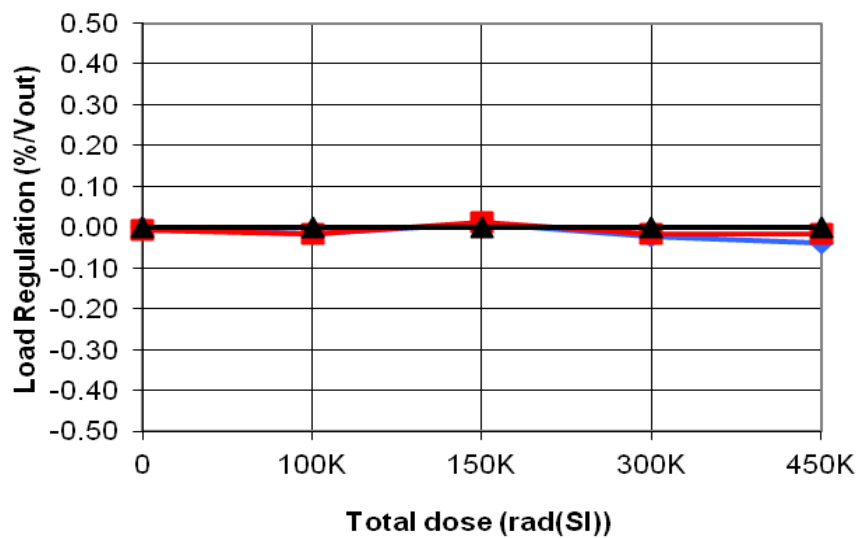
MSK5810KRH  
Shutdown Hysteresis vs. Total Dose



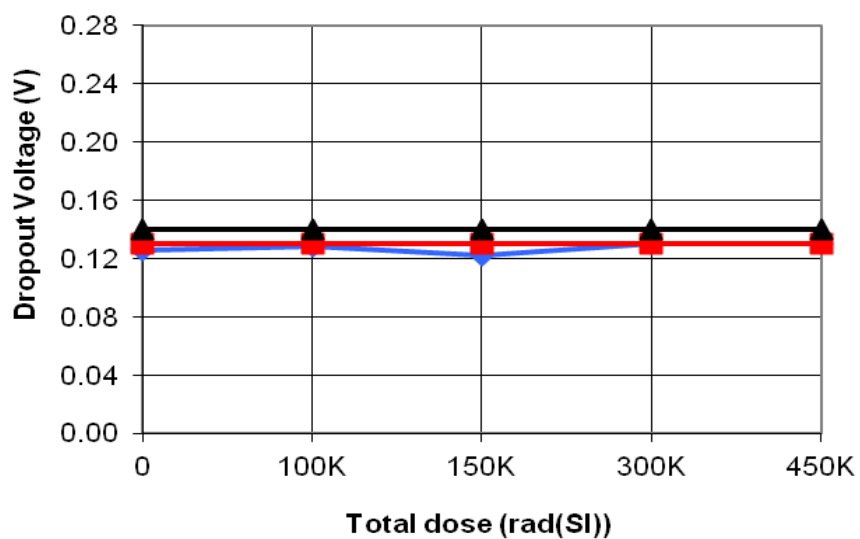
MSK5810KRH  
Feedback Voltage vs. Total Dose



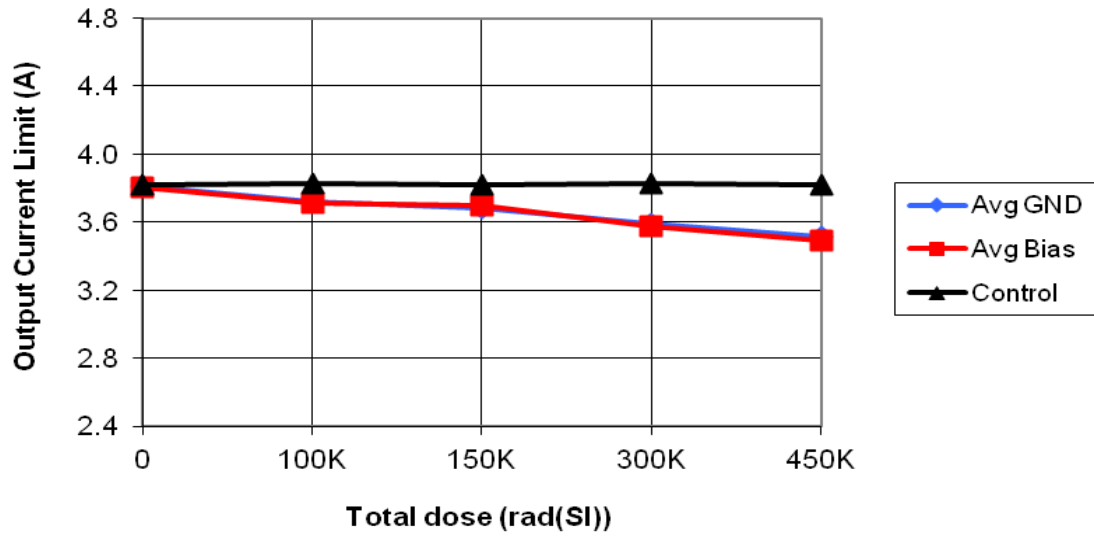
**MSK5810KRH**  
**Load Regulation vs. Total Dose**



**MSK5810KRH**  
**Dropout Voltage vs. Total Dose**



MSK5810KRH  
Output Current Limit vs. Total Dose





## **Total Dose Radiation Test Report**

### **MSK 5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

November 25, 2008 (MSK 5810RH – 1<sup>st</sup> Test)  
Updated on December 24, 2008  
March 21, 2009 (MSK 5822RH – 1<sup>st</sup> Test)  
March 26, 2009 (MSK 5810RH – 2<sup>nd</sup> Test)  
September 3, 2009 (MSK 5810RH – 3<sup>rd</sup> Test)  
November 6, 2009 (MSK 5810RH – 4<sup>th</sup> Test)  
May 14, 2010 (MSK 5810RH – 5<sup>th</sup> Test)  
September 17, 2010 (MSK 5810RH – 6<sup>th</sup> Test)  
December 10, 2010 (MSK 5810RH – 7<sup>th</sup> Test)  
April 1, 2011 (MSK5810RH – 8<sup>th</sup> Test)  
July 8, 2011 (MSK5810RH – 9<sup>th</sup> Test)  
June 14, 2013 (MSK5810RH – 10<sup>th</sup> Test, IC Wafer Lot: WD0051441#9  
Transistor Wafer Lot: CJ302831#13)

B. Horton  
C. Salce  
P. Dinneen

M.S. Kennedy Corporation  
Liverpool, NY

## **I. Introduction:**

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK 5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 93 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

## **V. Summary:**

Based on the test data recorded during radiation testing, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID

MSK 5810RH Biased/Unbiased Dose Rate Schedule
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Dosimetry Equipment
Bruker Biospin # 0162

Irradiation Date
6/14/13

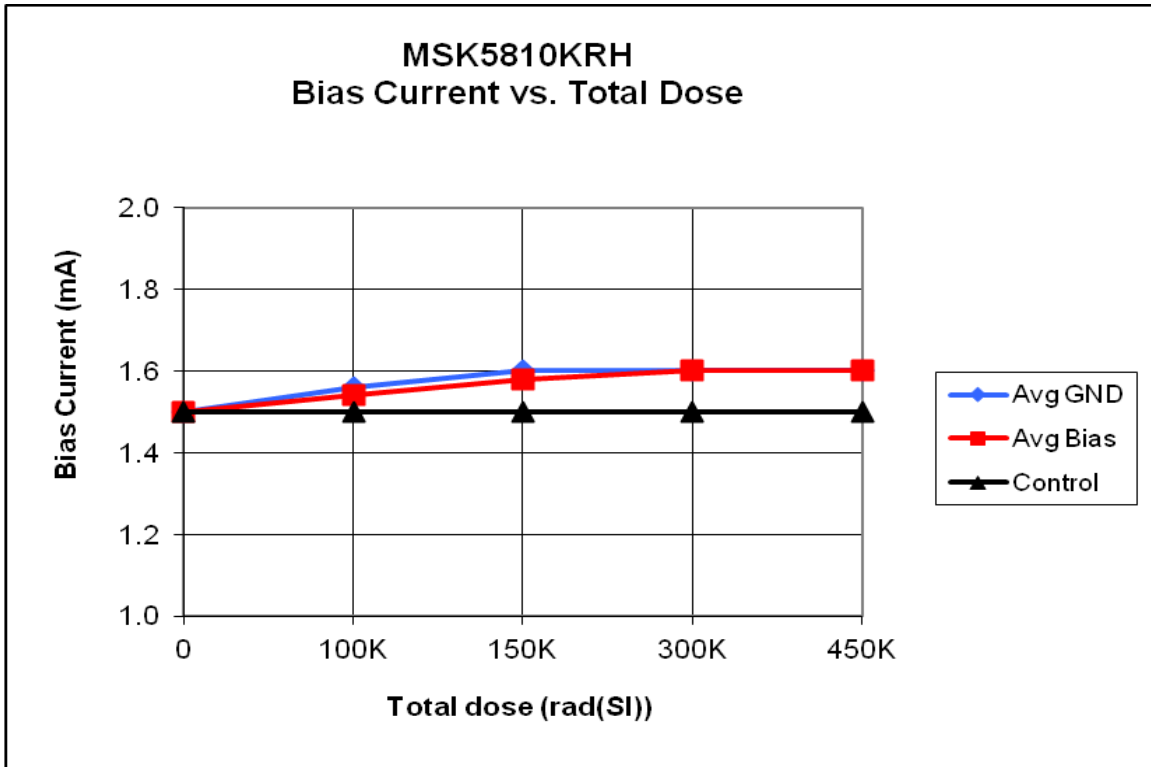
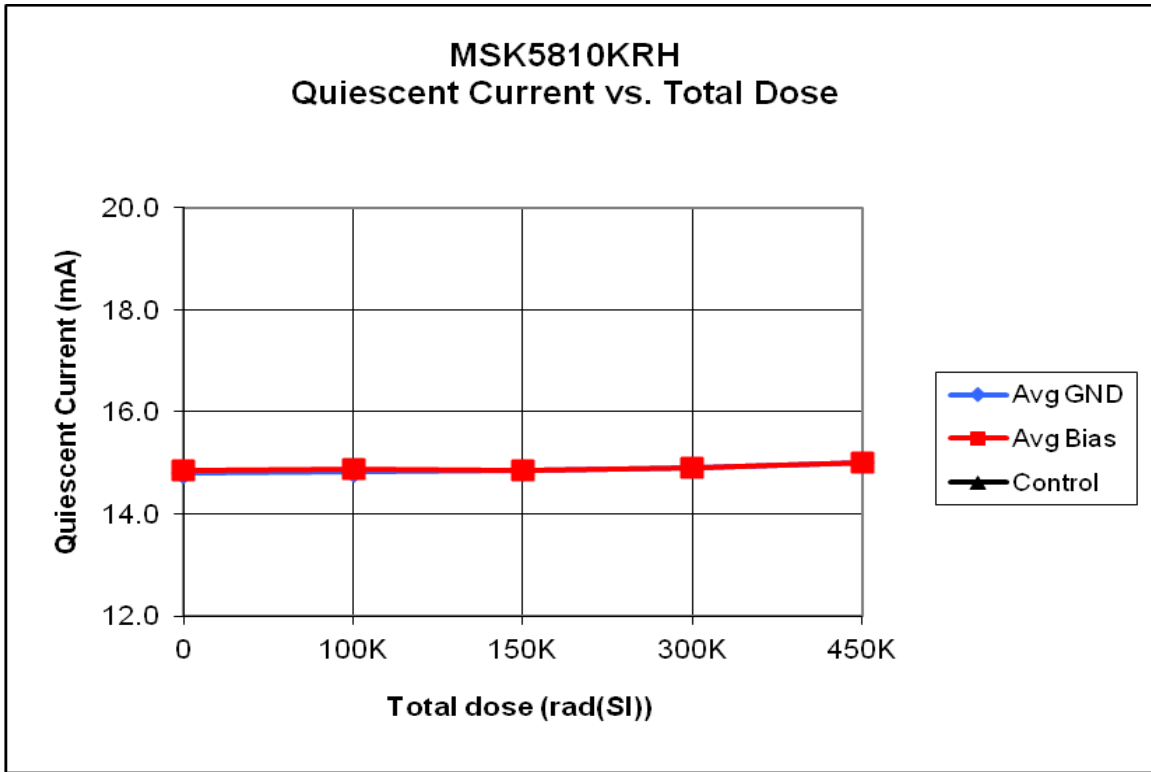
Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
18:28	103,044	103,044
9:14	51,522	154,566
27:42	154,566	309,132
27:42	154,566	463,698

Biased S/N – 0979, 0980, 0981, 0982, 0983
-------------------------------------------

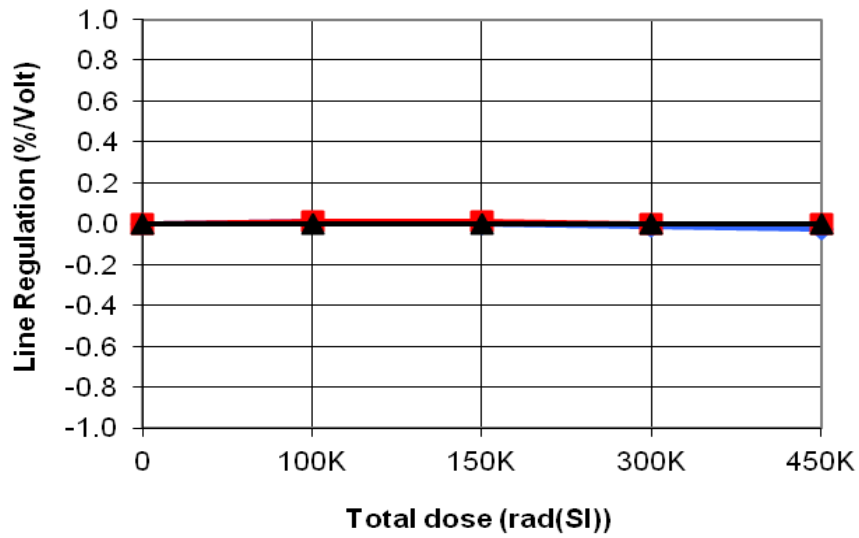
Unbiased S/N – 0984, 0985, 0986, 0987, 0988
---------------------------------------------

Table 1

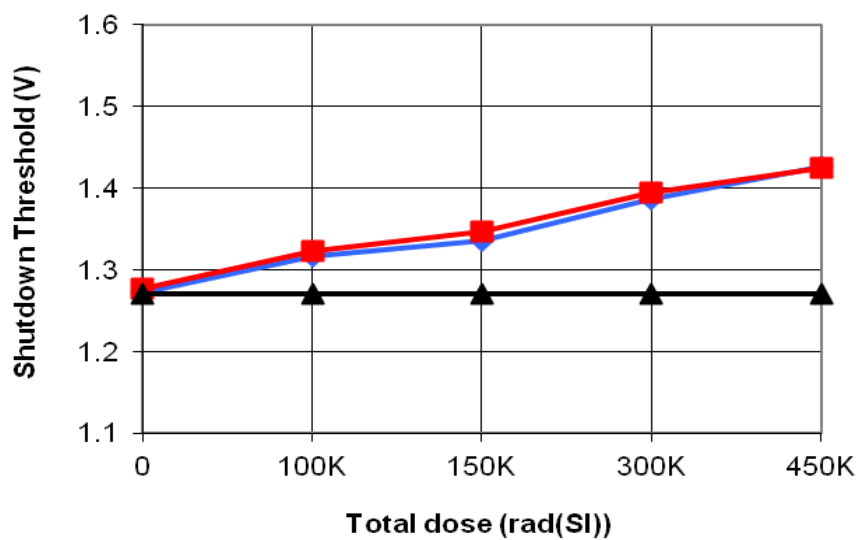
**Dose Time, Incremental Dose and Total Cumulative Dose**



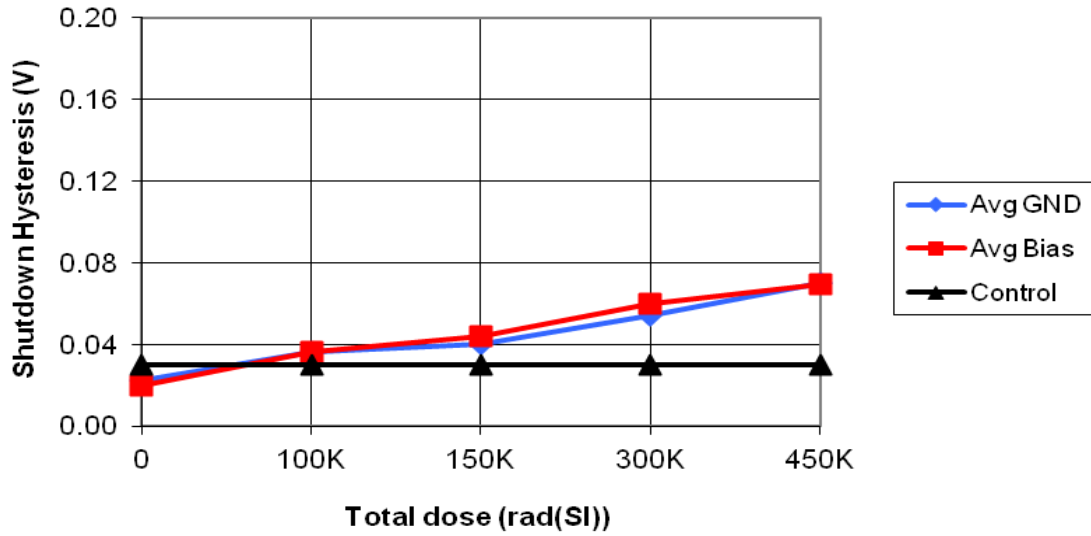
**MSK5810KRH**  
**Line Regulation vs. Total Dose**



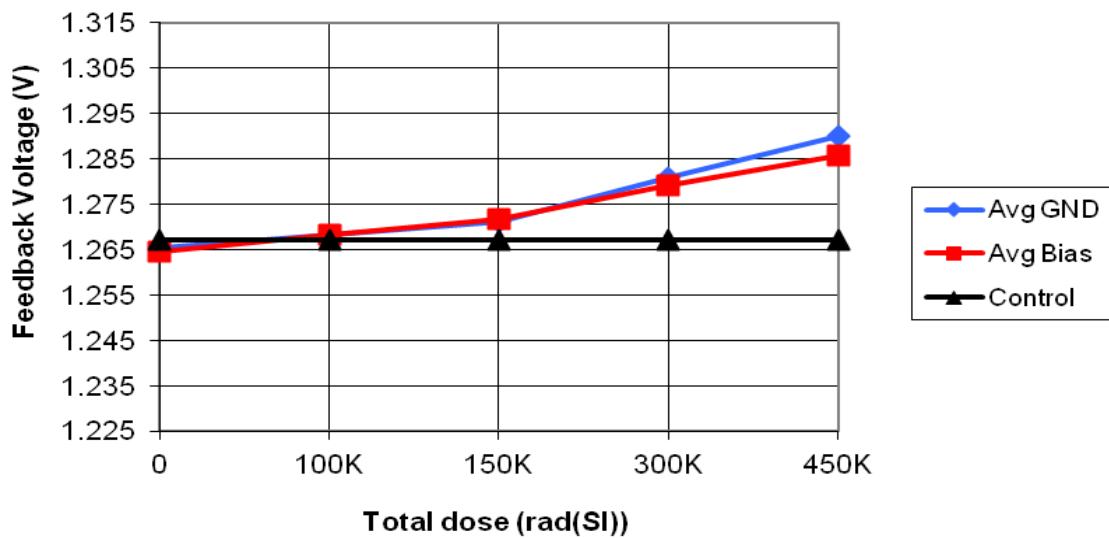
**MSK5810KRH**  
**Shutdown Threshold vs. Total Dose**



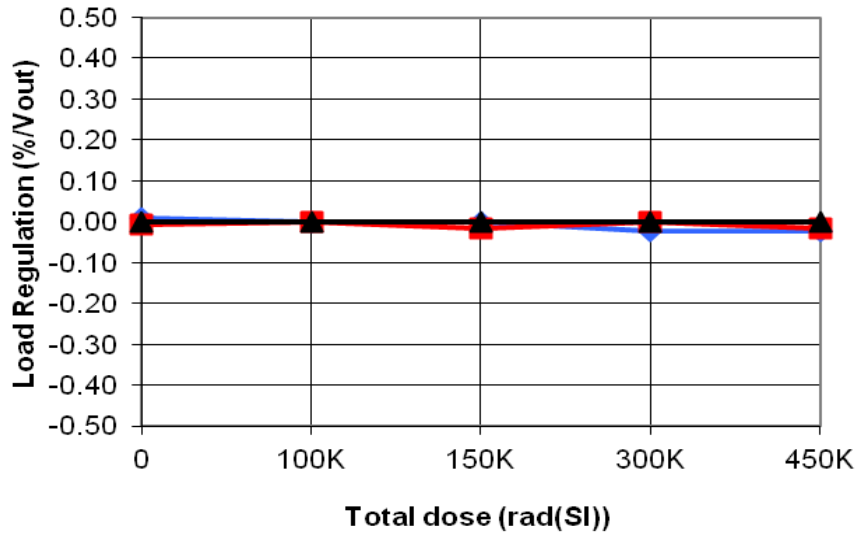
**MSK5810KRH**  
**Shutdown Hysteresis vs. Total Dose**



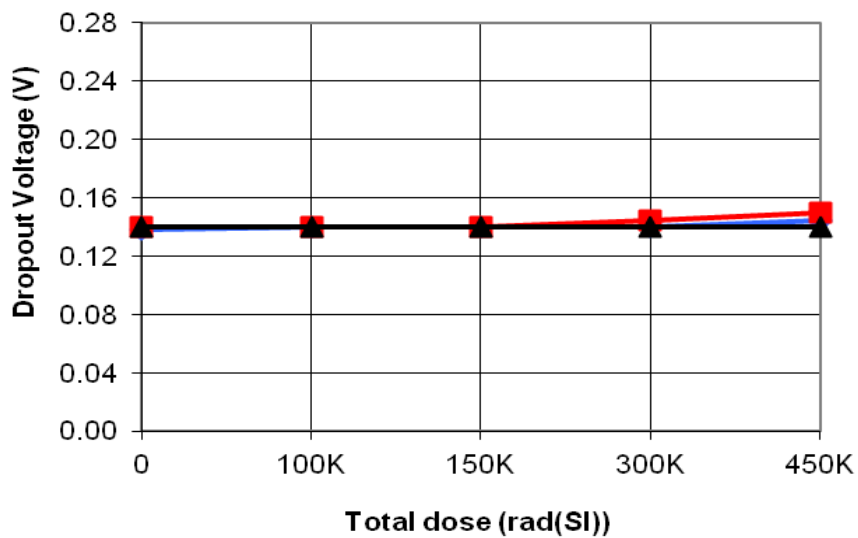
**MSK5810KRH**  
**Feedback Voltage vs. Total Dose**



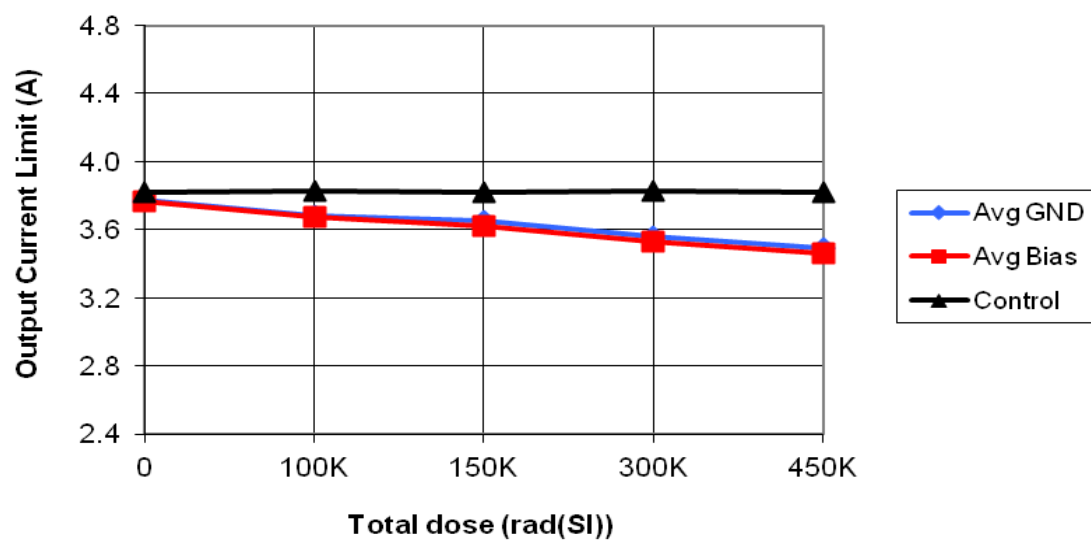
**MSK5810KRH**  
**Load Regulation vs. Total Dose**



**MSK5810KRH**  
**Dropout Voltage vs. Total Dose**



**MSK5810KRH**  
**Output Current Limit vs. Total Dose**





## **Total Dose Radiation Test Report**

### **MSK 5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

November 25, 2008 (MSK 5810RH – 1<sup>st</sup> Test)  
Updated on December 24, 2008  
March 21, 2009 (MSK 5822RH – 1<sup>st</sup> Test)  
March 26, 2009 (MSK 5810RH – 2<sup>nd</sup> Test)  
September 3, 2009 (MSK 5810RH – 3<sup>rd</sup> Test)  
November 6, 2009 (MSK 5810RH – 4<sup>th</sup> Test)  
May 14, 2010 (MSK 5810RH – 5<sup>th</sup> Test)  
September 17, 2010 (MSK 5810RH – 6<sup>th</sup> Test)  
December 10, 2010 (MSK 5810RH – 7<sup>th</sup> Test)  
April 1, 2011 (MSK5810RH – 8<sup>th</sup> Test)  
July 8, 2011 (MSK5810RH – 9<sup>th</sup> Test)

B. Horton  
C. Salce

M.S. Kennedy Corporation  
Liverpool, NY

## **I. Introduction:**

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK 5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 122 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

## **V. Summary:**

Based on the test data recorded during radiation testing, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID

MSK 5810RH Biased/Unbiased Dose Rate Schedule
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Dosimetry Equipment
Bruker Biospin # 0162

Irradiation Date
7/8/11

Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
14:05	103,090	103,090
7:02	51,484	154,574
21:06	154,452	309,026
21:06	154,452	463,478

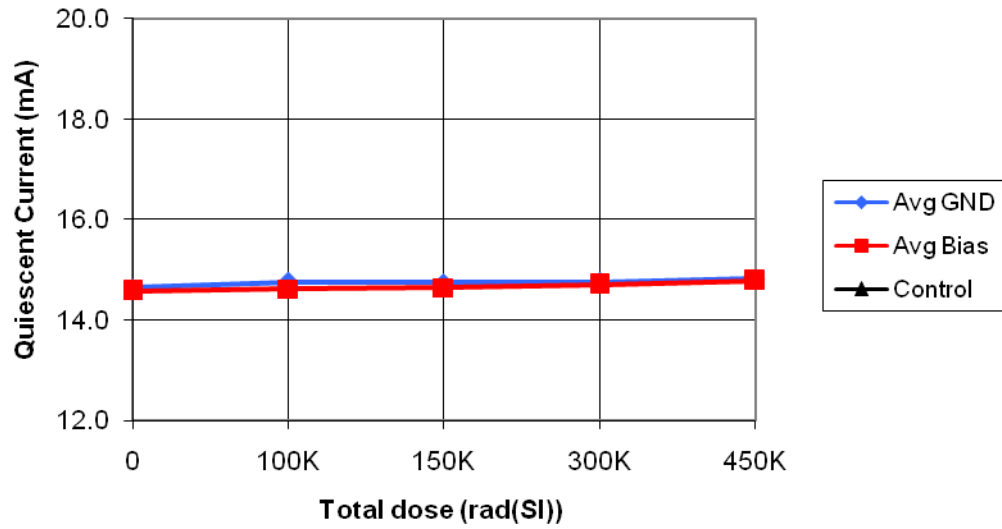
Biased S/N – 0673, 0674, 0675, 0676, 0677
-------------------------------------------

Unbiased S/N – 0678, 0679, 0680, 0681, 0682
---------------------------------------------

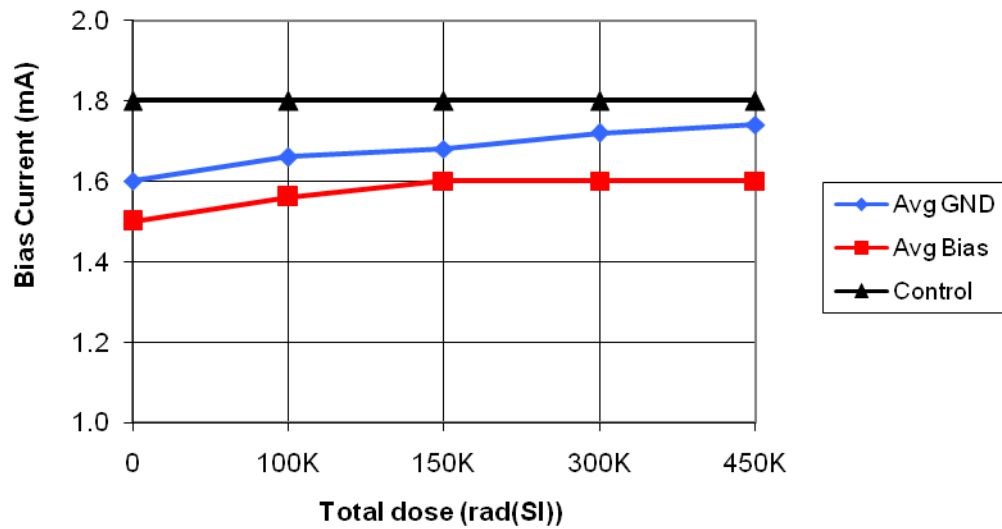
Table 1

**Dose Time, Incremental Dose and Total Cumulative Dose**

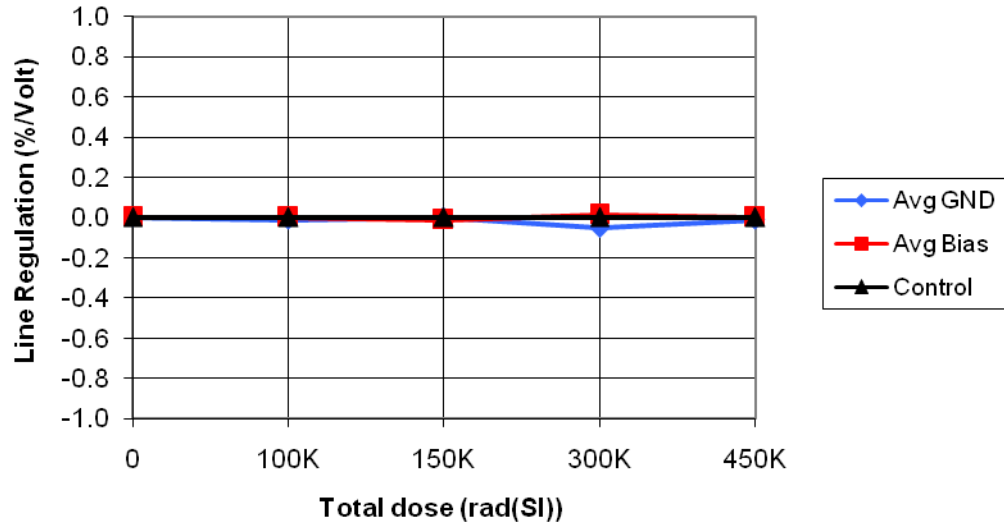
MSK5810KRH  
Quiescent Current vs. Total Dose



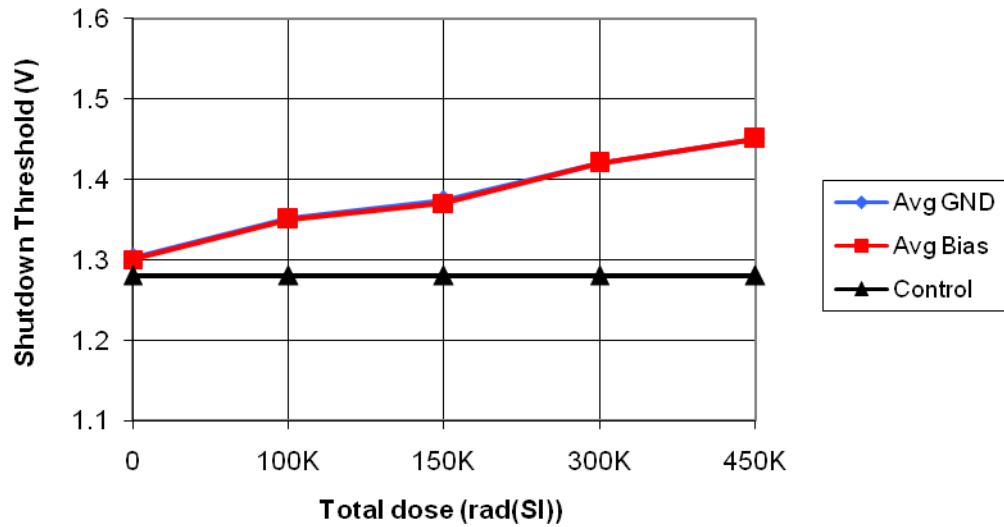
MSK5810KRH  
Bias Current vs. Total Dose



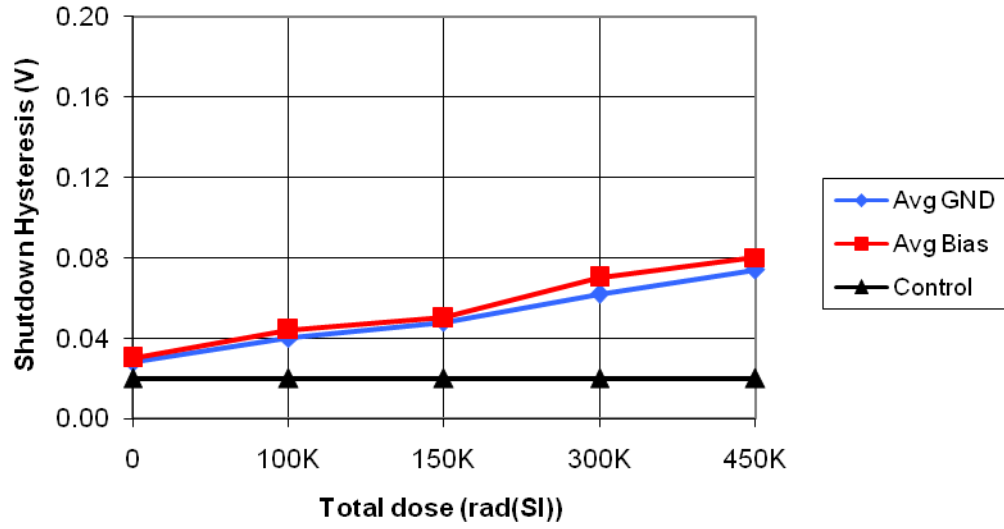
MSK5810KRH  
Line Regulation vs. Total Dose



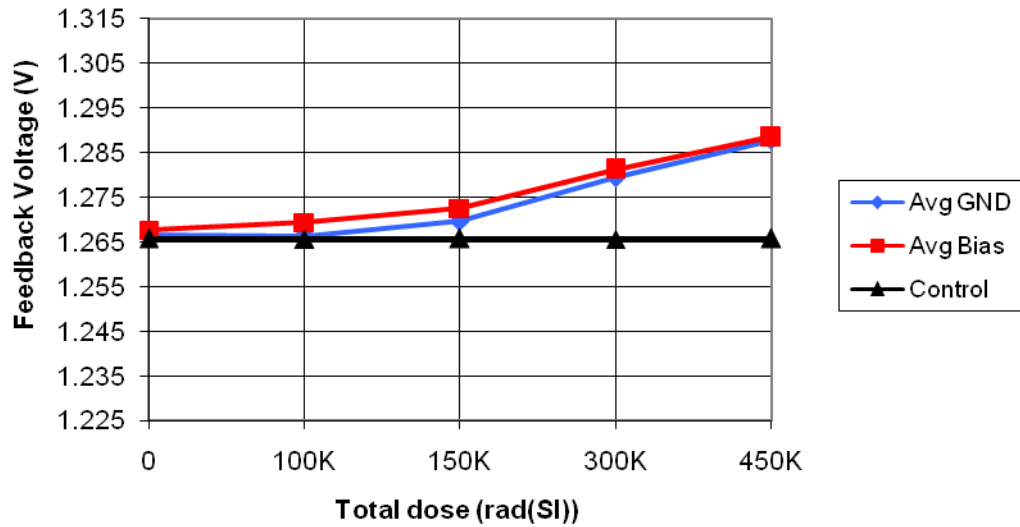
MSK5810KRH  
Shutdown Threshold vs. Total Dose



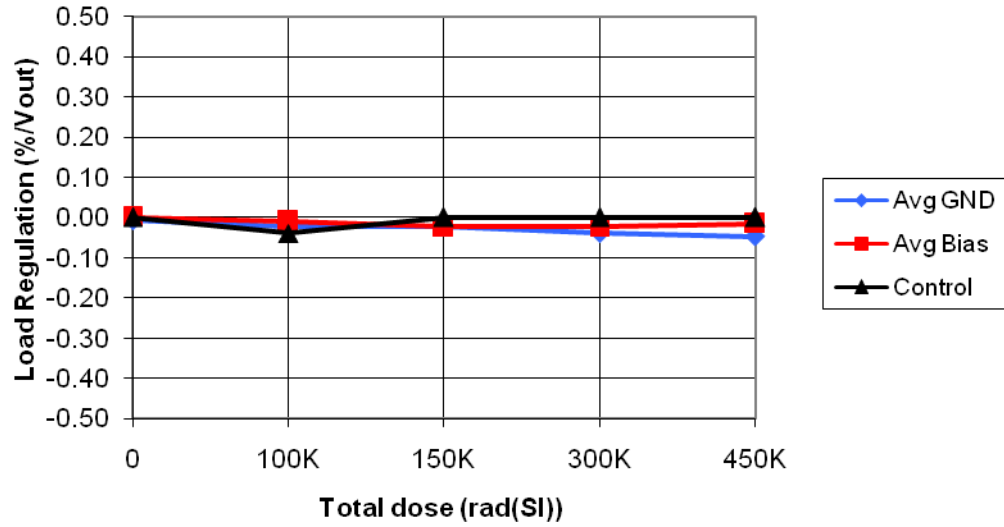
MSK5810KRH  
Shutdown Hysteresis vs. Total Dose



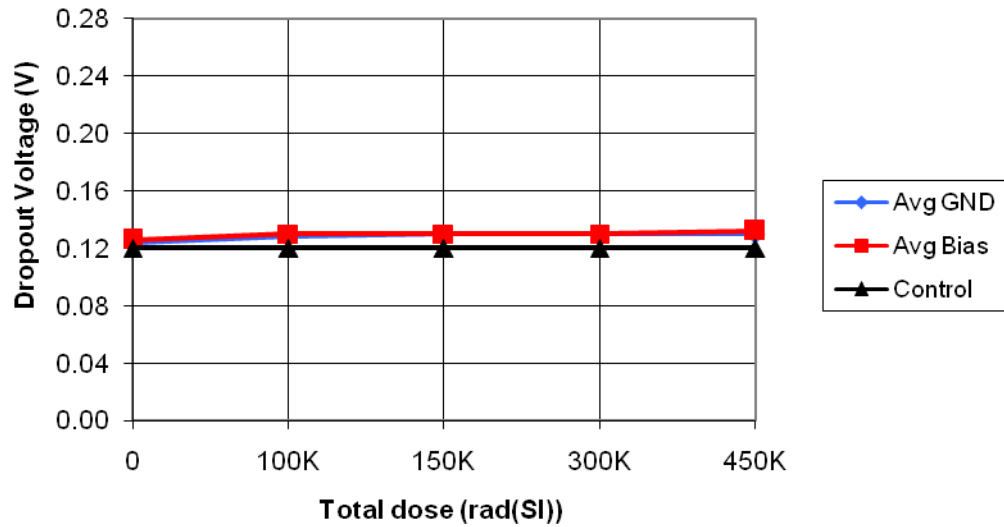
MSK5810KRH  
Feedback Voltage vs. Total Dose



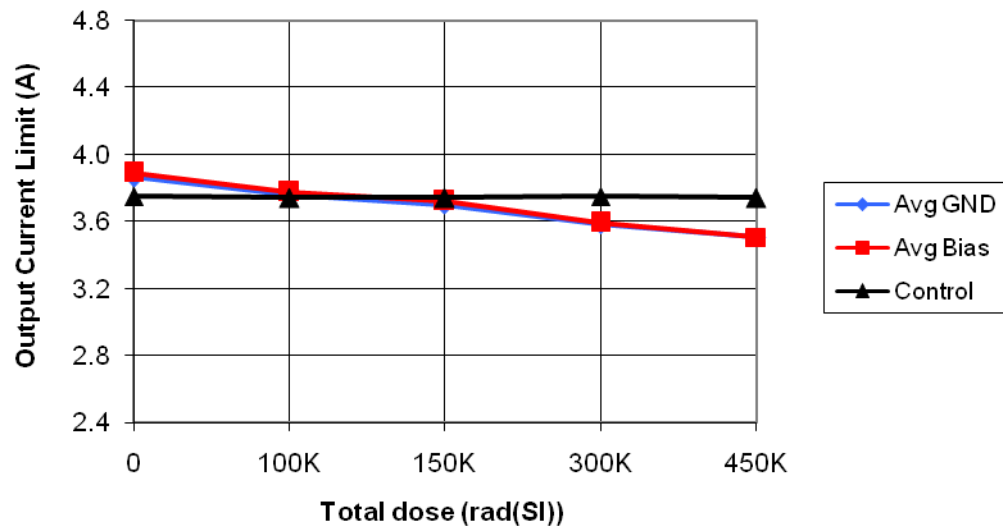
**MSK5810KRH**  
**Load Regulation vs. Total Dose**



**MSK5810KRH**  
**Dropout Voltage vs. Total Dose**



MSK5810KRH  
Output Current Limit vs. Total Dose





## **Total Dose Radiation Test Report**

### **MSK 5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

November 25, 2008 (MSK 5810RH – 1<sup>st</sup> Test)  
Updated on December 24, 2008  
March 21, 2009 (MSK 5822RH – 1<sup>st</sup> Test)  
March 26, 2009 (MSK 5810RH – 2<sup>nd</sup> Test)  
September 3, 2009 (MSK 5810RH – 3<sup>rd</sup> Test)  
November 6, 2009 (MSK 5810RH – 4<sup>th</sup> Test)  
May 14, 2010 (MSK 5810RH – 5<sup>th</sup> Test)  
September 17, 2010 (MSK 5810RH – 6<sup>th</sup> Test)  
December 10, 2010 (MSK 5810RH – 7<sup>th</sup> Test)  
April 1, 2011 (MSK5810RH – 8<sup>th</sup> Test)

M. Bilecki  
B. Erwin

M.S. Kennedy Corporation  
Liverpool, NY

## **I. Introduction:**

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK 5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 125 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

## **V. Summary:**

Based on the test data recorded during radiation testing, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID

MSK 5810RH Biased/Unbiased Dose Rate Schedule
--------------------------------------------------

Dosimetry Equipment
Bruker Biospin # 0162

Irradiation Date
4/1/11

Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
13:44	103,000	103,000
6:52	51,500	154,500
20:36	154,500	309,000
20:36	154,500	463,500

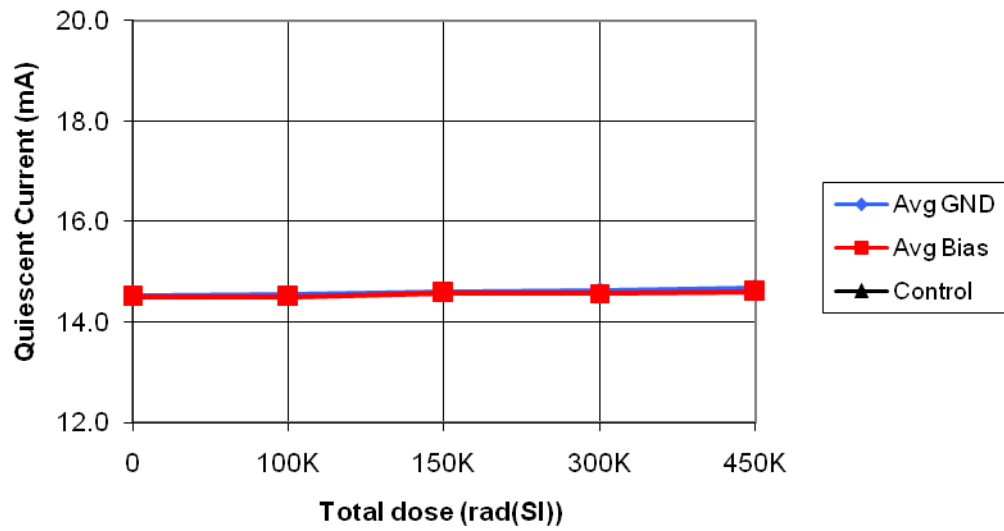
Biased S/N – 0762, 0763, 0764, 0765, 0766
-------------------------------------------

Unbiased S/N – 0757, 0758, 0759, 0760, 0761
---------------------------------------------

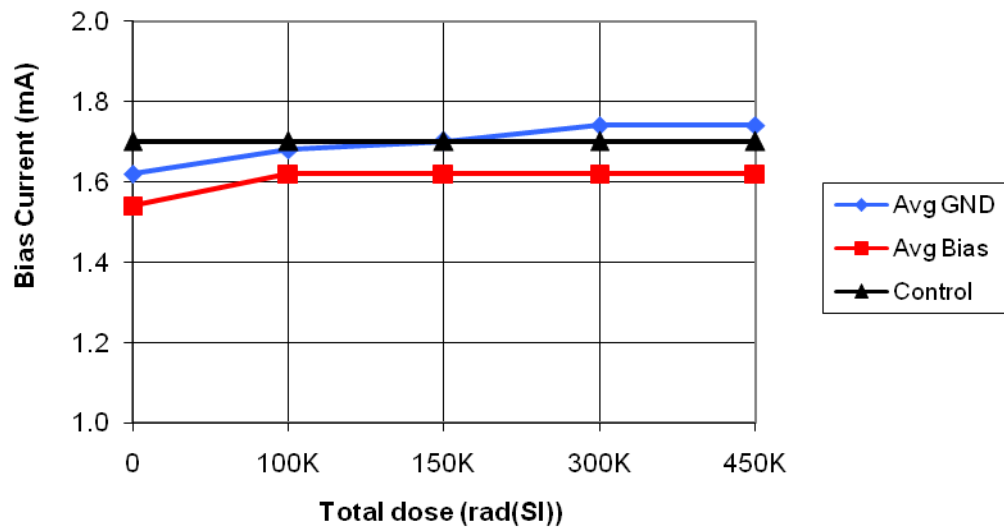
Table 1

**Dose Time, Incremental Dose and Total Cumulative Dose**

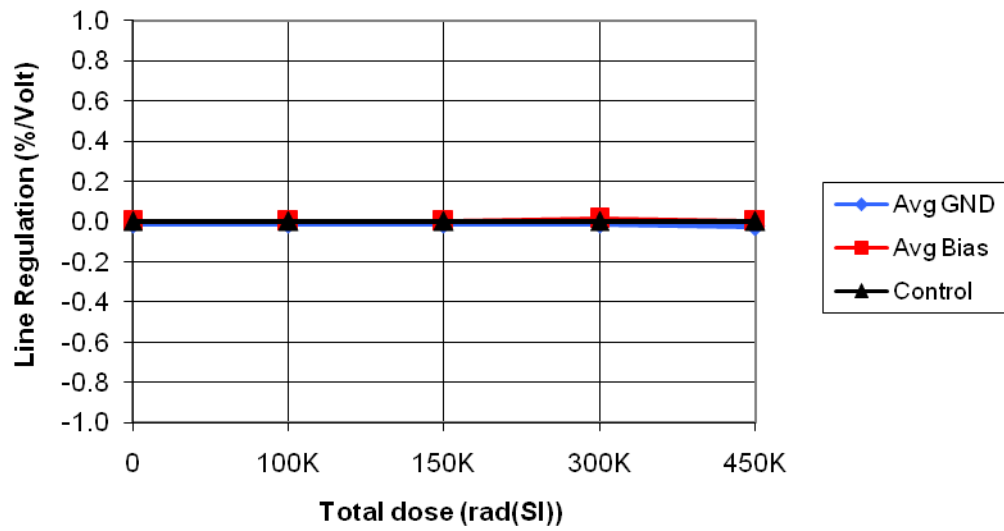
**MSK5810KRH**  
**Quiescent Current vs. Total Dose**



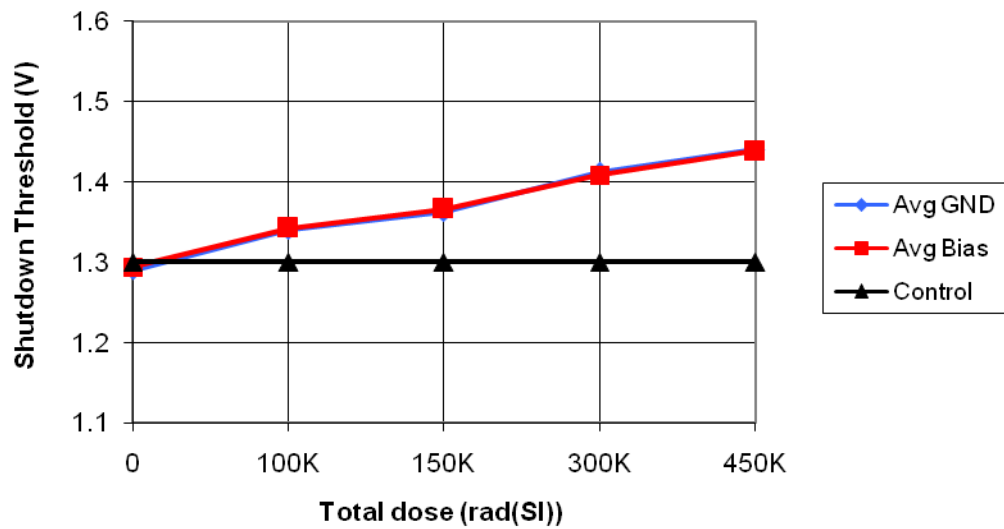
**MSK5810KRH**  
**Bias Current vs. Total Dose**



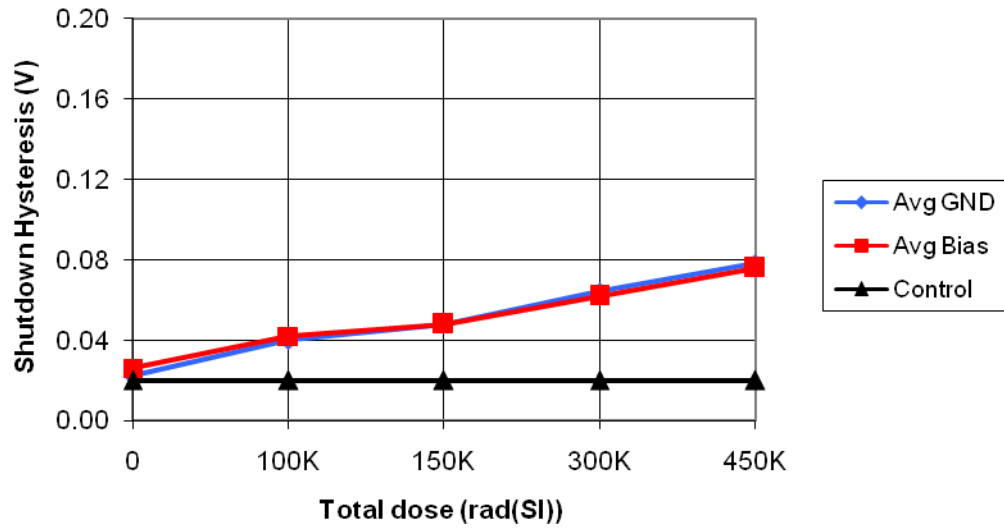
MSK5810KRH  
Line Regulation vs. Total Dose



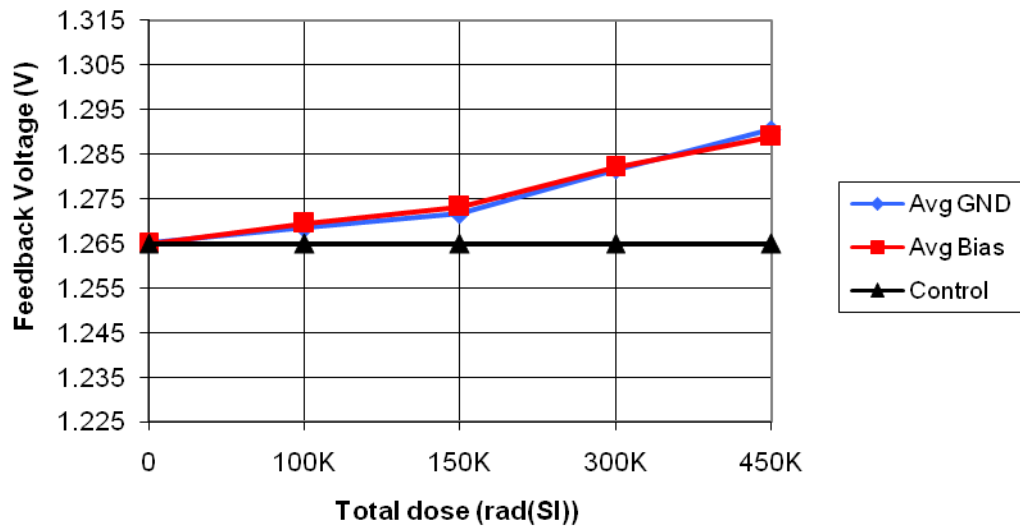
MSK5810KRH  
Shutdown Threshold vs. Total Dose



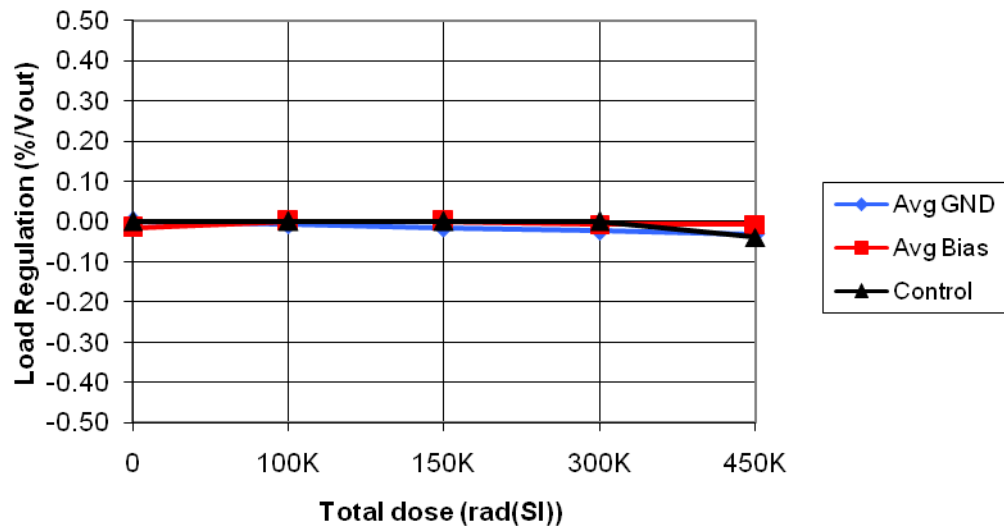
MSK5810KRH  
Shutdown Hysteresis vs. Total Dose



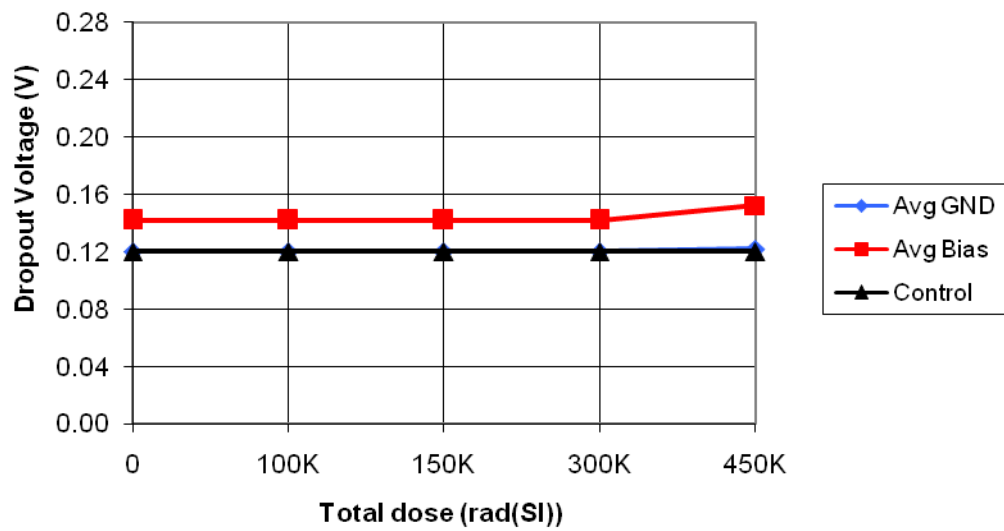
MSK5810KRH  
Feedback Voltage vs. Total Dose



MSK5810KRH  
Load Regulation vs. Total Dose

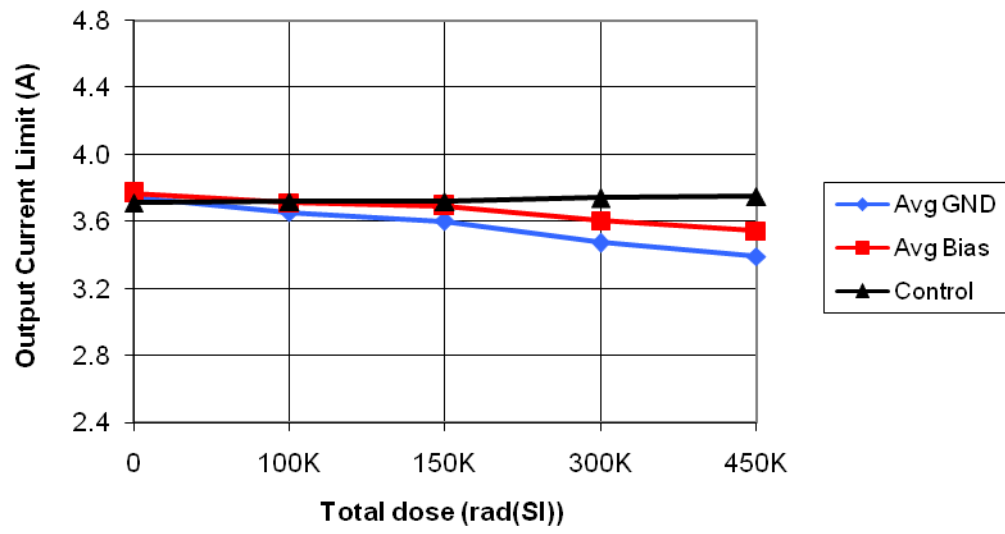


MSK5810KRH  
Dropout Voltage vs. Total Dose



# MSK5810KRH

## Output Current Limit vs. Total Dose





## **Total Dose Radiation Test Report**

### **MSK 5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

November 25, 2008 (MSK 5810RH – 1<sup>st</sup> Test)  
Updated on December 24, 2008  
March 21, 2009 (MSK 5822RH – 1<sup>st</sup> Test)  
March 26, 2009 (MSK 5810RH – 2<sup>nd</sup> Test)  
September 3, 2009 (MSK 5810RH – 3<sup>rd</sup> Test)  
November 6, 2009 (MSK 5810RH – 4<sup>th</sup> Test)  
May 14, 2010 (MSK 5810RH – 5<sup>th</sup> Test)  
September 17, 2010 (MSK 5810RH – 6<sup>th</sup> Test)  
December 10, 2010 (MSK 5810RH – 7<sup>th</sup> Test)

B. Erwin  
R. Wakeman

M.S. Kennedy Corporation  
Liverpool, NY

## **I. Introduction:**

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK 5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 132 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Nine devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Four devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

## **V. Summary:**

Based on the test data recorded during radiation testing, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID

MSK 5810RH Biased/Unbiased Dose Rate Schedule
--------------------------------------------------

Dosimetry Equipment
Bruker Biospin # 0162

Irradiation Date
12/10/10

Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
6:43	51,584	51,584
6:43	51,584	103,168
6:43	51,584	154,752
6:43	51,584	206,336
13:25	103,040	309,376
20:07	154,496	463,872

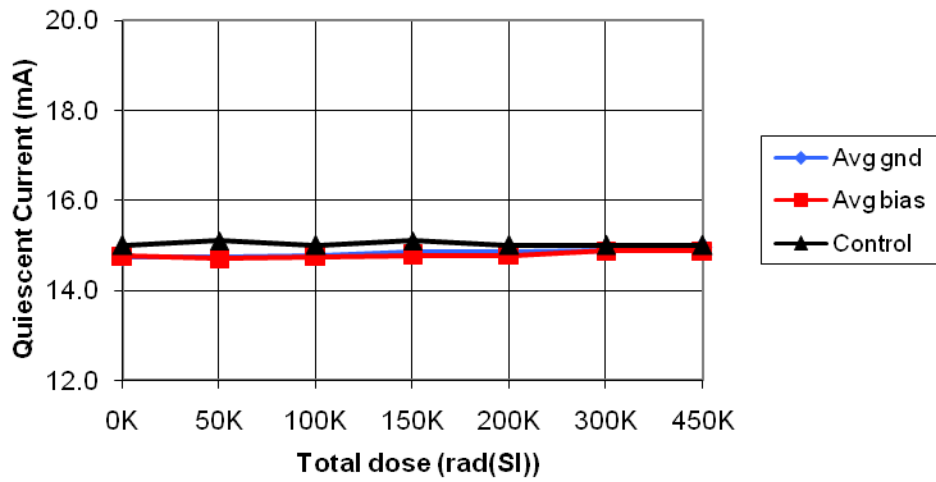
Biased S/N – 0538, 0539, 0540, 0541, 0542
-------------------------------------------

Unbiased S/N – 0543, 0544, 0545, 0546, 0547
---------------------------------------------

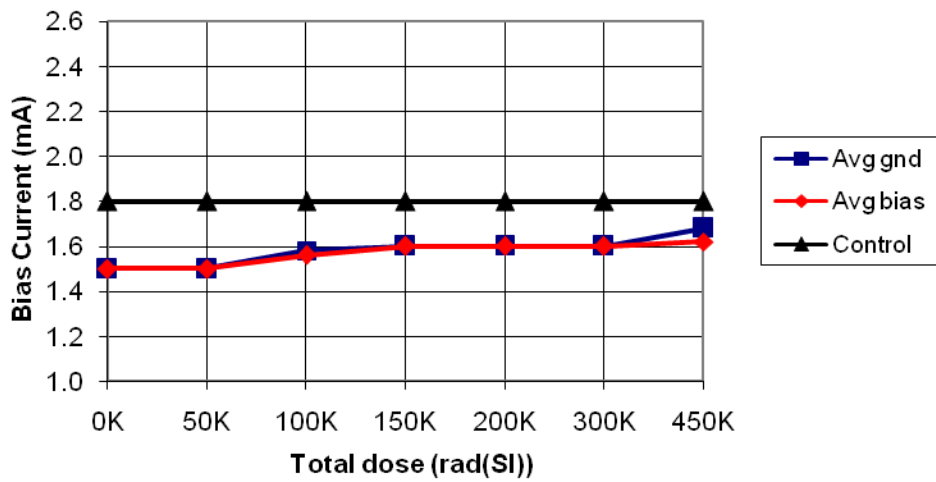
Table 1

**Dose Time, Incremental Dose and Total Cumulative Dose**

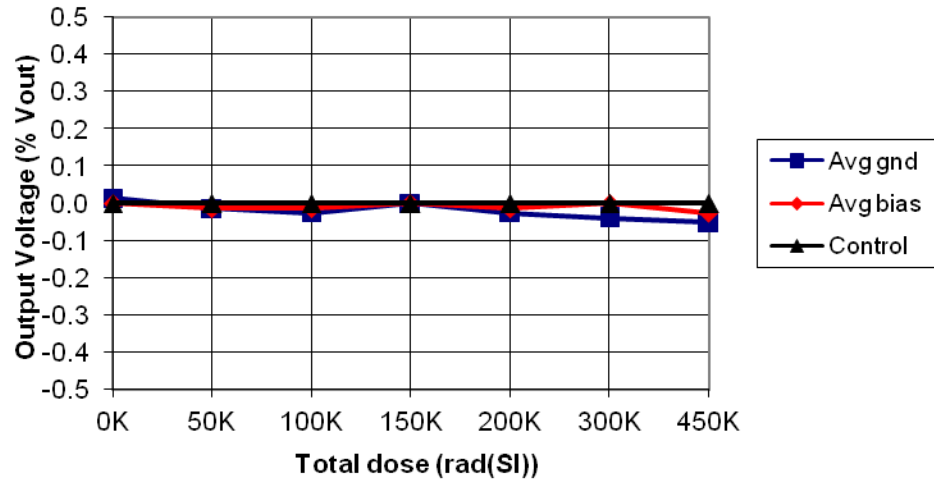
**MSK5810RH**  
**Quiescent Current vs. Total Dose**



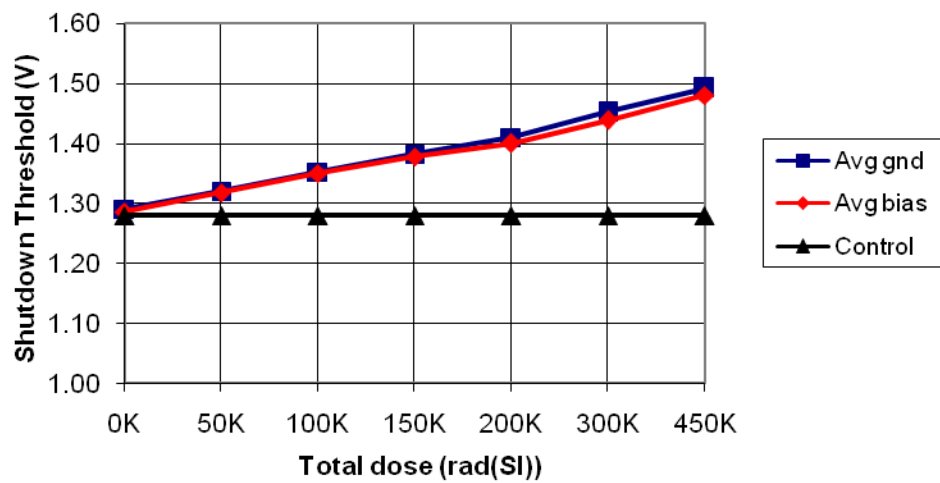
**MSK5810RH**  
**Bias Current vs. Total Dose**



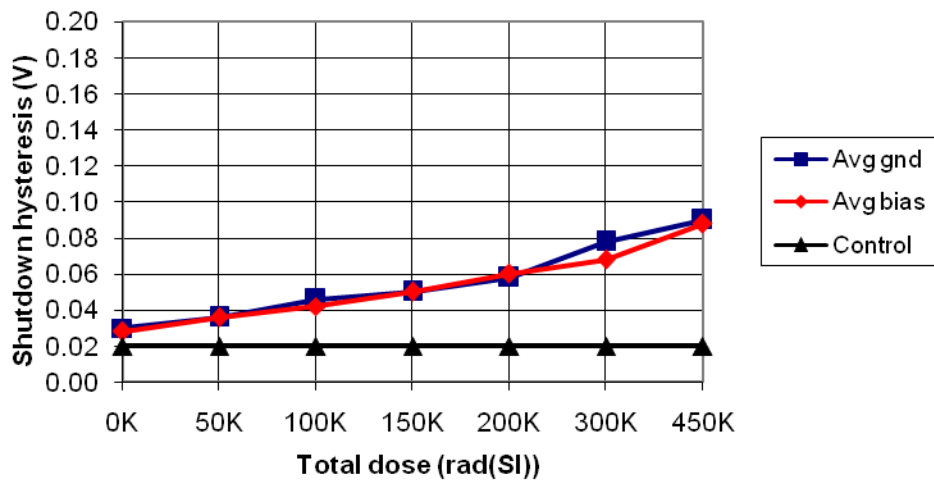
MSK5810RH  
Line Regulation vs. Total Dose



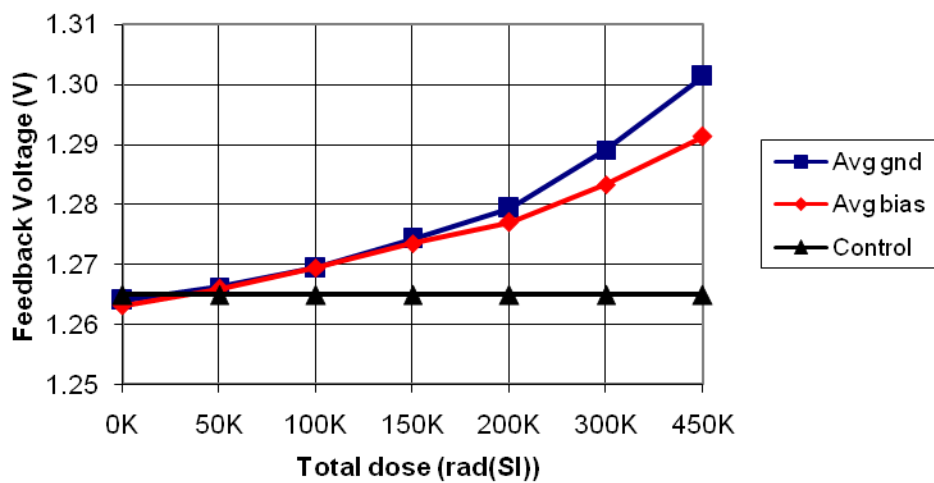
MSK5810RH  
Shutdown Threshold vs. Total Dose



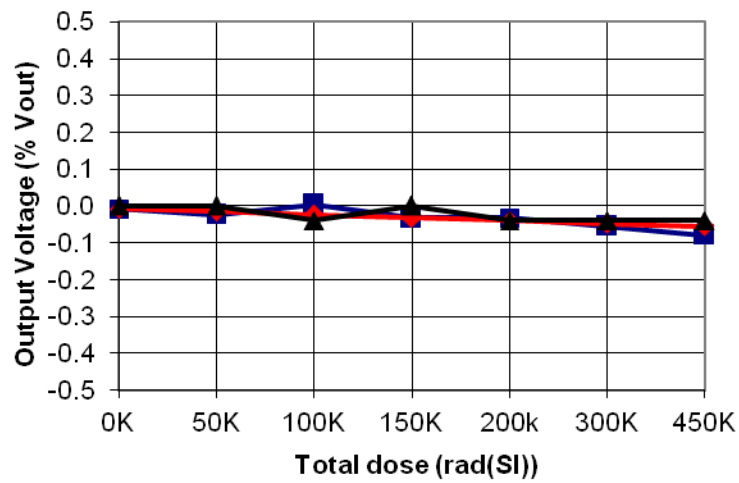
MSK5810RH  
Shutdown Hysteresis vs. Total Dose



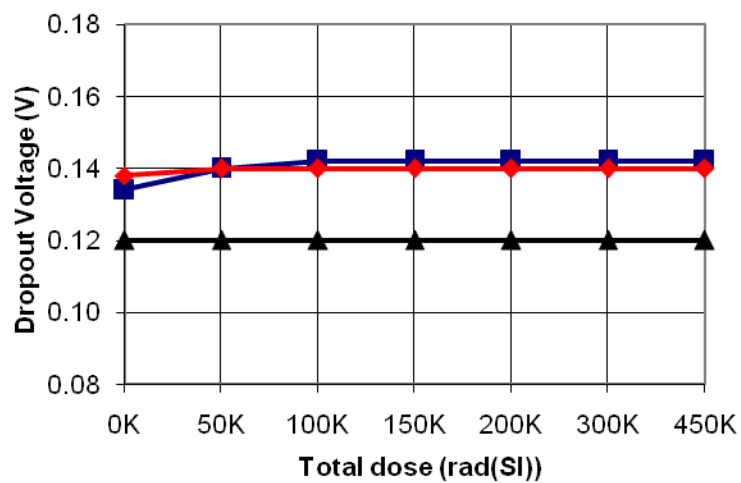
MSK5810RH  
Feedback Voltage vs. Total Dose



MSK5810RH  
Load Regulation vs. Total Dose

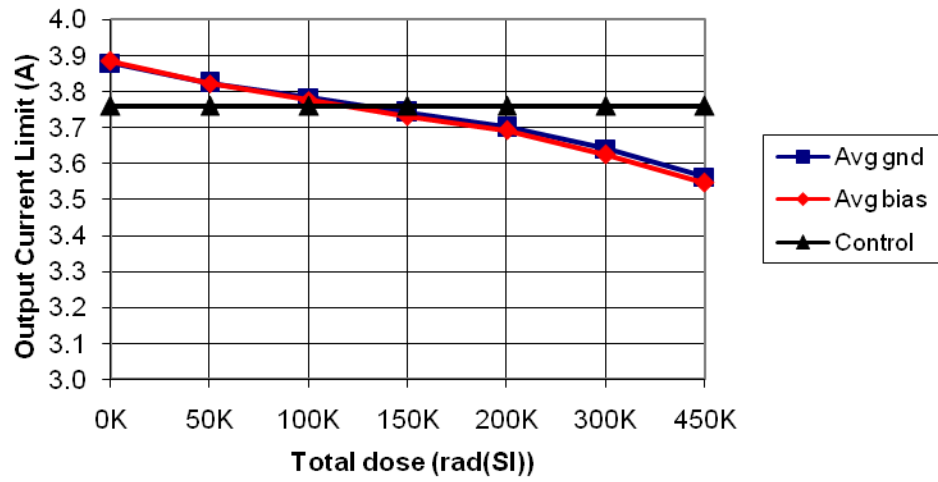


MSK5810RH  
Dropout Voltage vs. Total Dose



# MSK5810RH

## Output Current Limit vs. Total Dose





## **Total Dose Radiation Test Report**

### **MSK 5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

November 25, 2008 (MSK 5810RH – 1<sup>st</sup> Test)  
Updated on December 24, 2008  
March 21, 2009 (MSK 5822RH – 1<sup>st</sup> Test)  
March 26, 2009 (MSK 5810RH – 2<sup>nd</sup> Test)  
September 3, 2009 (MSK 5810RH – 3<sup>rd</sup> Test)  
November 6, 2009 (MSK 5810RH – 4<sup>th</sup> Test)  
May 14, 2010 (MSK 5810RH – 5<sup>th</sup> Test)  
September 17, 2010 (MSK 5810RH – 6<sup>th</sup> Test)

B. Horton  
R. Wakeman

M.S. Kennedy Corporation  
Liverpool, NY

## **I. Introduction:**

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK 5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 132 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Nine devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Four devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

## **V. Summary:**

Based on the test data recorded during radiation testing, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 300 KRAD (Si) TID.

MSK 5810RH Biased/Unbiased Dose Rate Schedule
--------------------------------------------------

Dosimetry Equipment
---------------------

Bruker Biospin # 0162
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Irradiation Date
------------------

09/17/10
----------

Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
13:00	102,960	102,960
6:30	51,480	154,440
19:31	154,572	309,012
19:31	154,572	463,584

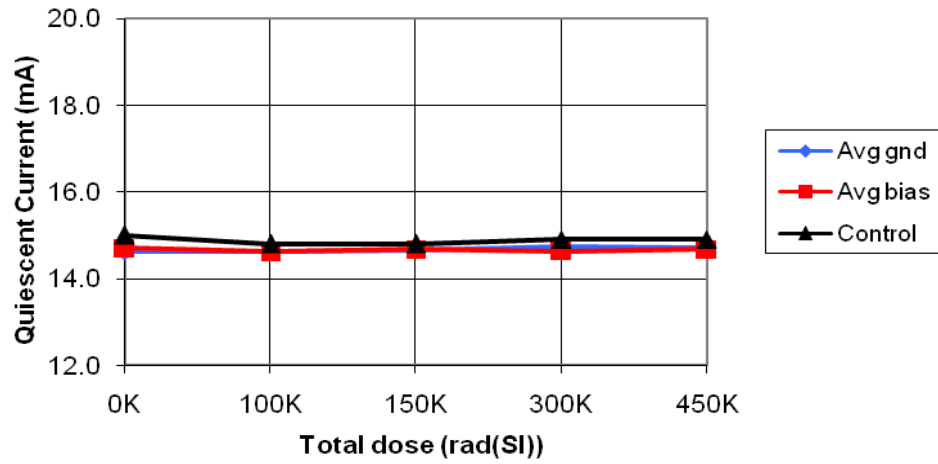
Biased S/N – 0476, 0477, 0478, 0480
-------------------------------------

Unbiased S/N – 0471, 0472, 0473, 0474, 0475
---------------------------------------------

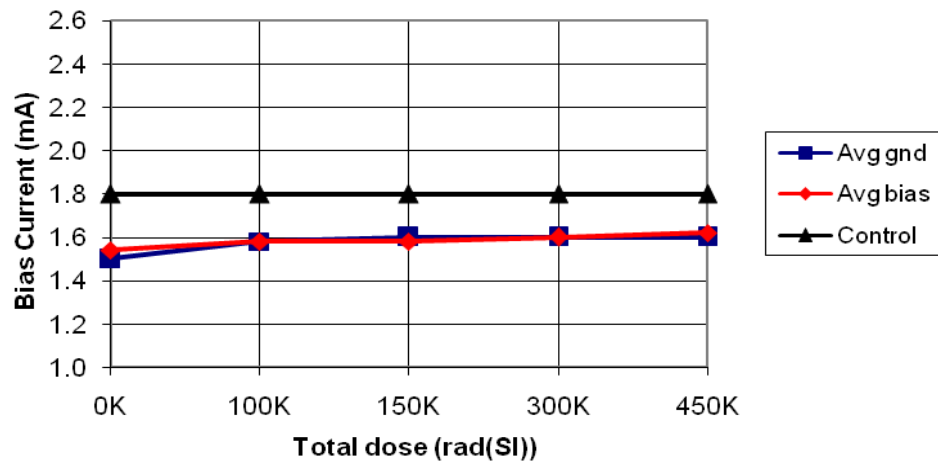
Table 1

**Dose Time, Incremental Dose and Total Cumulative Dose**

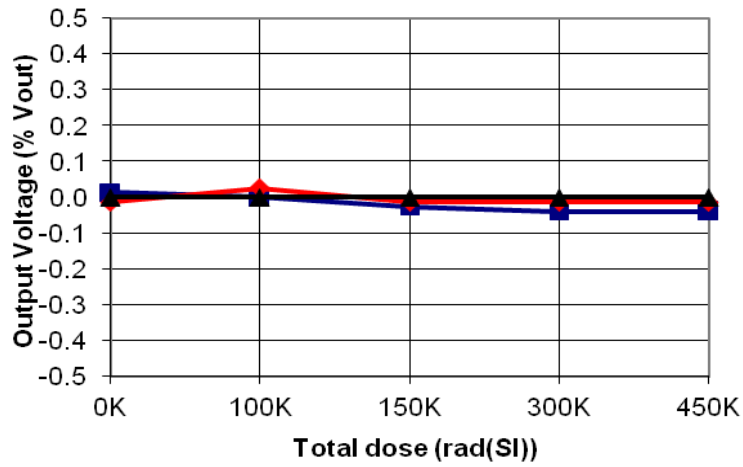
MSK5810KRH  
Quiescent Current vs. Total Dose



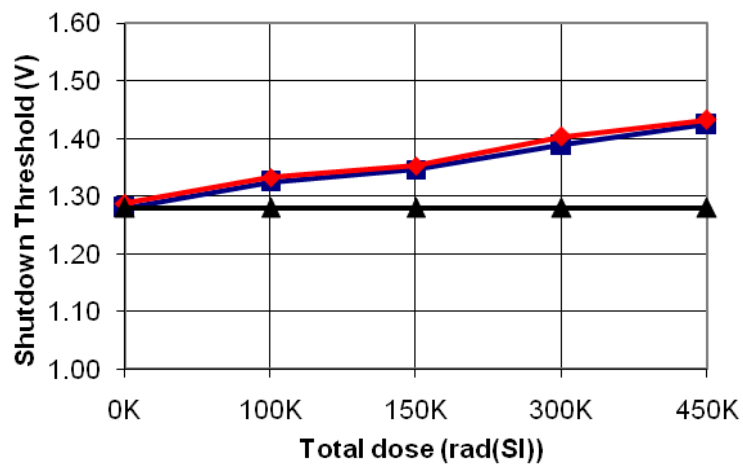
MSK5810KRH  
Bias Current vs. Total Dose



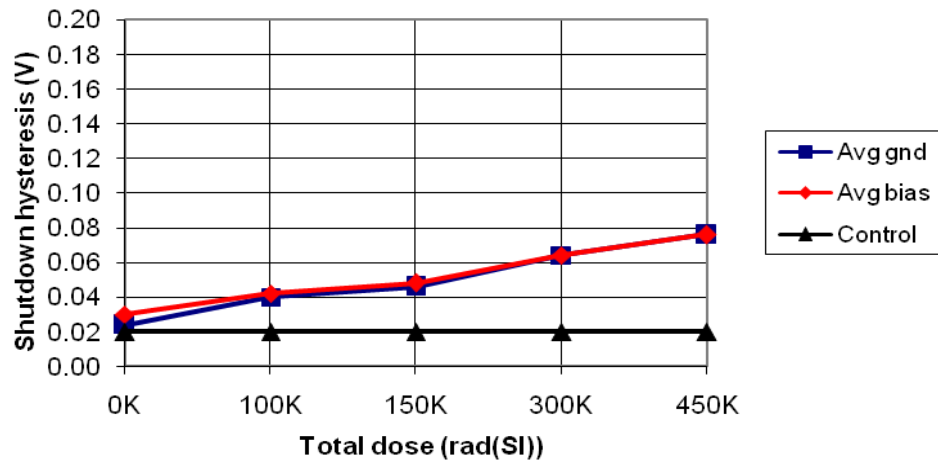
MSK5810KRH  
Line Regulation vs. Total Dose



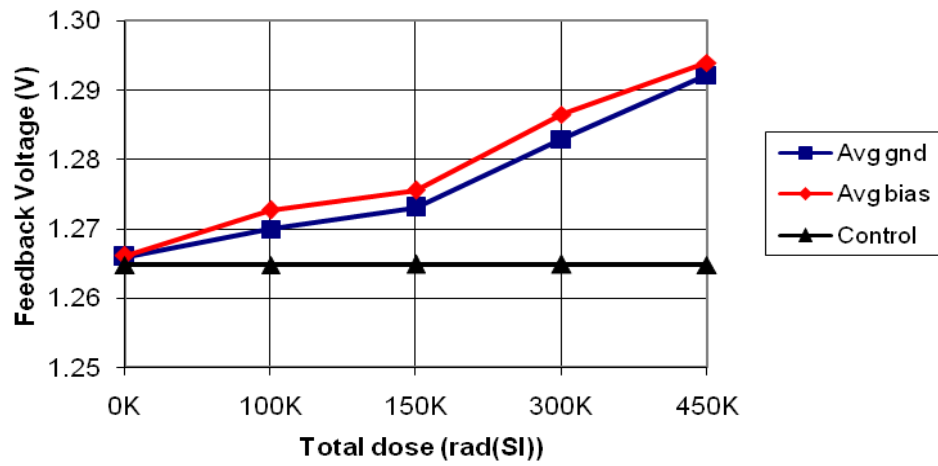
MSK5810KRH  
Shutdown Threshold vs. Total Dose



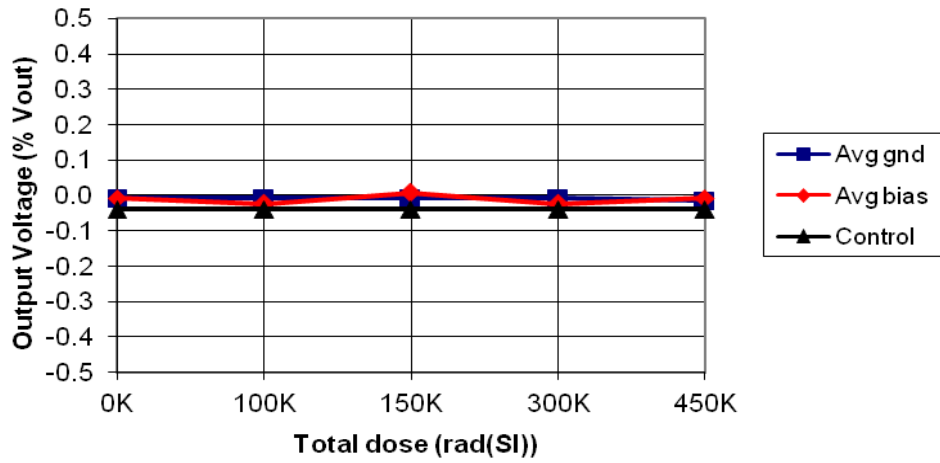
MSK5810KRH  
Shutdown Hysteresis vs. Total Dose



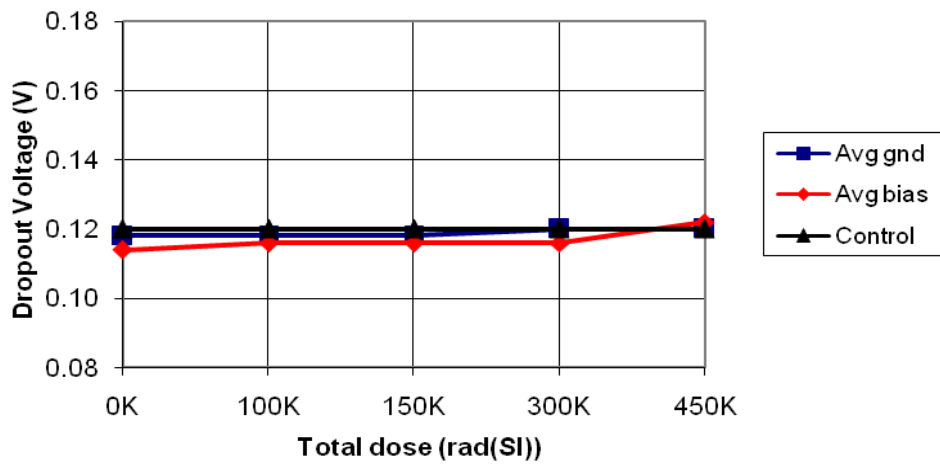
MSK5810KRH  
Feedback Voltage vs. Total Dose



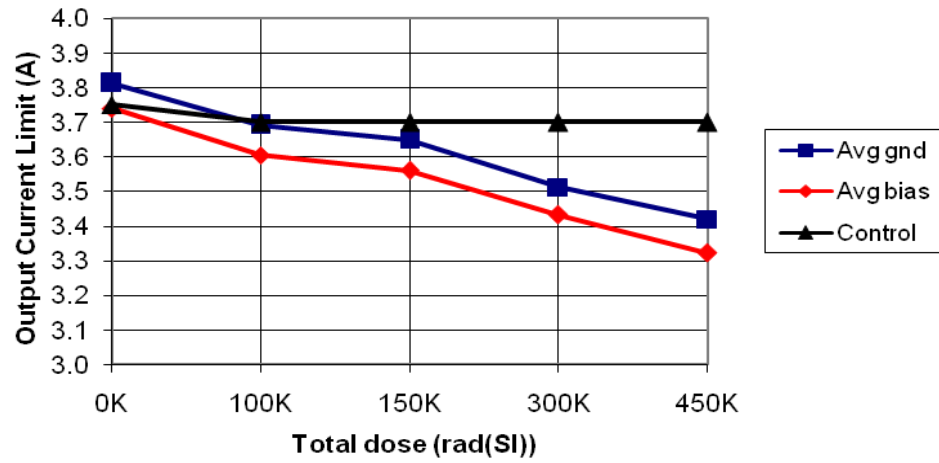
MSK5810KRH  
Load Regulation vs. Total Dose



MSK5810KRH  
Dropout Voltage vs. Total Dose



MSK5810KRH  
Output Current Limit vs. Total Dose





## **Total Dose Radiation Test Report**

### **MSK 5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

November 25, 2008 (MSK 5810RH – 1<sup>st</sup> Test)

Updated on December 24, 2008

March 21, 2009 (MSK 5822RH – 1<sup>st</sup> Test)

March 26, 2009 (MSK 5810RH – 2<sup>nd</sup> Test)

September 3, 2009 (MSK 5810RH – 3<sup>rd</sup> Test)

November 6, 2009 (MSK 5810RH – 4<sup>th</sup> Test)

May 14, 2010 (MSK 5810RH – 5<sup>th</sup> Test)

M. Bilecki

B. Erwin

M.S. Kennedy Corporation  
Liverpool, NY

## **I. Introduction:**

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK 5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 138 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

## **V. Summary:**

Based on the test data recorded during radiation testing, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID.

MSK 5810RH Biased/Unbiased Dose Rate Schedule
--------------------------------------------------

Dosimetry Equipment
Bruker Biospin # 0141

Irradiation Date
05/14/10

Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
12:27	103,086	103,086
6:14	51,612	154,698
18:40	154,560	309,258
18:40	154,560	463,818

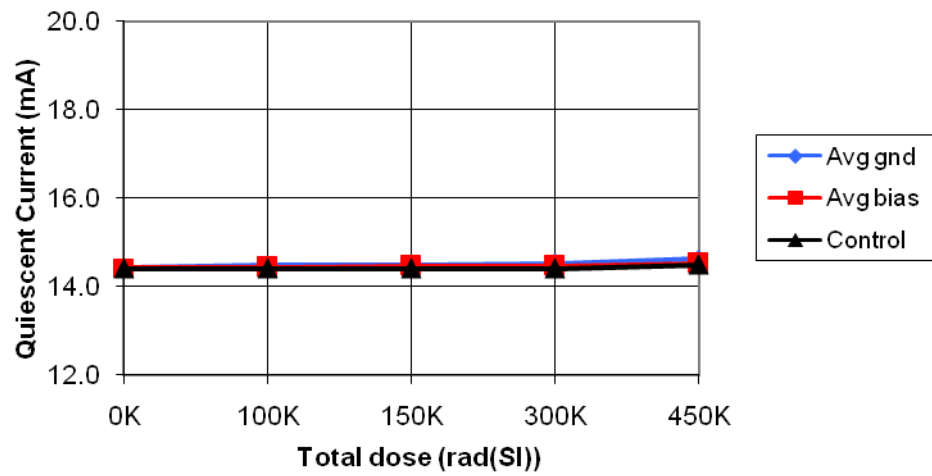
Biased S/N – 0360, 0361, 0362, 0363, 0364
-------------------------------------------

Unbiased S/N – 0365, 0366, 0367, 0368, 0369
---------------------------------------------

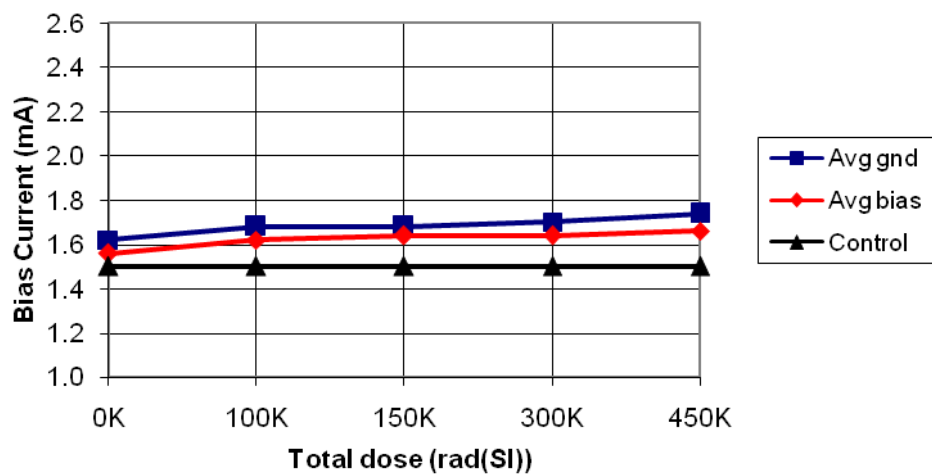
Table 1

**Dose Time, Incremental Dose and Total Cumulative Dose**

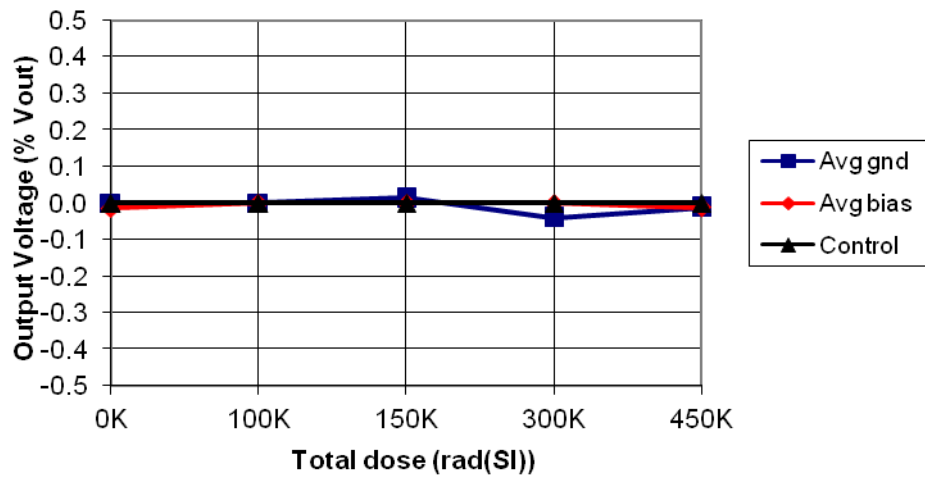
MSK5810RH  
Quiescent Current vs. Total Dose



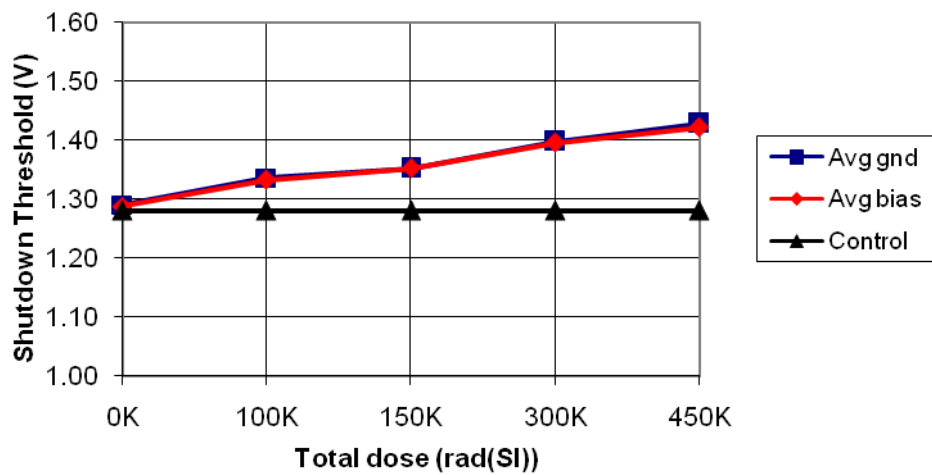
MSK5810RH  
Bias Current vs. Total Dose



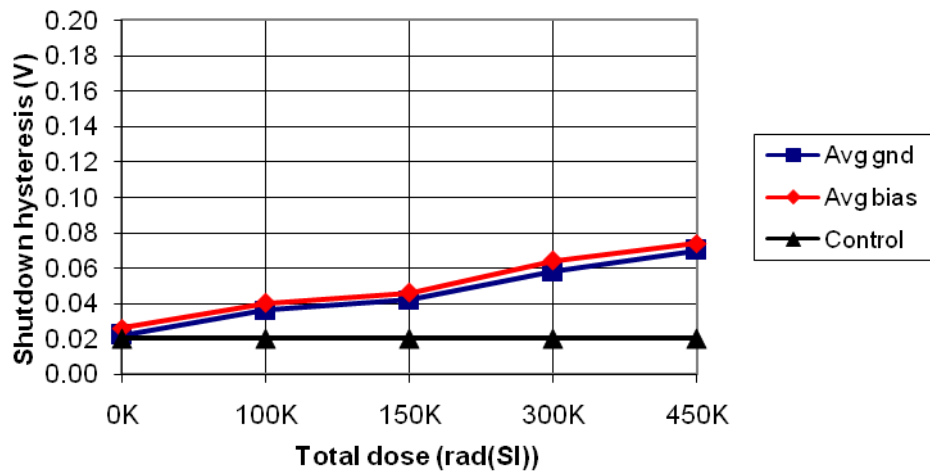
MSK5810RH  
Line Regulation vs. Total Dose



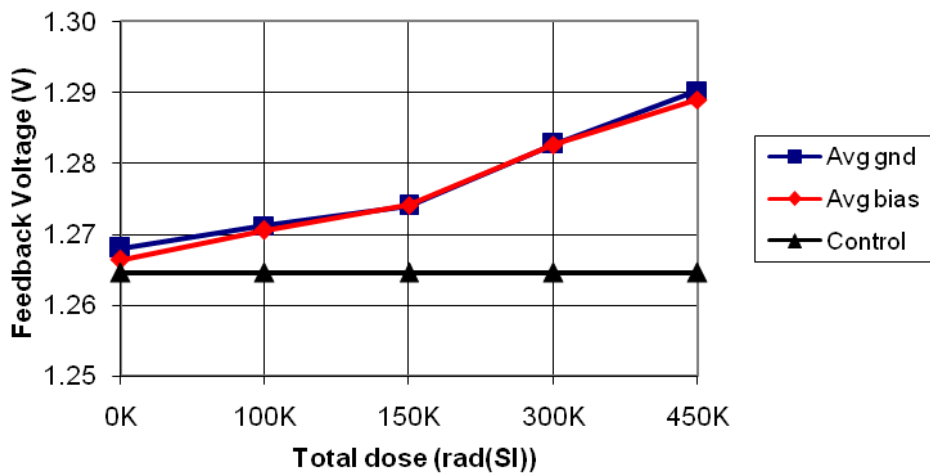
MSK5810RH  
Shutdown Threshold vs. Total Dose



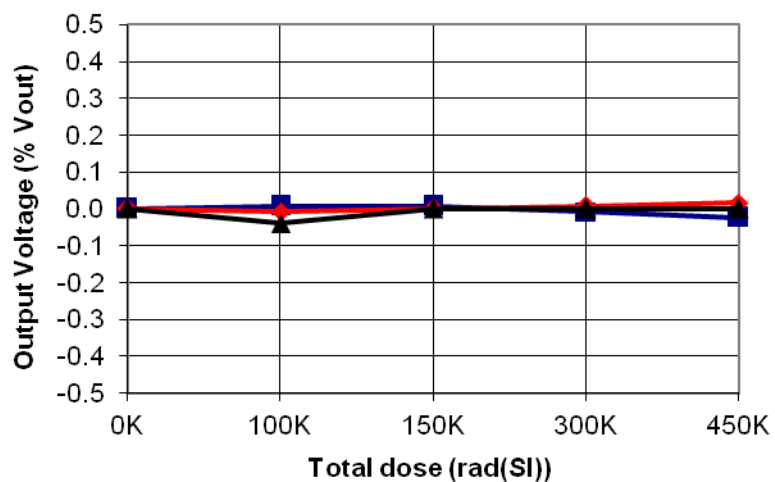
MSK5810RH  
Shutdown Hysteresis vs. Total Dose



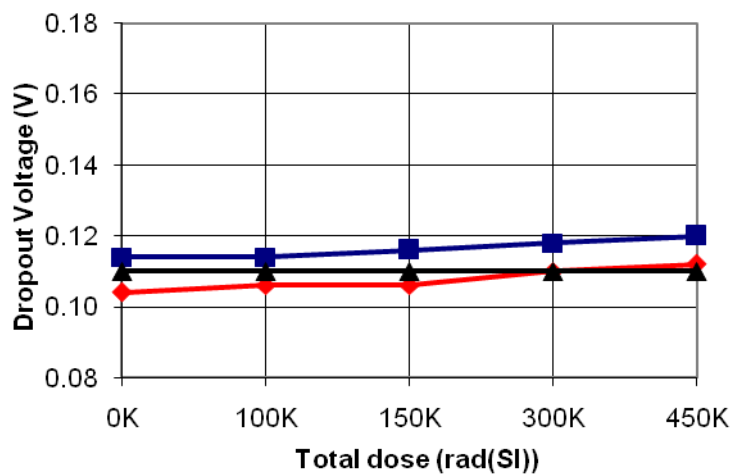
MSK5810RH  
Feedback Voltage vs. Total Dose



### MSK5810RH Load Regulation vs. Total Dose

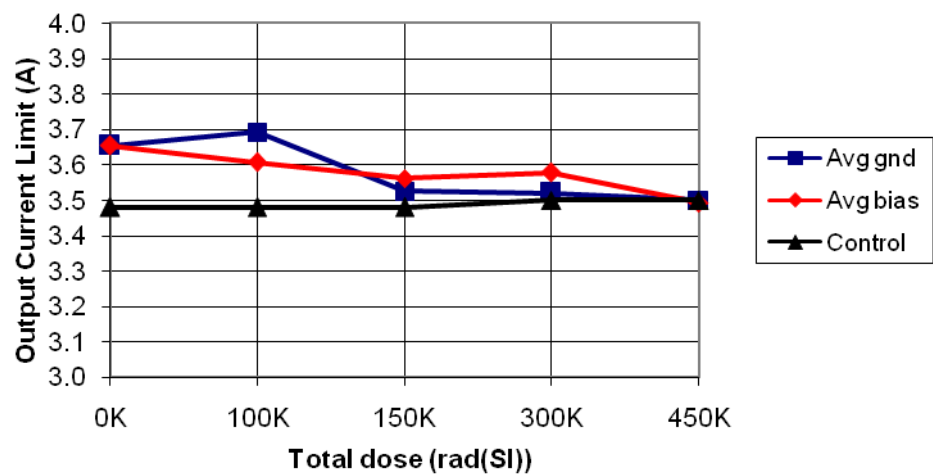


### MSK5810RH Dropout Voltage vs. Total Dose



# MSK5810RH

## Output Current Limit vs. Total Dose





## **Total Dose Radiation Test Report**

### **MSK 5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH, MSK 5827RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

November 25, 2008 (MSK 5810RH – 1<sup>st</sup> Test)

Updated on December 24, 2008

March 21, 2009 (MSK 5822RH – 1<sup>st</sup> Test)

March 26, 2009 (MSK 5810RH – 2<sup>nd</sup> Test)

September 3, 2009 (MSK 5810RH – 3<sup>rd</sup> Test)

November 6, 2009 (MSK 5810RH – 4<sup>th</sup> Test)

M. Bilecki  
B. Erwin

M.S. Kennedy Corporation  
Liverpool, NY

## **I. Introduction:**

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK 5800RH, MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 156 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were biased during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

## **V. Summary:**

Based on the test data recorded during radiation testing, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID.

MSK 5810RH Biased/Unbiased Dose Rate Schedule
--------------------------------------------------

Dosimetry Equipment
---------------------

Bruker Biospin # 0141
-----------------------

Irradiation Date
------------------

11/06/09
----------

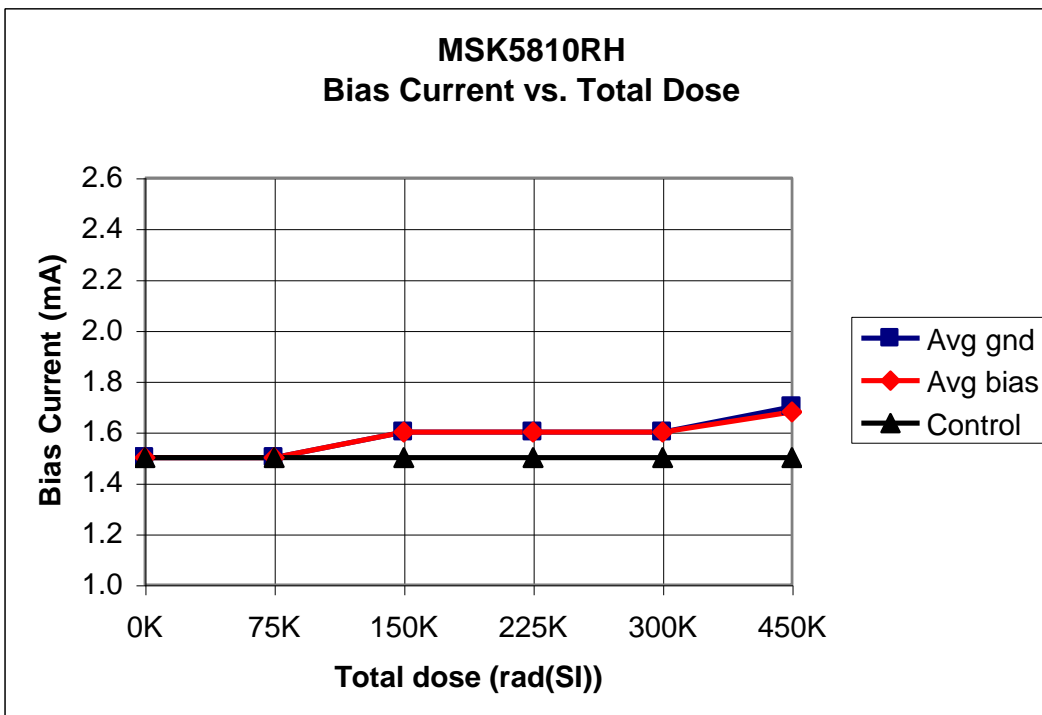
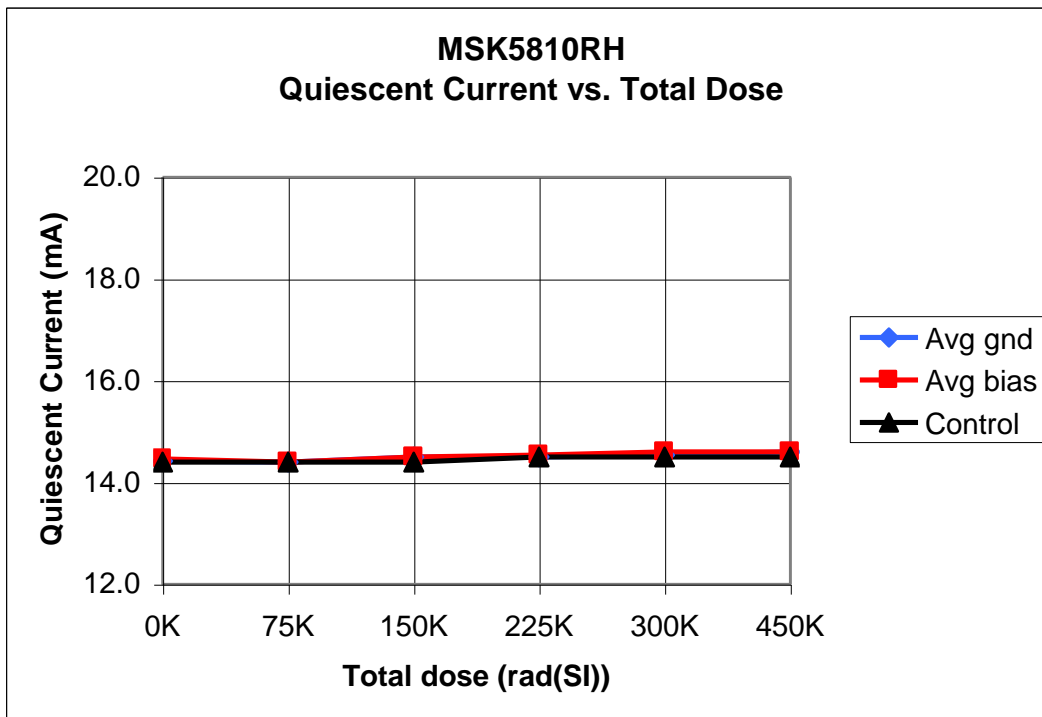
Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
8:16	77,376	77,376
8:16	77,376	154,752
8:16	77,376	232,128
8:16	77,376	309,504
16:32	154,752	464,256

Biased S/N – 0315, 0316, 0317, 0318, 0319
-------------------------------------------

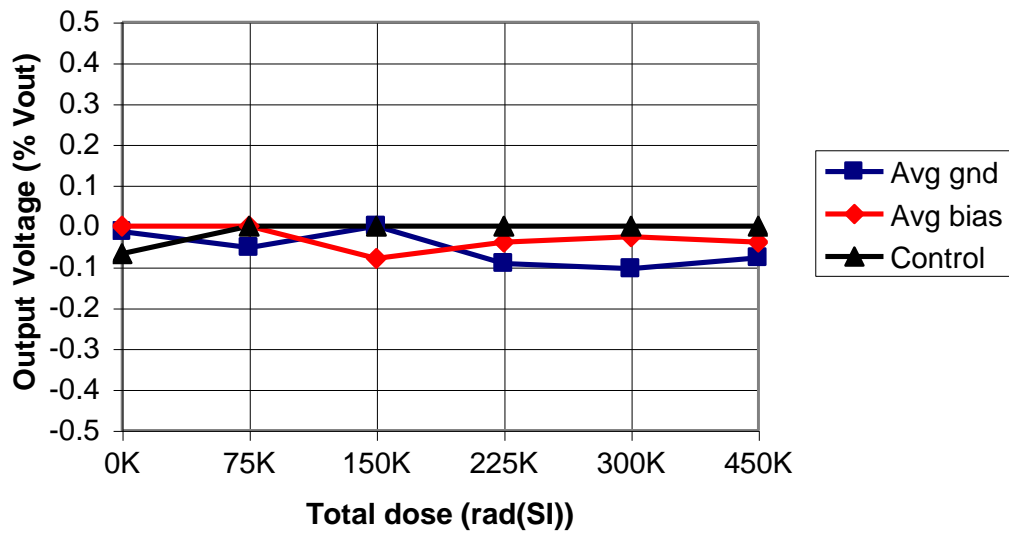
Unbiased S/N – 0320, 0321, 0322, 0324, 0325
---------------------------------------------

Table 1

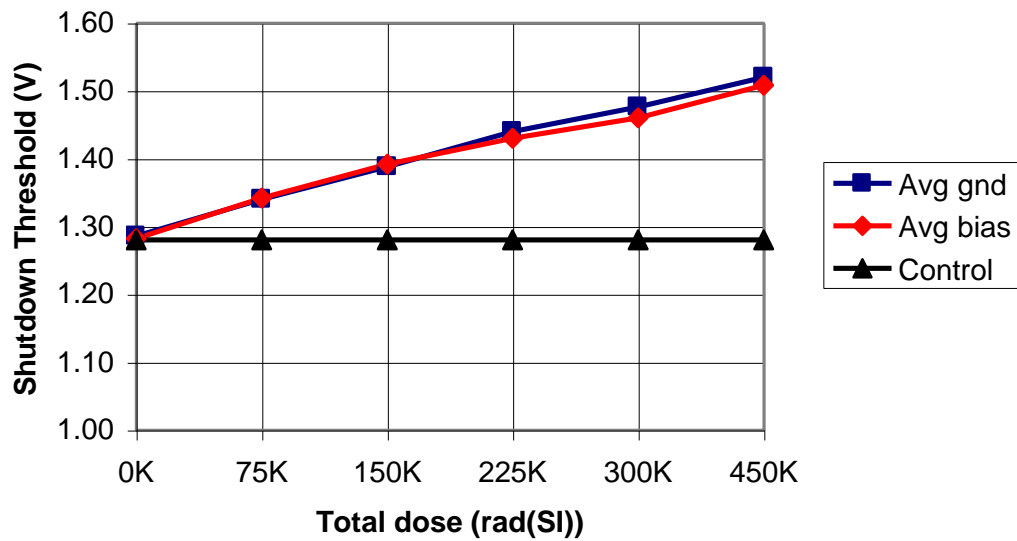
**Dose Time, Incremental Dose and Total Cumulative Dose**



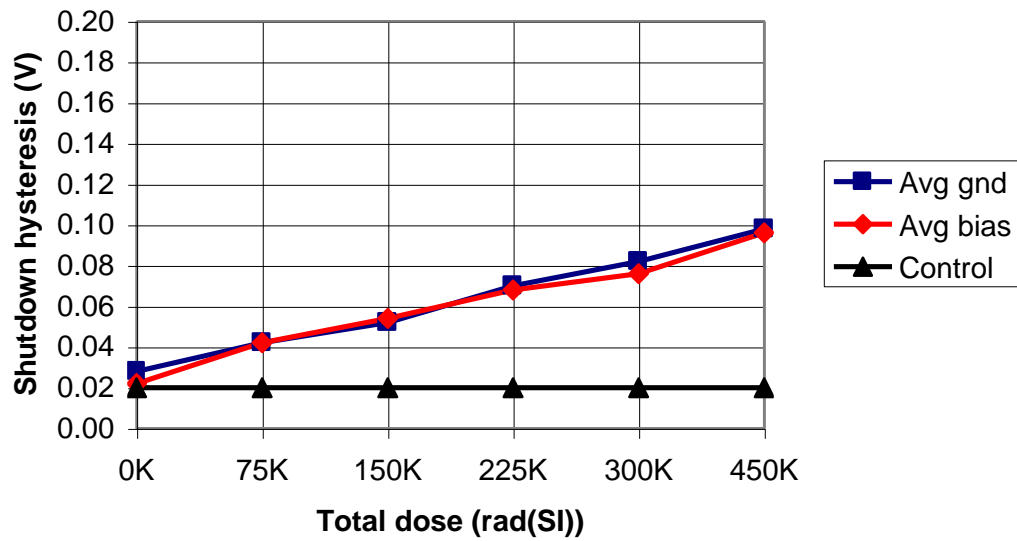
**MSK5810RH**  
**Line Regulation vs. Total Dose**



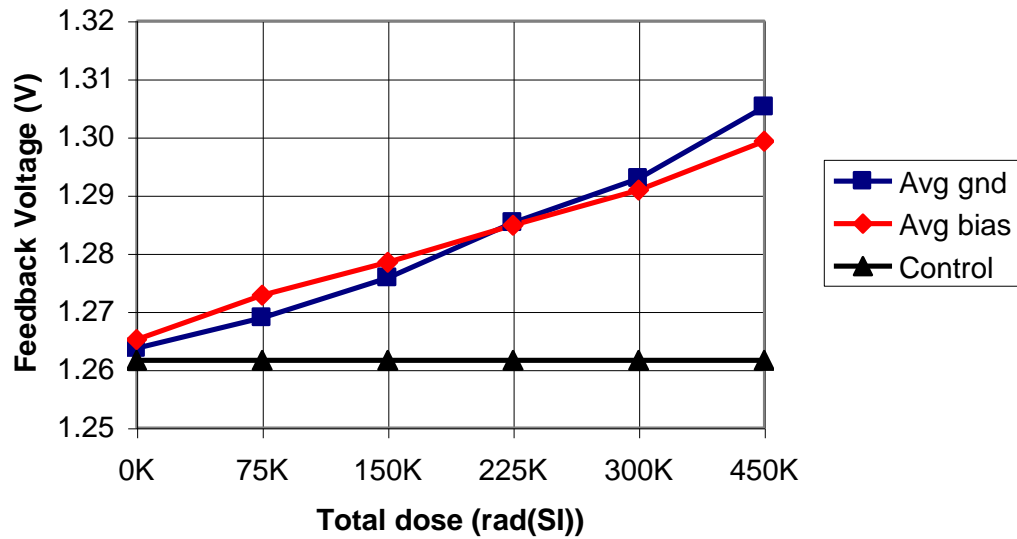
**MSK5810RH**  
**Shutdown Threshold vs. Total Dose**

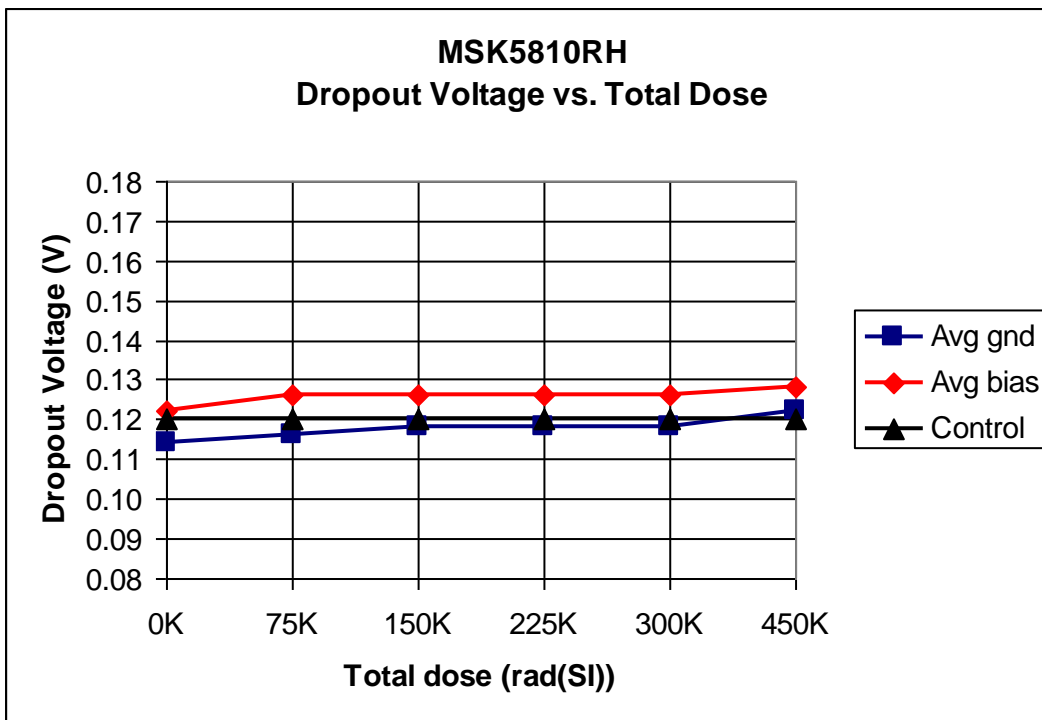
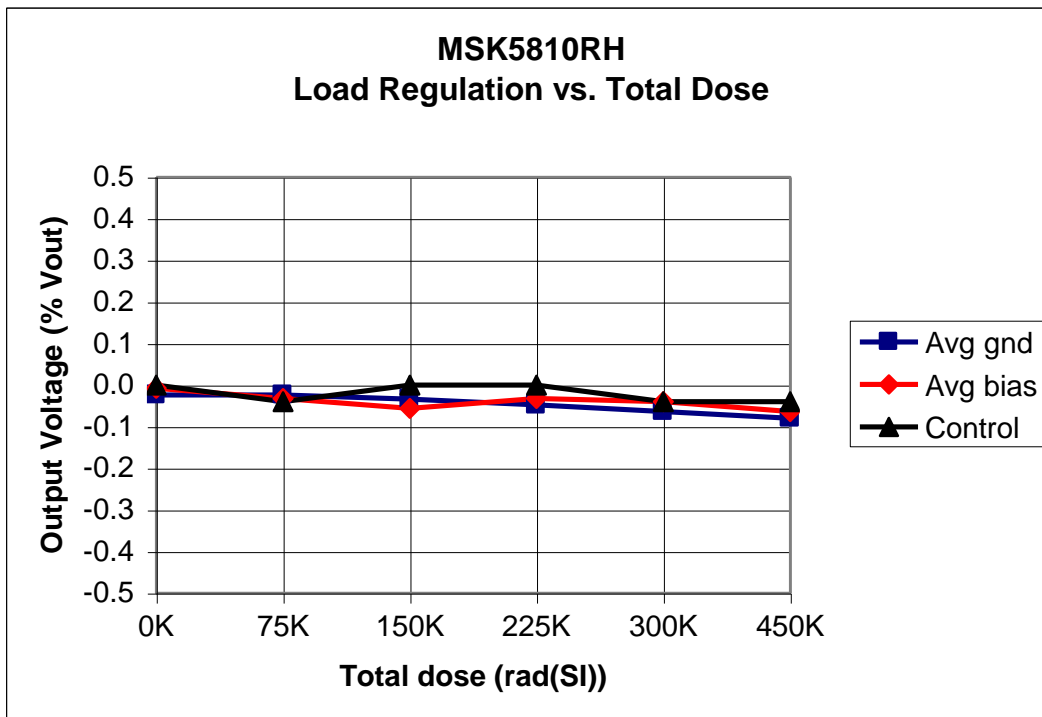


**MSK5810RH**  
**Shutdown Hysteresis vs. Total Dose**

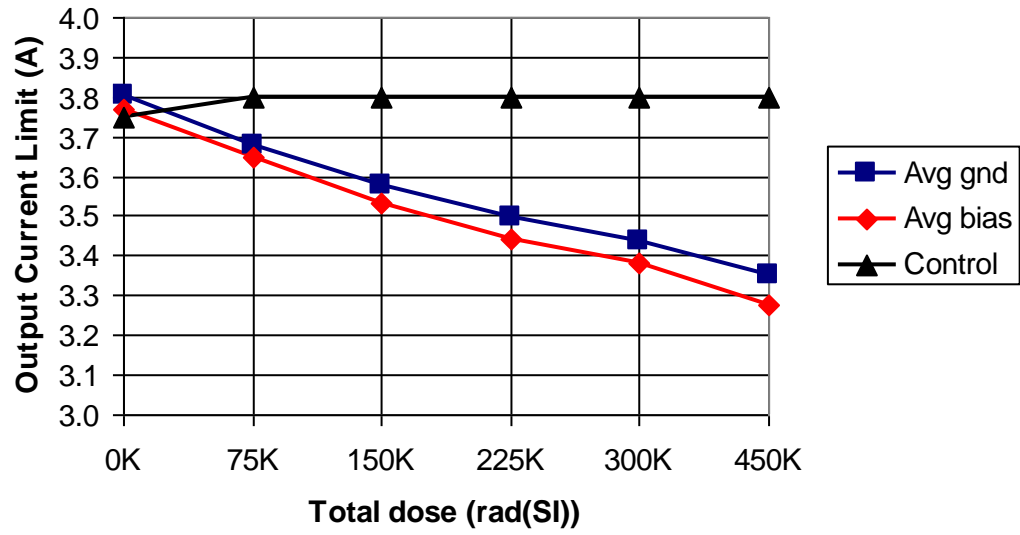


**MSK5810RH**  
**Feedback Voltage vs. Total Dose**





**MSK5810RH**  
**Output Current Limit vs. Total Dose**





## **Total Dose Radiation Test Report**

**MSK 5810 RH**  
**(MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH)**  
**RAD Hard Ultra Low Dropout**  
**Adjustable Positive Linear Regulator**

November 25, 2008 (First Test)  
Updated on December 24, 2008  
March 26, 2009 (Second Test)  
September 3, 2009 (Third Test)

M. Bilecki  
B. Erwin

M.S. Kennedy Corporation  
Liverpool, NY

## **I. Introduction:**

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK5800RH, MSK 5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and MSK5827RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 172 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were kept under bias during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

## **V. Summary:**

Based on the test data recorded during radiation testing, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID.

MSK 5810RH Biased/Unbiased Dose Rate Schedule
--------------------------------------------------

Dosimetry Equipment
Bruker Biospin # 0141

Irradiation Date
09/03/09

Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
5:00	51,600	51,600
5:00	51,600	103,200
5:00	51,600	154,800
5:00	51,600	206,400
9:59	103,028	309,428
14:58	154,456	463,884

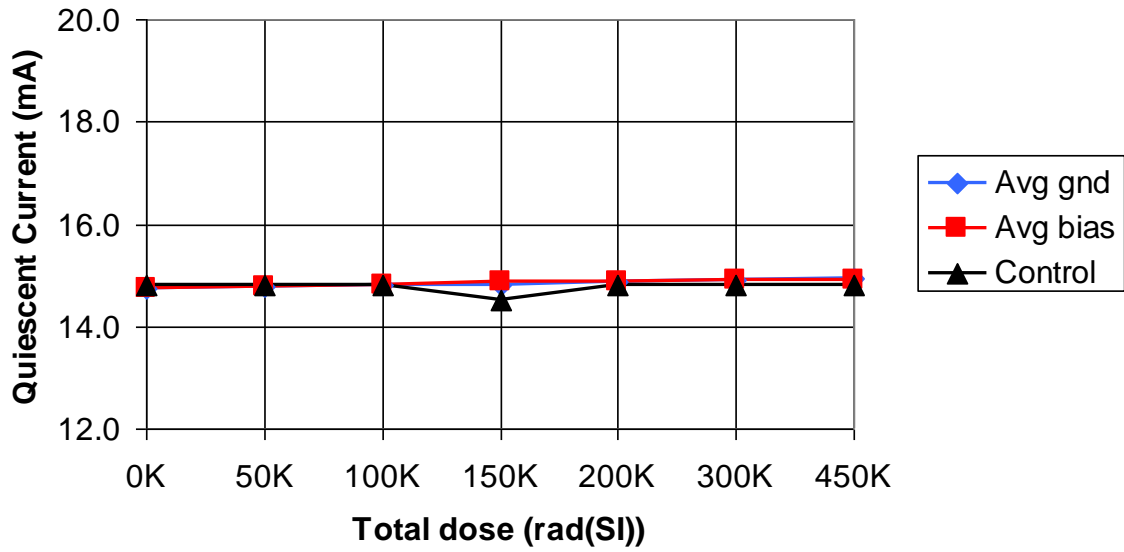
Biased S/N – 0276, 0277, 0278, 0279, 0280
-------------------------------------------

Unbiased S/N – 0281, 0282, 0283, 0284, 0285
---------------------------------------------

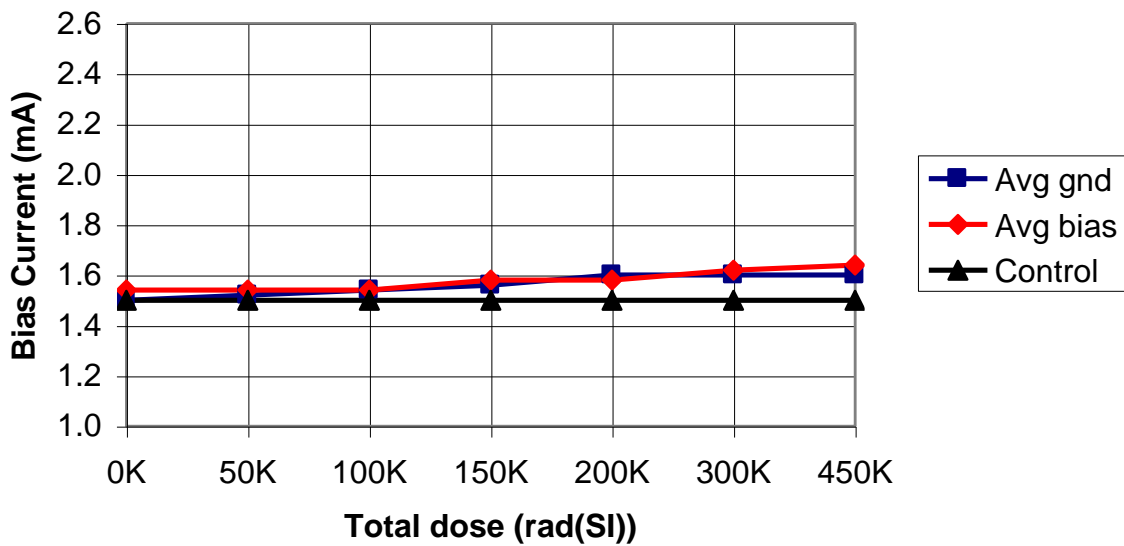
Table 1

**Dose Time, Incremental Dose and Total Cumulative Dose**

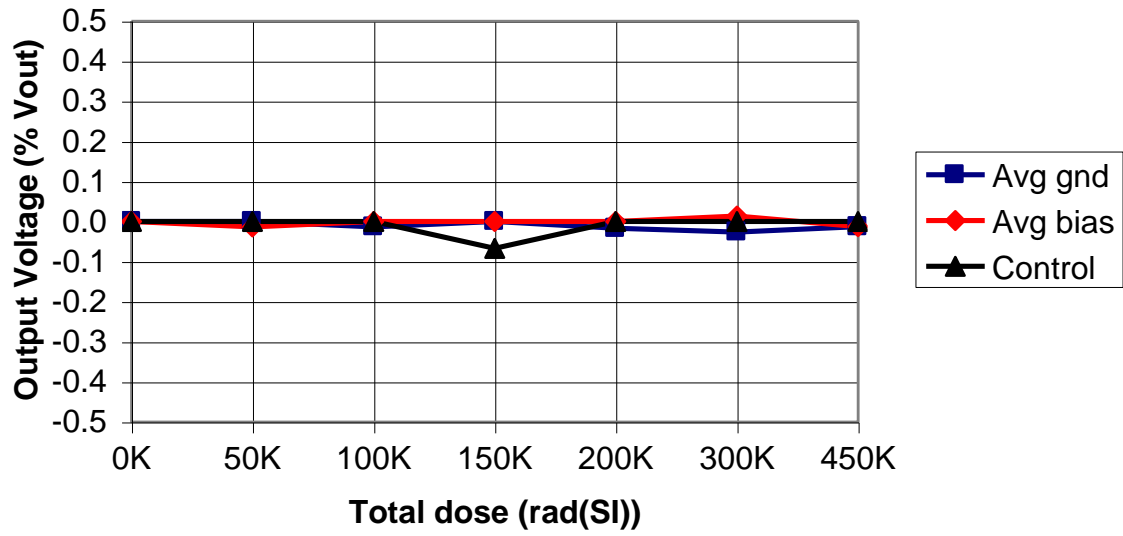
**MSK5810RH**  
**Quiescent Current vs. Total Dose**



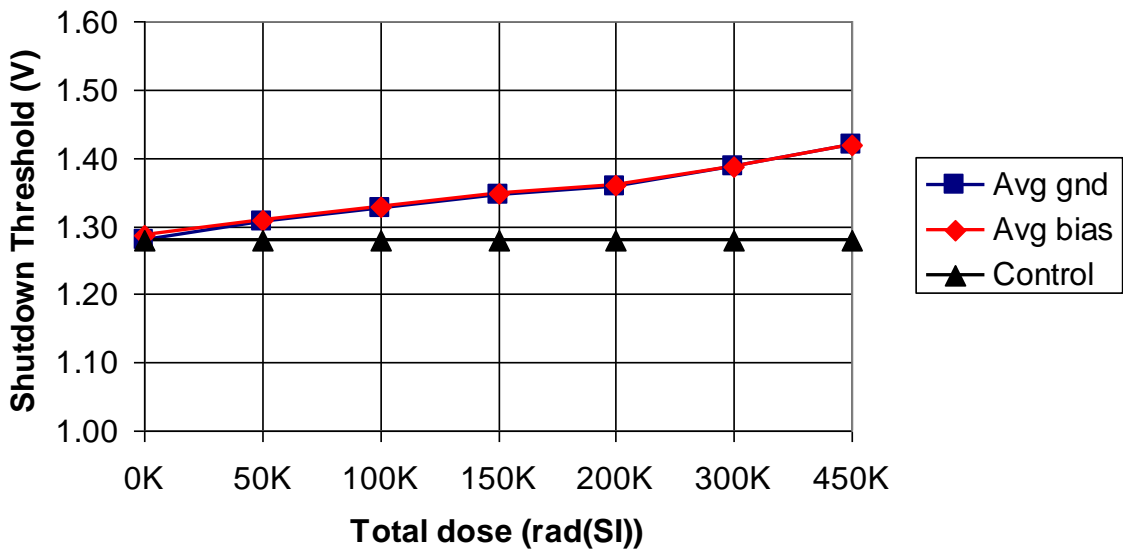
**MSK5810RH**  
**Bias Current vs. Total Dose**



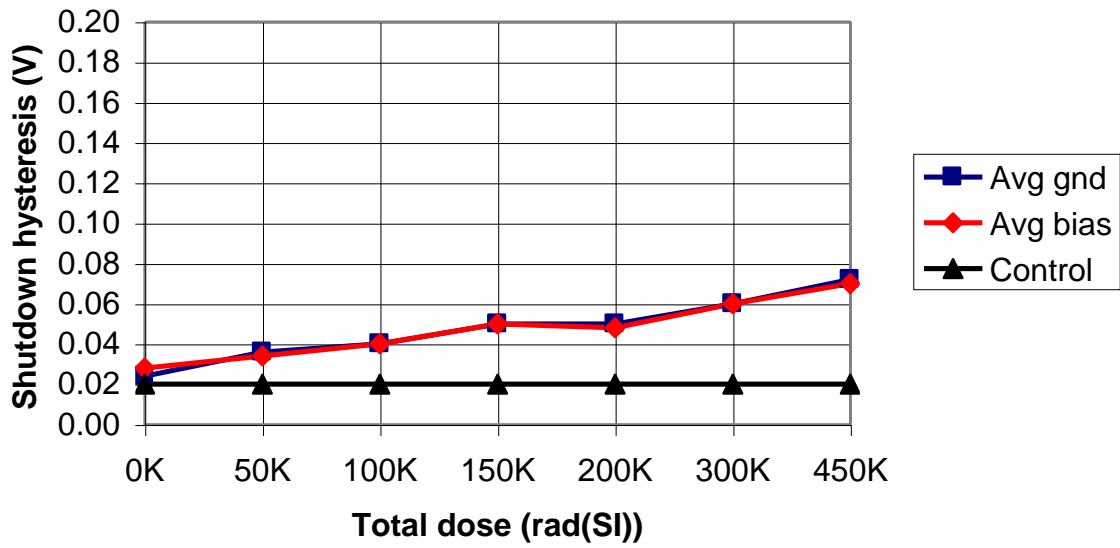
### MSK5810RH Line Regulation vs. Total Dose



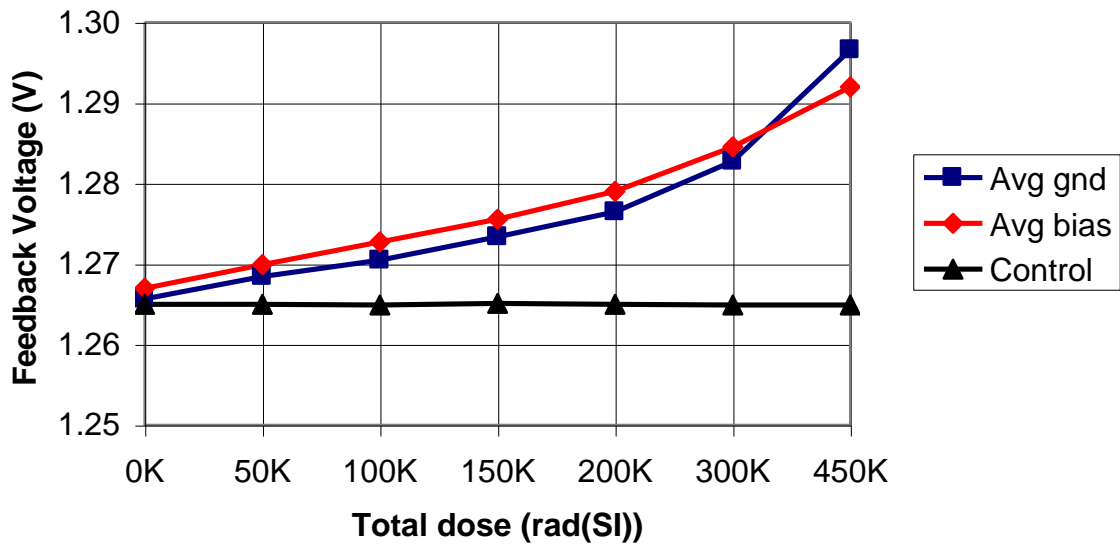
### MSK5810RH Shutdown Threshold vs. Total Dose



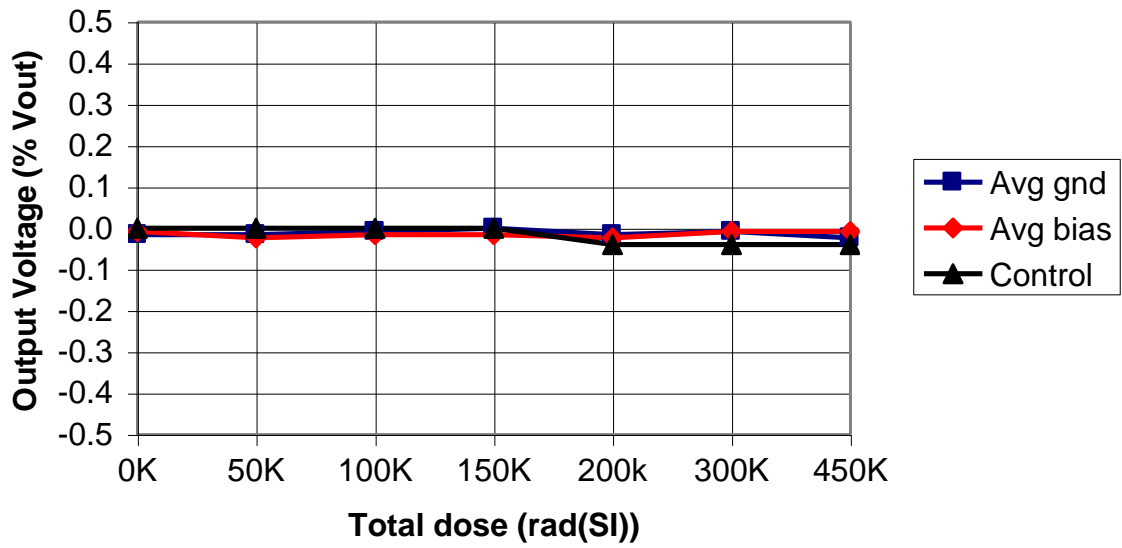
### MSK5810RH Shutdown Hysteresis vs. Total Dose



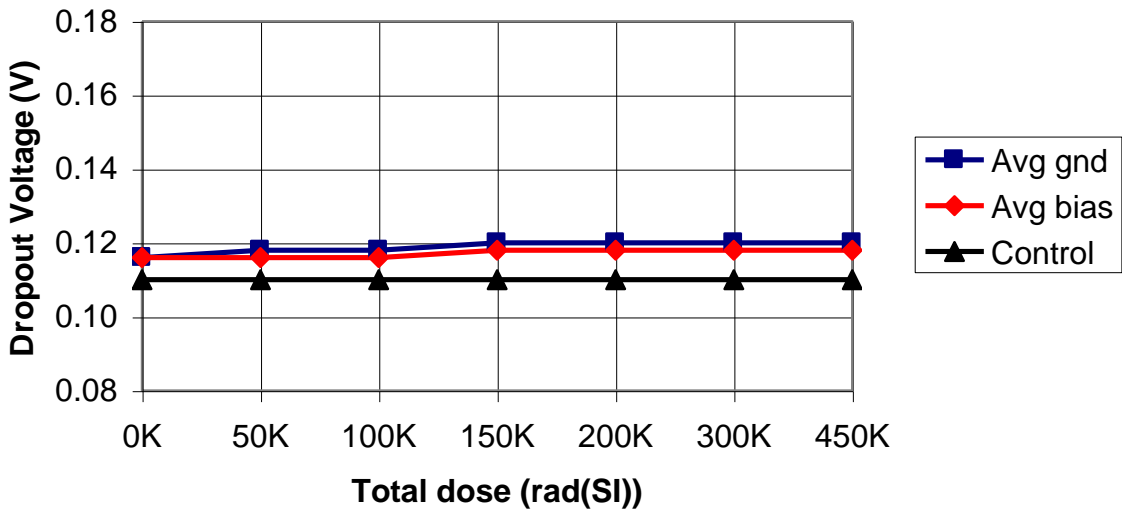
### MSK5810RH Feedback Voltage vs. Total Dose



### MSK5810RH Load Regulation vs. Total Dose

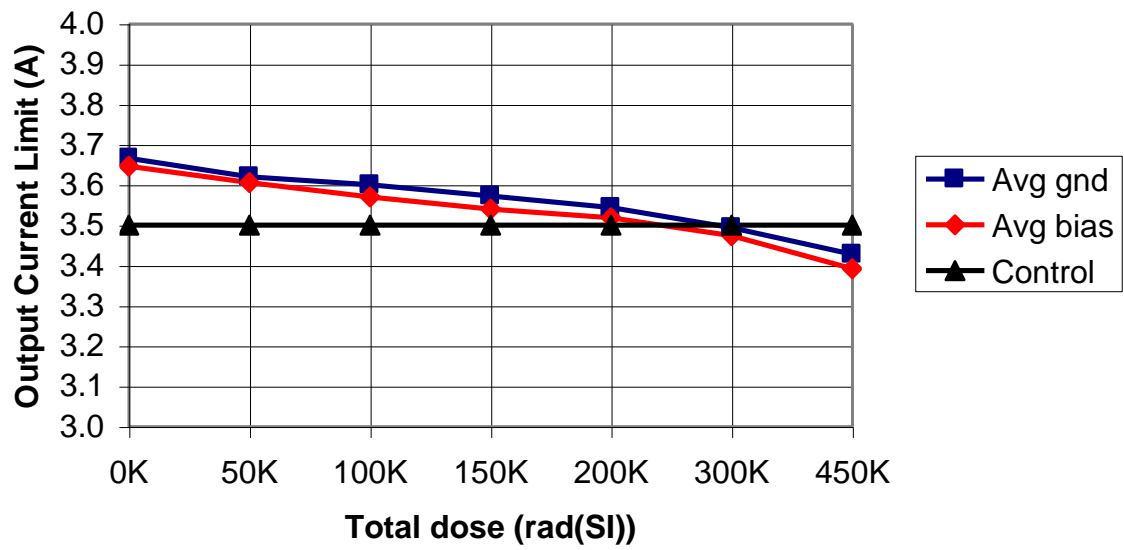


### MSK5810RH Dropout Voltage vs. Total Dose



# MSK5810RH

## Output Current Limit vs. Total Dose





## **Total Dose Radiation Test Report**

### **MSK 5810 RH (MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH) RAD Hard Ultra Low Dropout Adjustable Positive Linear Regulator**

November 25, 2008 (First Test)  
Updated on December 24, 2008  
March 26, 2009 (Second Test)

M. Bilecki  
P. Musil

M.S. Kennedy Corporation  
Liverpool, NY

## **I. Introduction:**

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and the MSK5800RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 184 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were kept under bias during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

## **V. Summary:**

Based on the test data recorded during radiation testing and statistical analysis, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID.

MSK 5810RH Biased/Unbiased Dose Rate Schedule
--------------------------------------------------

Dosimetry Equipment
---------------------

Bruker Biospin # 0141
-----------------------

Irradiation Date
------------------

03/17/09
----------

Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
4:40	51,520	51,520
4:40	51,520	103,040
4:40	51,520	154,560
4:40	51,520	206,080
9:20	103,040	309,120
14:00	154,560	463,680

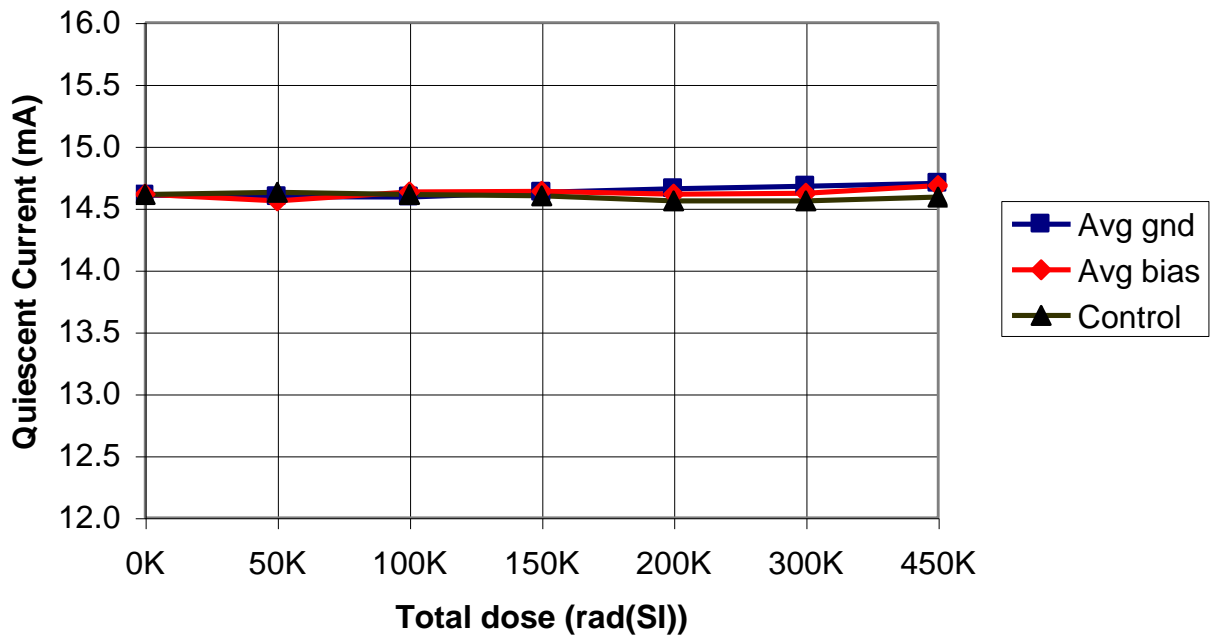
Biased S/N – 0054, 0055, 0056, 0057, 0058
-------------------------------------------

Unbiased S/N – 0059, 0060, 0061, 0062, 0063
---------------------------------------------

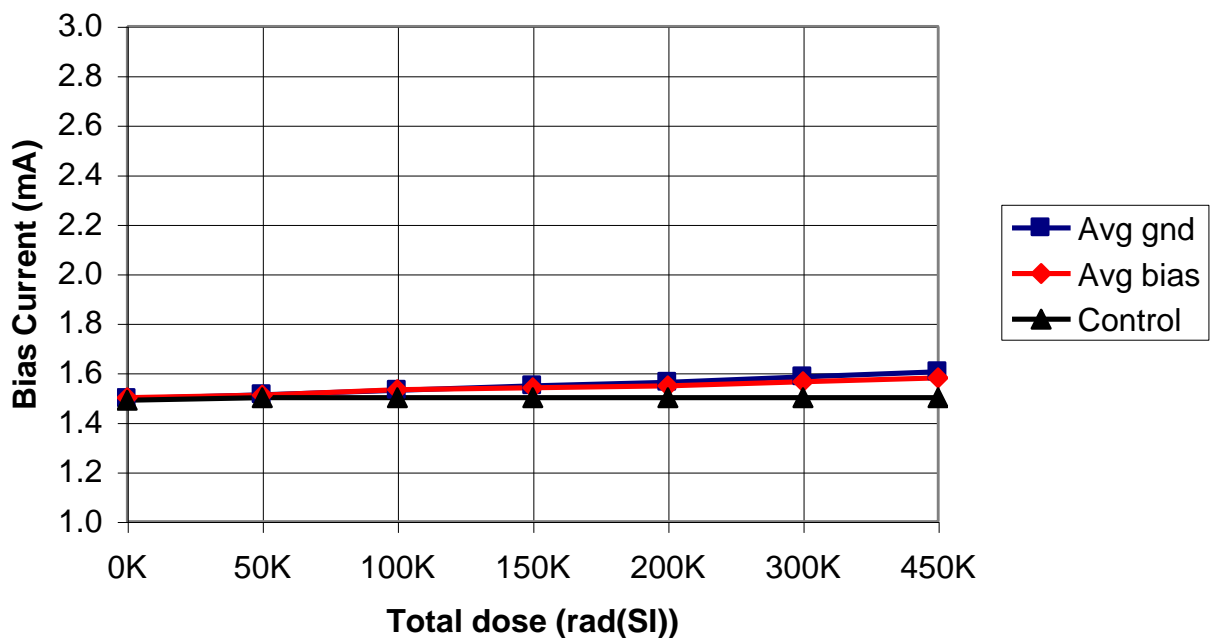
Table 1

**Dose Time, Incremental Dose and Total Cumulative Dose**

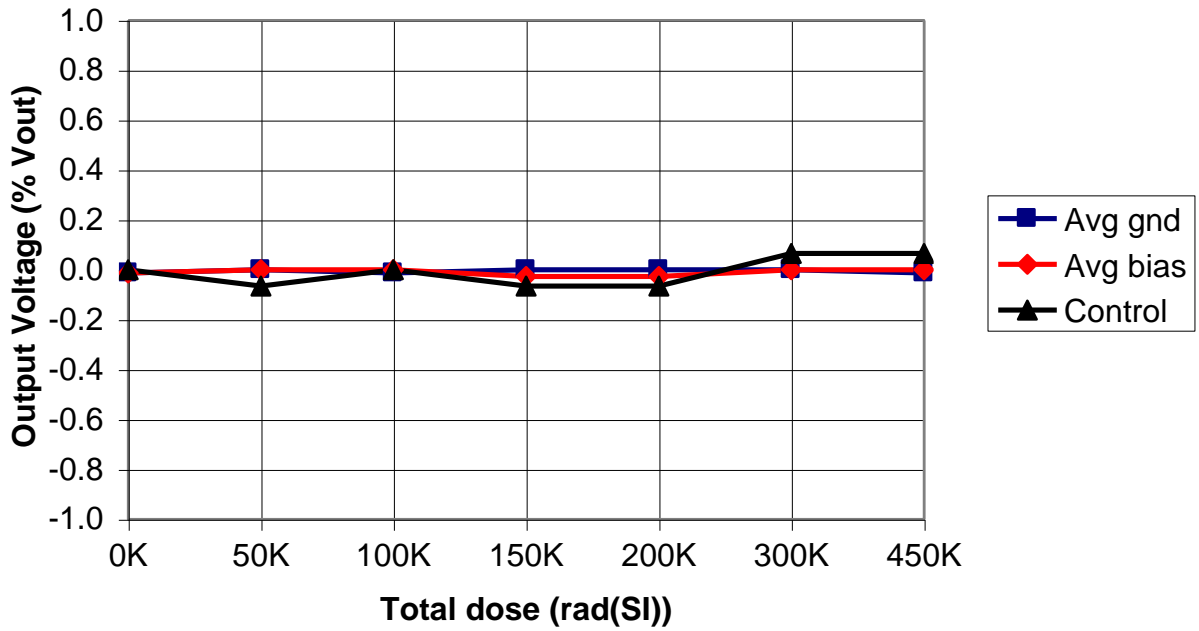
### MSK5810RH Quiescent Current vs. Total Dose



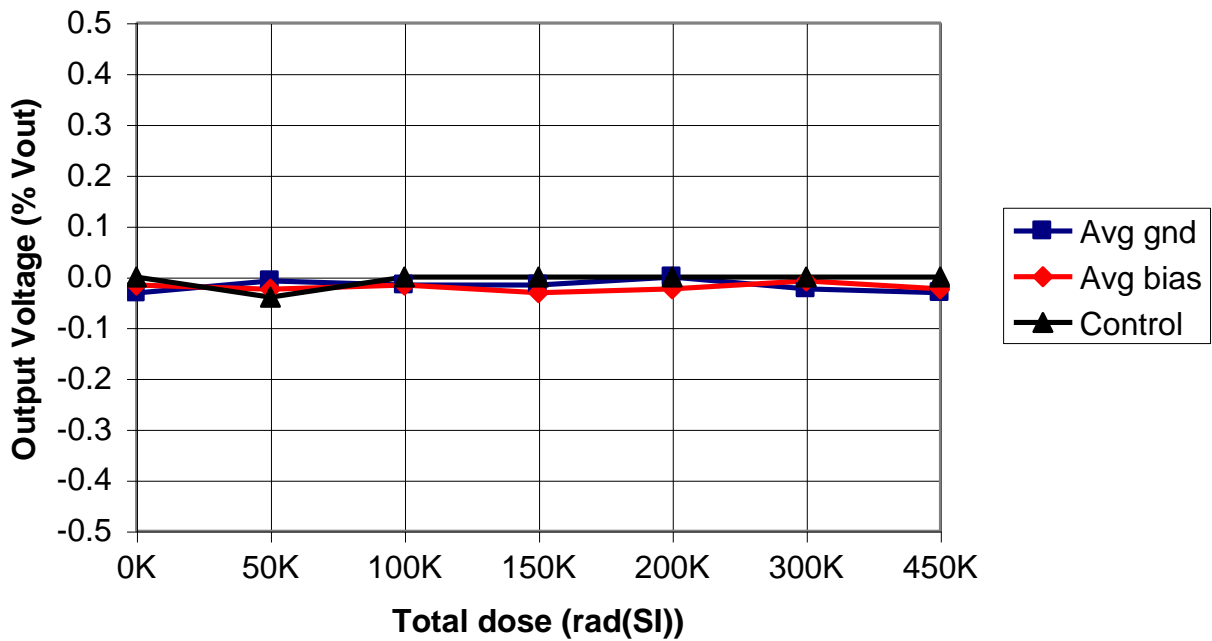
### MSK5810RH Bias Current vs. Total Dose



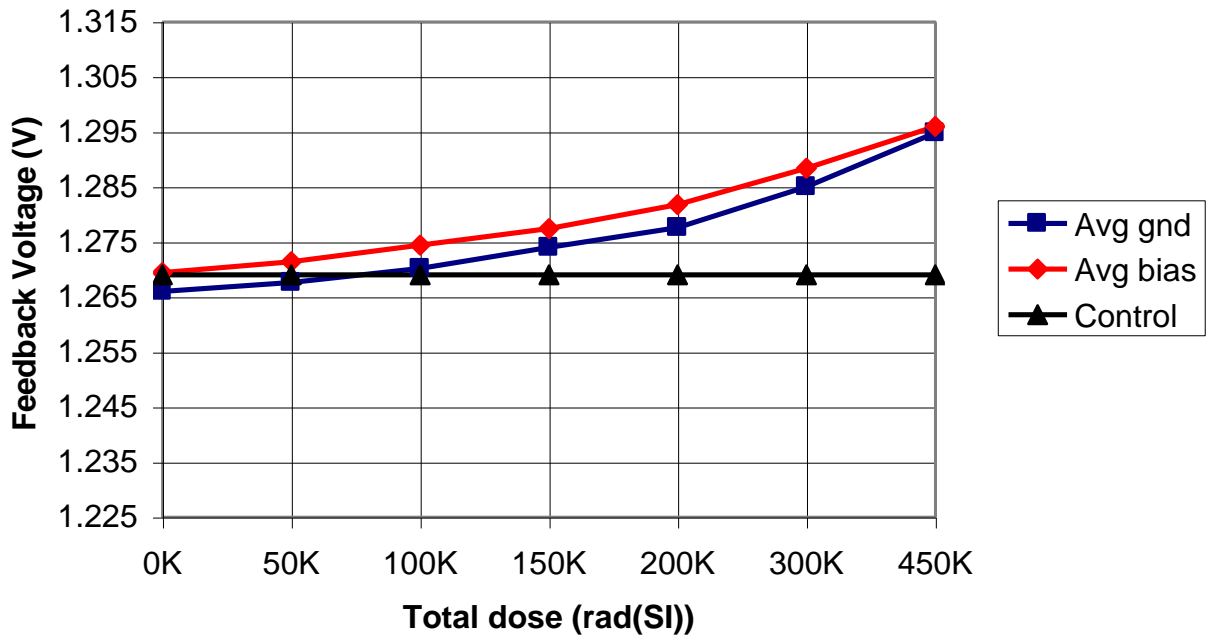
### MSK5810RH Line Regulation vs. Total Dose



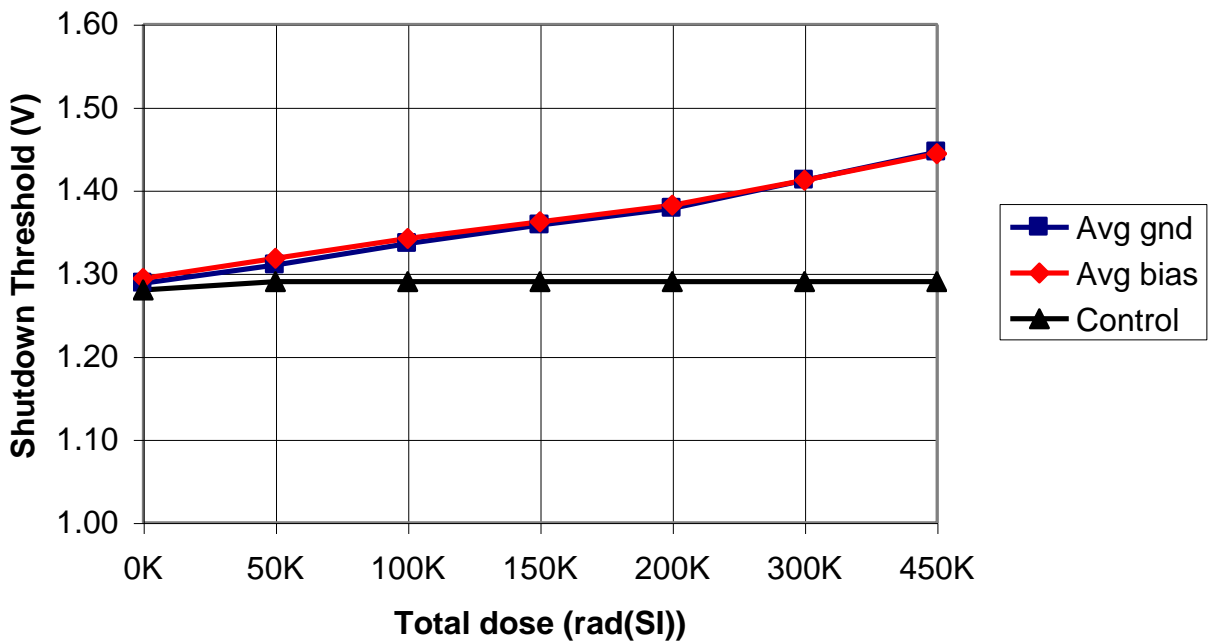
### MSK5810RH Load Regulation vs. Total Dose



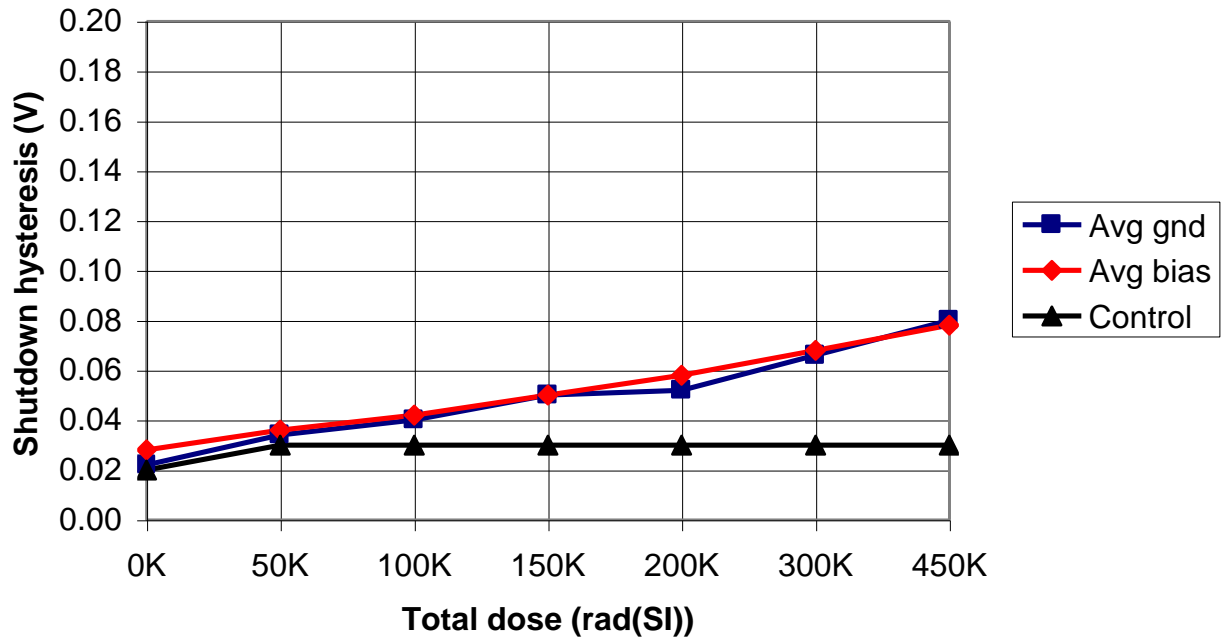
### MSK5810RH Feedback Voltage vs. Total Dose



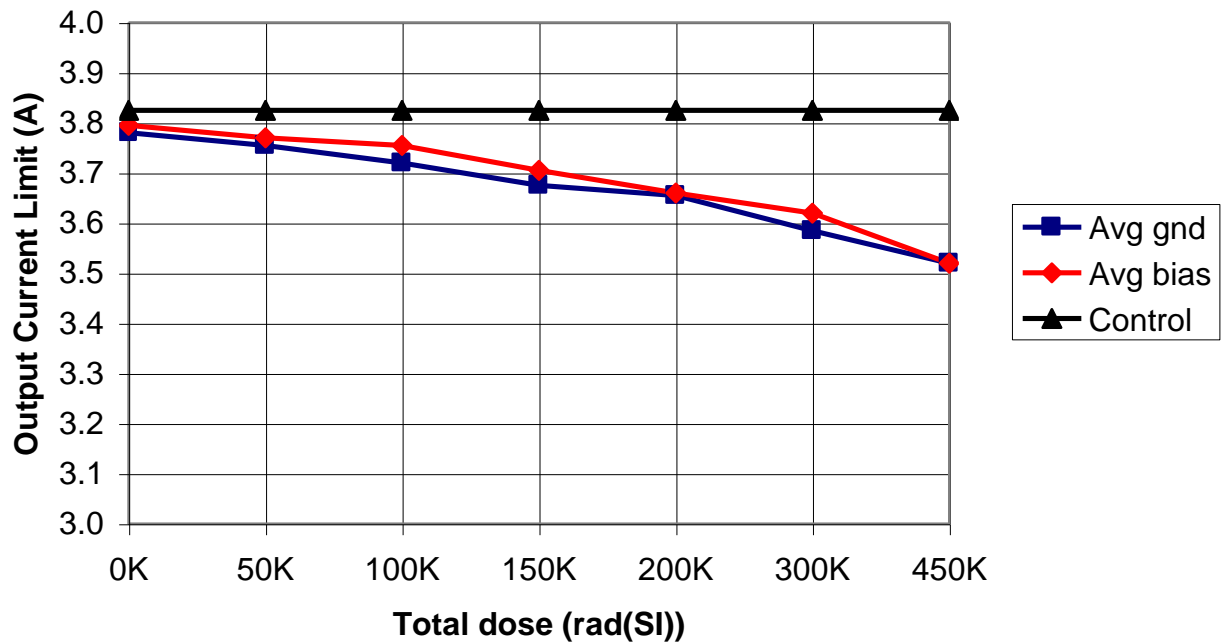
### MSK5810RH Shutdown Threshold vs. Total Dose



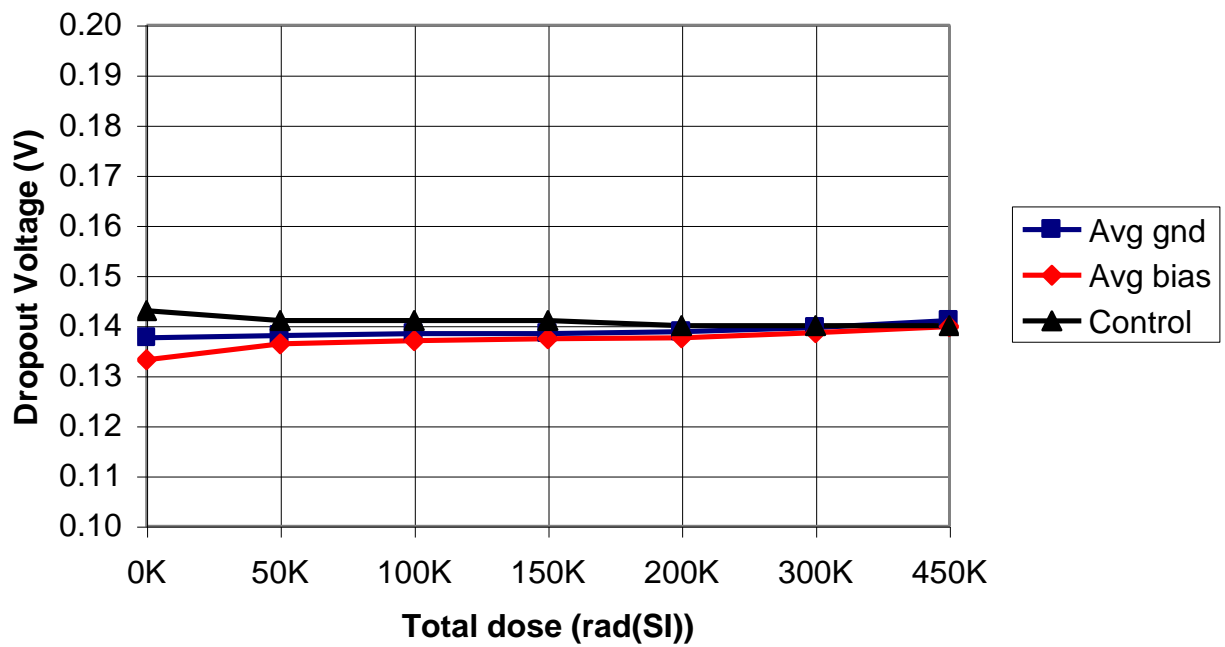
### MSK5810RH Shutdown Hysteresis vs. Total Dose



### MSK5810RH Output Current Limit vs. Total Dose



### MSK5810RH Dropout Voltage vs. Total Dose





**Total Dose Radiation Test Report**

**MSK 5822 RH**

**RAD Hard Ultra Low Dropout  
Adjustable Positive Linear Regulator**

March 21, 2009

J. Douglas  
P. Musil

M.S. Kennedy Corporation  
Liverpool, NY

**I. Introduction:**

The total dose radiation test plan for the MSK 5822 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5822 RH.

**II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 179 Rads(Si)/sec. The total dose schedule can be found in Table I.

**III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were kept under bias during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

**IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

**V. Summary:**

Based on the test data recorded during radiation testing, the MSK5822RH qualified as a 300 KRAD (Si) radiation hardened device. Output Voltage, Output Current Limit and Drop Out Voltage exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID.

MSK 5822RH Biased/Unbiased Dose Rate Schedule
--------------------------------------------------

Dosimetry Equipment
---------------------

Bruker Biospin # 0141
-----------------------

Irradiation Date
------------------

03/17/09
----------

Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
4:48	51,552	51,552
4:48	51,552	103,104
4:48	51,552	154,656
4:48	51,552	206,208
9:36	103,104	309,312
14:22	154,298	463,610

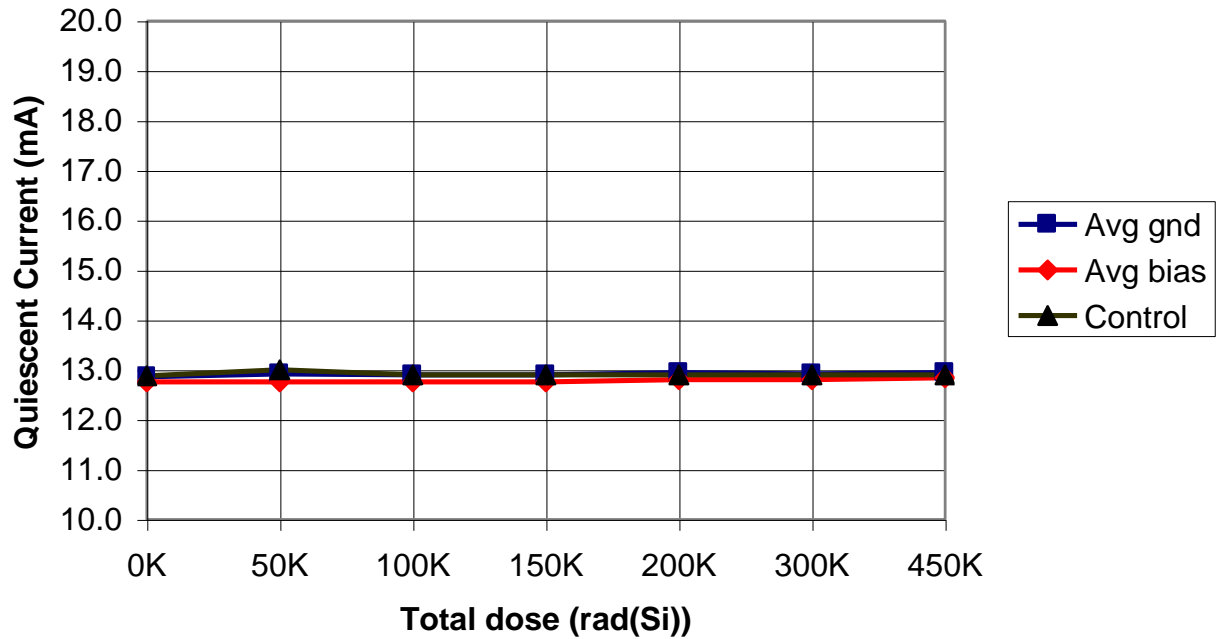
Biased S/N – 5874,5875,5876,5877,5878
---------------------------------------

Unbiased S/N – 5879,5880,5881,5883,5885
-----------------------------------------

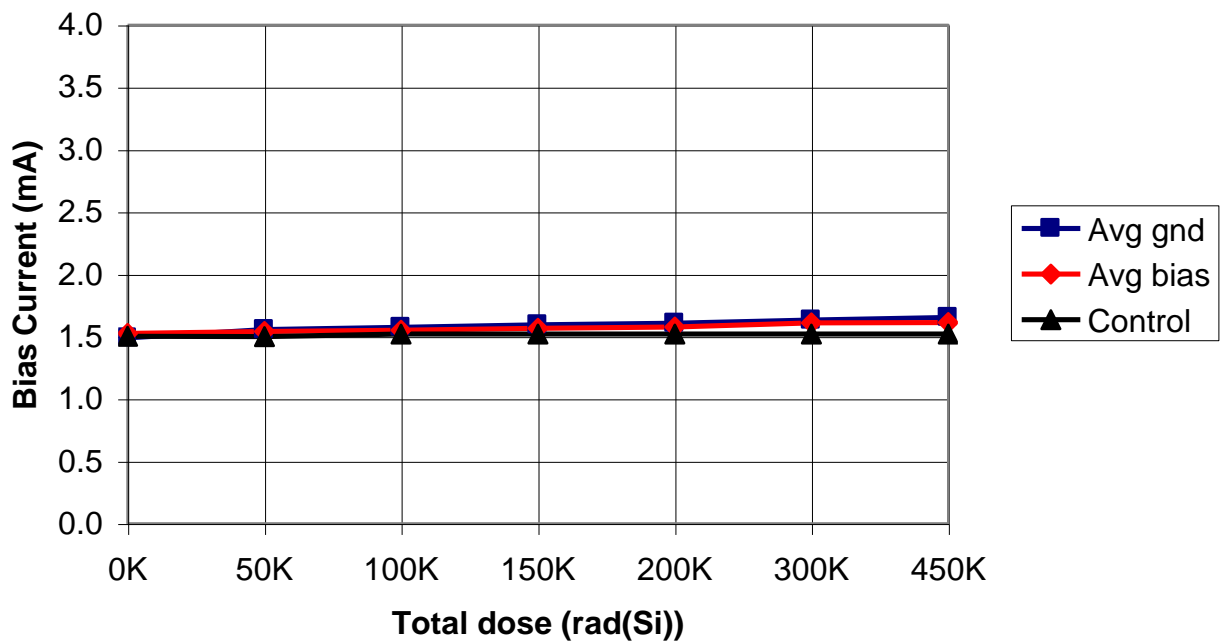
Table 1

**Dose Time, Incremental Dose and Total Cumulative Dose**

### MSK5822RH Quiescent Current vs. Total Dose

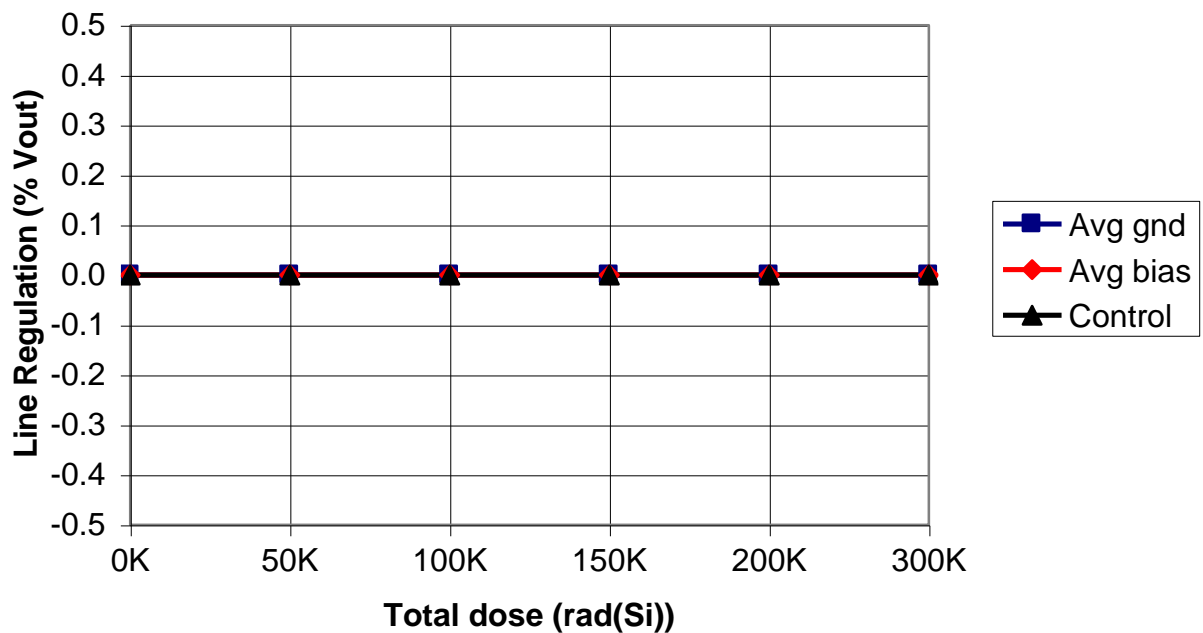


### MSK5822RH Bias Current vs. Total Dose



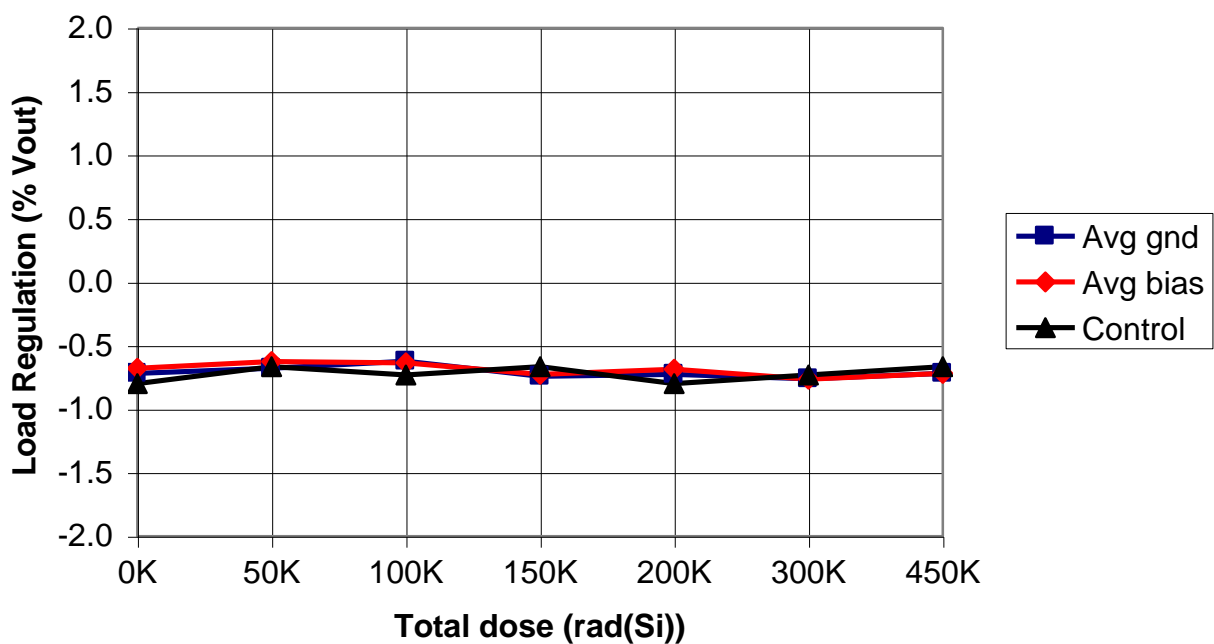
### MSK5822RH

#### Line Regulation vs. Total Dose



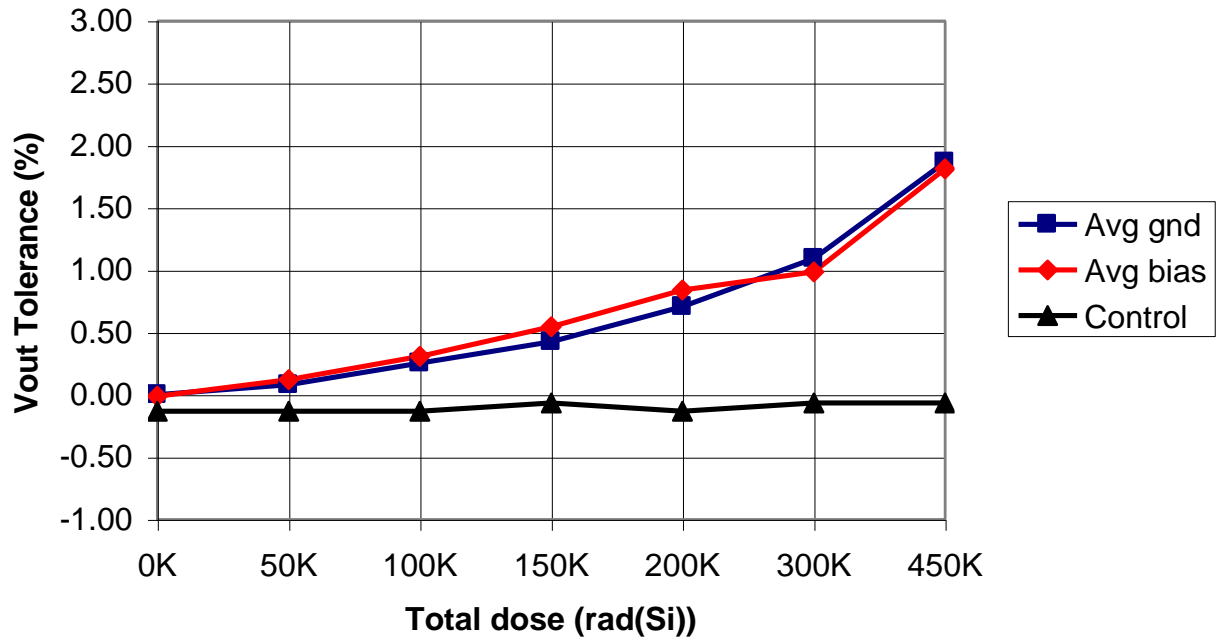
### MSK5822RH

#### Load Regulation vs. Total Dose



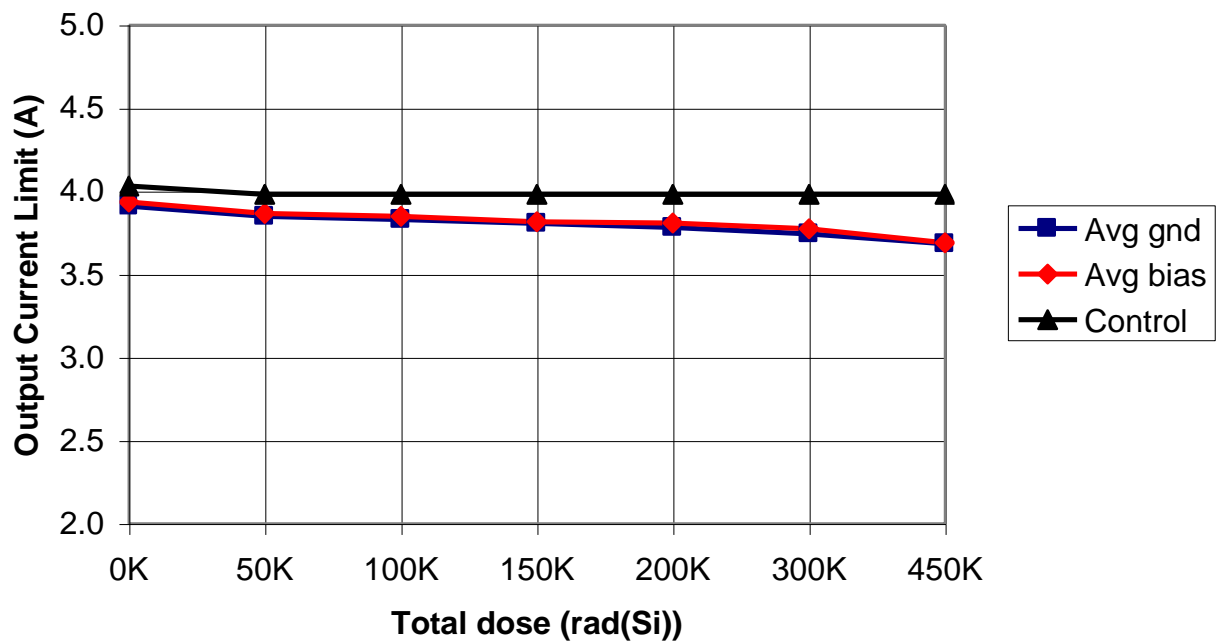
### MSK5822RH

#### Output Voltage Tolerance vs. Total Dose

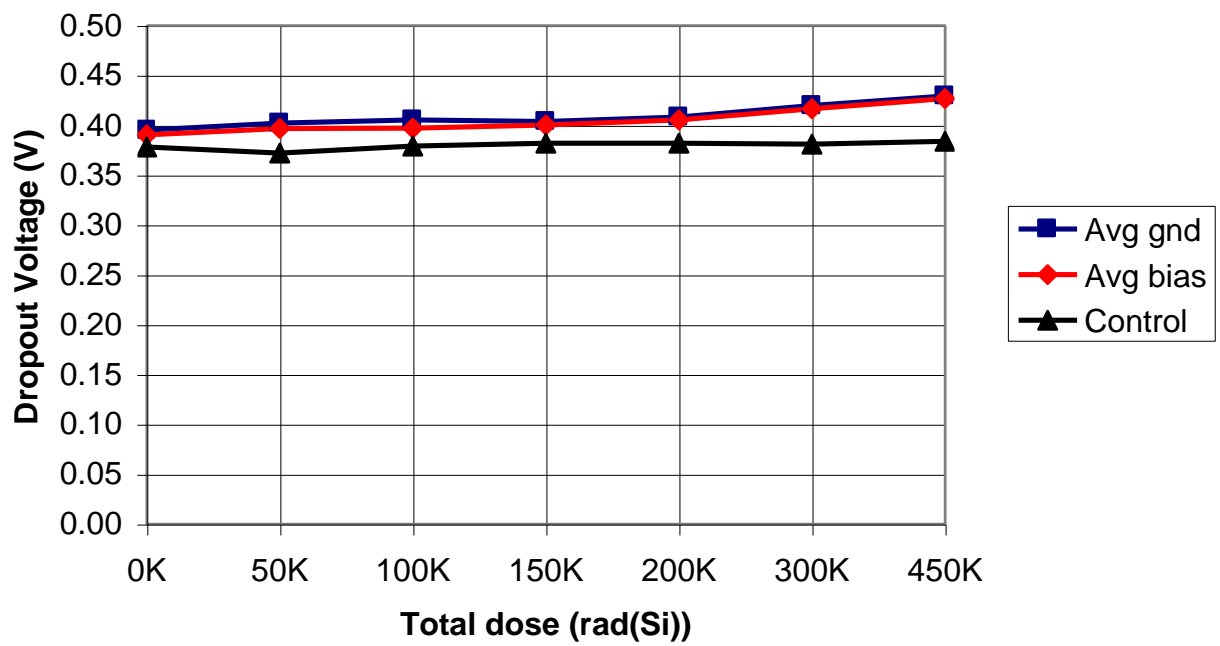


### MSK5822RH

#### Output Current Limit vs. Total Dose



### MSK5822RH Dropout Voltage vs. Total Dose



## **Total Dose Radiation Test Report**

**MSK 5810 RH**  
**(MSK5800RH, MSK5820RH, MSK5821RH, MSK5822RH)**  
**RAD Hard Ultra Low Dropout**  
**Adjustable Positive Linear Regulator**

November 25, 2008 (First Test)  
Updated on December 24, 2008  
March 26, 2009 (Second Test)

M. Bilecki  
P. Musil

M.S. Kennedy Corporation  
Liverpool, NY



## **I. Introduction:**

The total dose radiation test plan for the MSK 5810 RH series was developed to qualify the devices as RAD Hard to 300 KRAD (Si). The testing was performed beyond 300 KRAD (Si) to show trends in device performance as a function of total dose. The test does not classify maximum radiation tolerance of the device, but simply offers designers insight to the critical parameter-shifts up to the specified total dose level. The MSK5810RH, MSK5820RH, MSK5821RH, MSK5822RH, and the MSK5800RH all use the same active components. The data in this report is from direct measurement of the MSK5810RH response to irradiation but it is indicative of the response of all five device types and is applicable to all five types.

MIL-STD-883 Method 1019.7 and ASTM F1892-06 were used as guidelines in the development and implementation of the total dose test plan for the MSK 5810RH.

## **II. Radiation Source:**

Total dose was performed at the University of Massachusetts, Lowell, using a cobalt 60 radiation source. The dose rate was determined to be 184 Rads(Si)/sec. The total dose schedule can be found in Table I.

## **III. Test Setup:**

All test samples were subjected to Group A Electrical Test at 25°C in accordance with the device data sheet. In addition, all devices received 320 hours of burn-in per MIL-STD-883 Method 1015. For test platform verification, one control device was tested at 25°C. Ten devices were then tested at 25°C, prior to irradiation, and were found to be within acceptable test limits.

The devices were vertically aligned with the radiation source and enclosed in a lead/aluminum container during irradiation. Five devices were kept under bias during irradiation. Maximum recommended operating voltage of +7.5V was used for the bias condition. Five devices had all leads grounded during irradiation for the unbiased condition.

After each irradiation the device leads were shorted together and transported to the MSK automatic electrical test platform and tested IAW MSK device data sheet. Testing was performed on irradiated devices, as well as the control device, at each total dose level. Electrical tests were completed within one hour of irradiation. Devices were subjected to subsequent radiation doses within two hours of removal from the radiation field.

## **IV. Data:**

All performance curves are averaged from the test results of the biased and unbiased devices, respectively. If required, full test data can be obtained by contacting M.S. Kennedy Corporation.

## **V. Summary:**

Based on the test data recorded during radiation testing and statistical analysis, the MSK5810RH qualified as a 300 KRAD (Si) radiation hardened device. Feedback Voltage, Shutdown Threshold, and Output Current Limit exhibited the most significant shift due to irradiation, however all performance curves stayed within specification up to 450 KRAD (Si) TID.

MSK 5810RH Biased/Unbiased Dose Rate Schedule
--------------------------------------------------

Dosimetry Equipment
Bruker Biospin # 0141

Irradiation Date
03/17/09

Exposure Length (min:sec)	Incremental Dose rads(Si)	Cumulative Dose rads(Si)
4:40	51,520	51,520
4:40	51,520	103,040
4:40	51,520	154,560
4:40	51,520	206,080
9:20	103,040	309,120
14:00	154,560	463,680

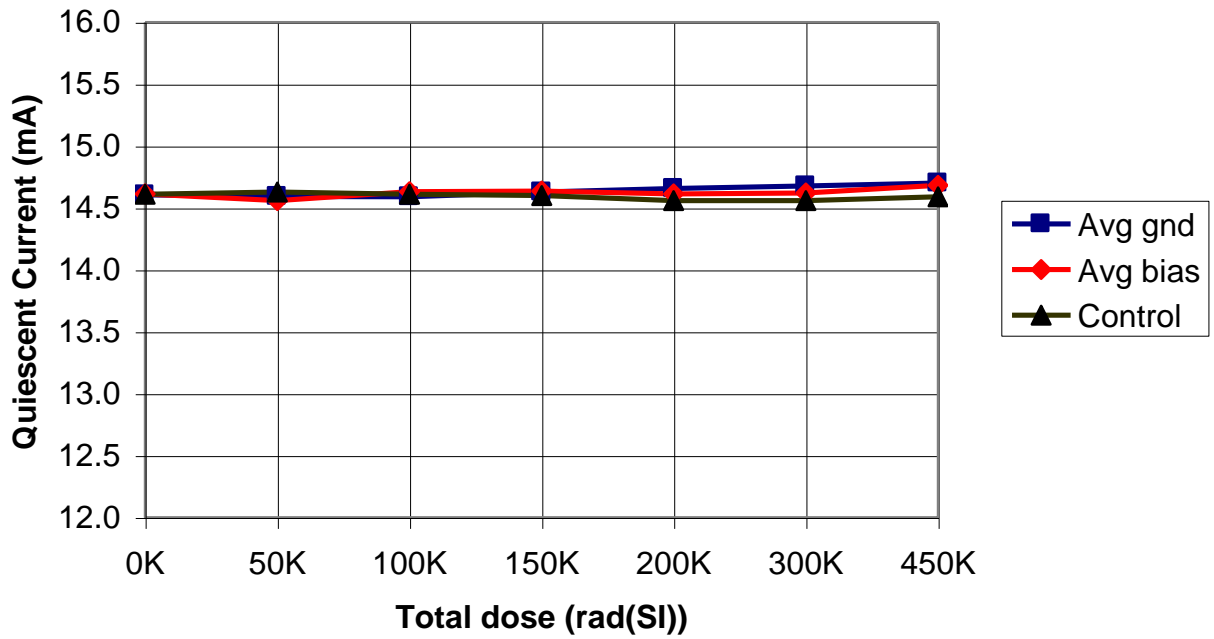
Biased S/N – 0054, 0055, 0056, 0057, 0058
-------------------------------------------

Unbiased S/N – 0059, 0060, 0061, 0062, 0063
---------------------------------------------

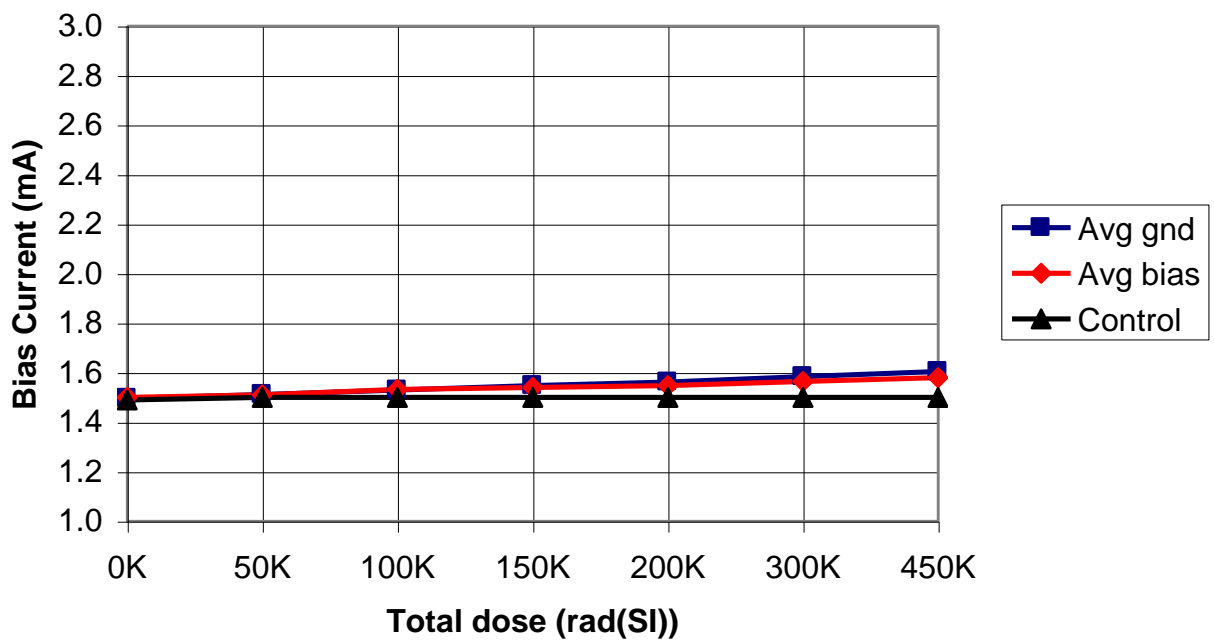
Table 1

**Dose Time, Incremental Dose and Total Cumulative Dose**

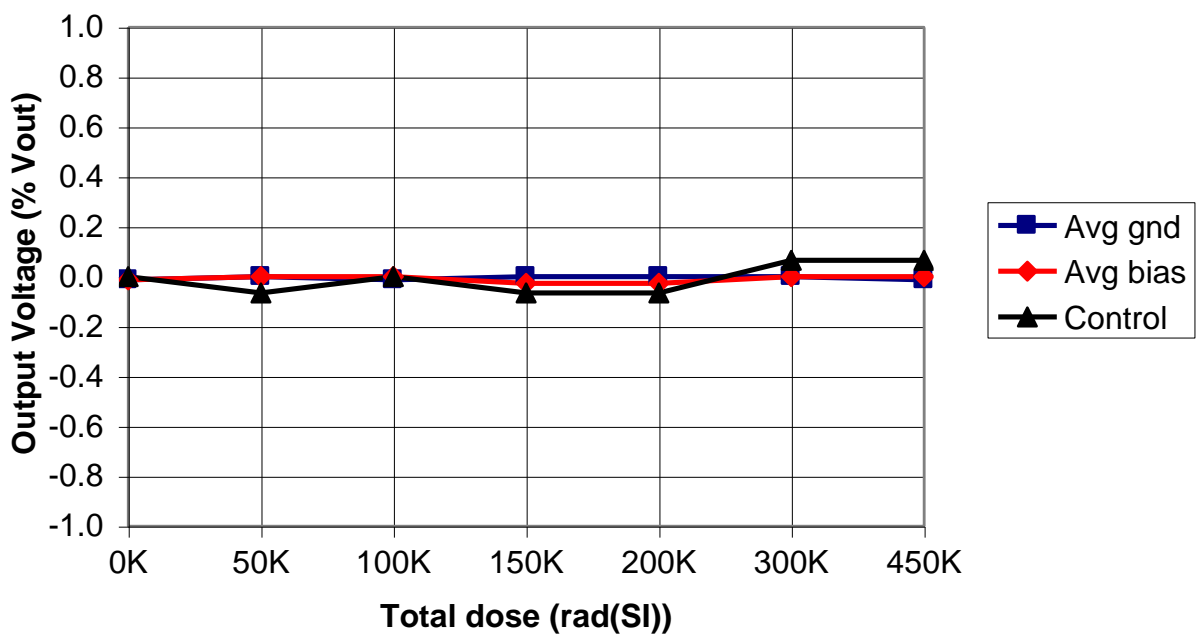
### MSK5810RH Quiescent Current vs. Total Dose



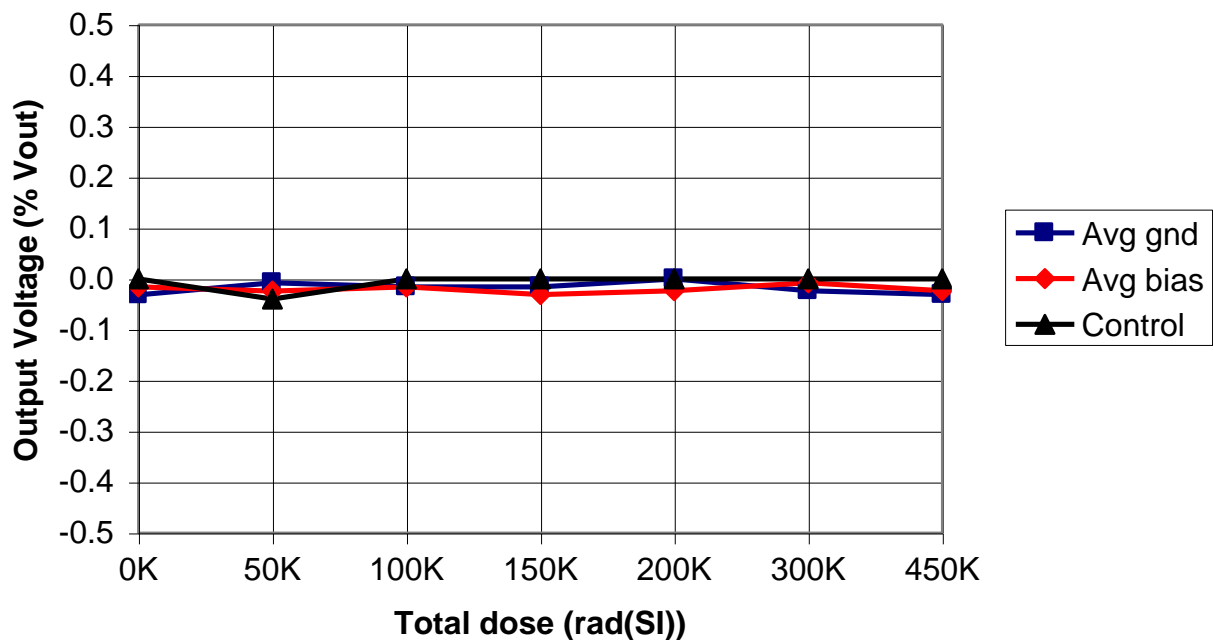
### MSK5810RH Bias Current vs. Total Dose

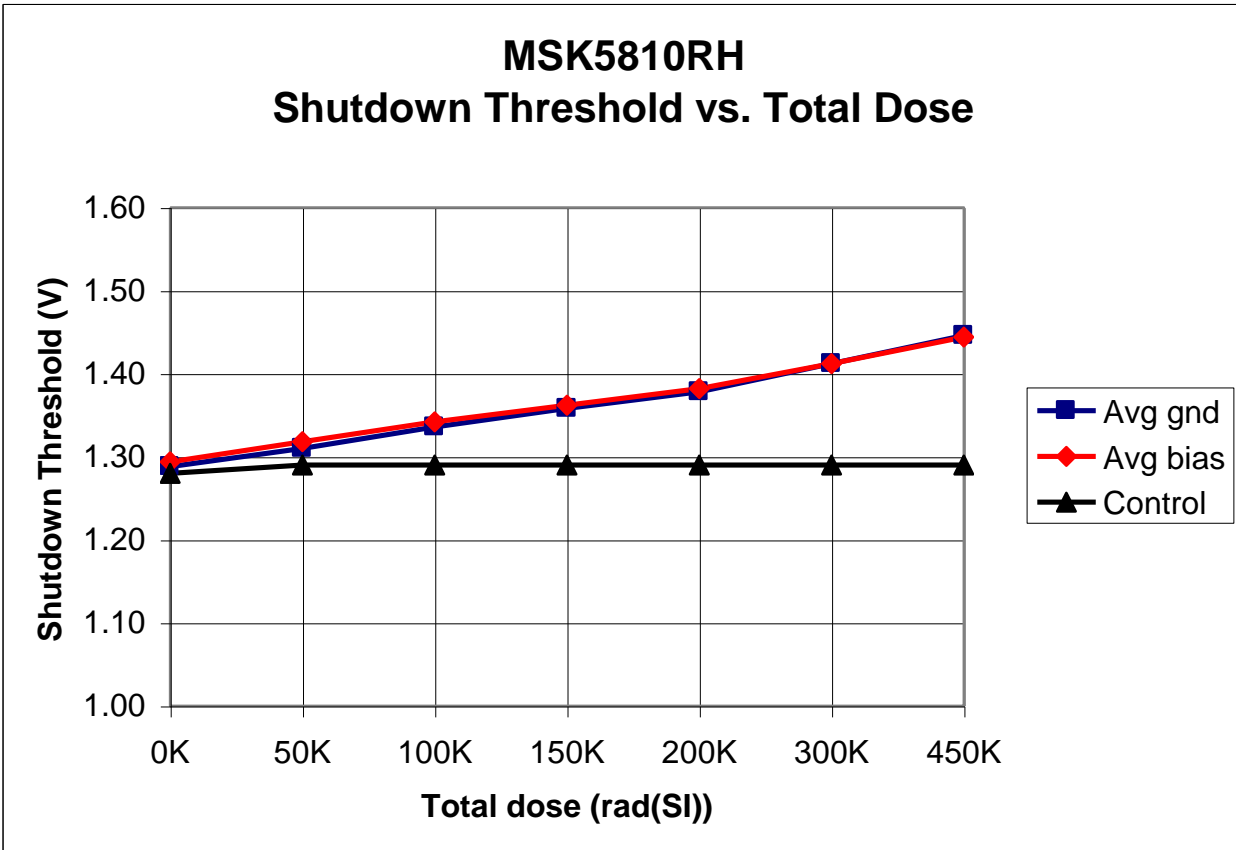
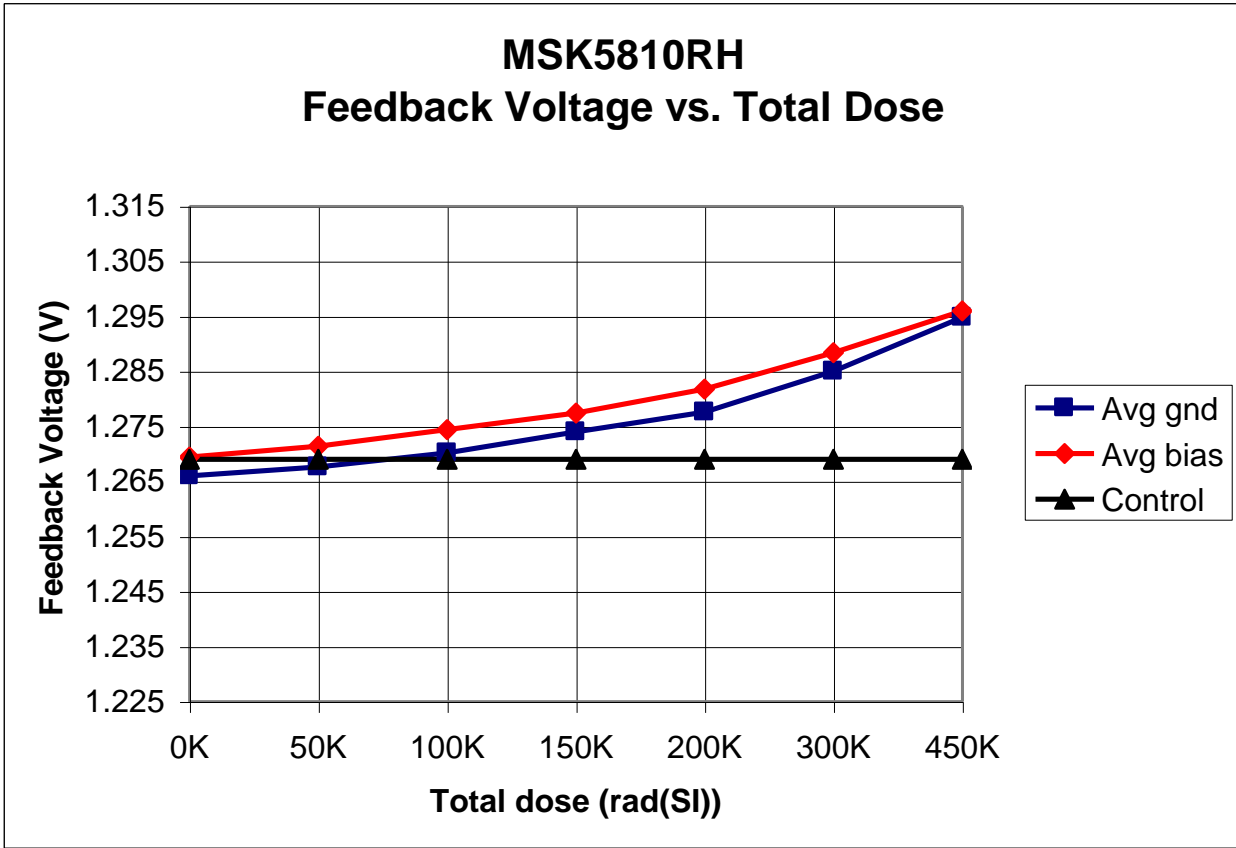


### MSK5810RH Line Regulation vs. Total Dose

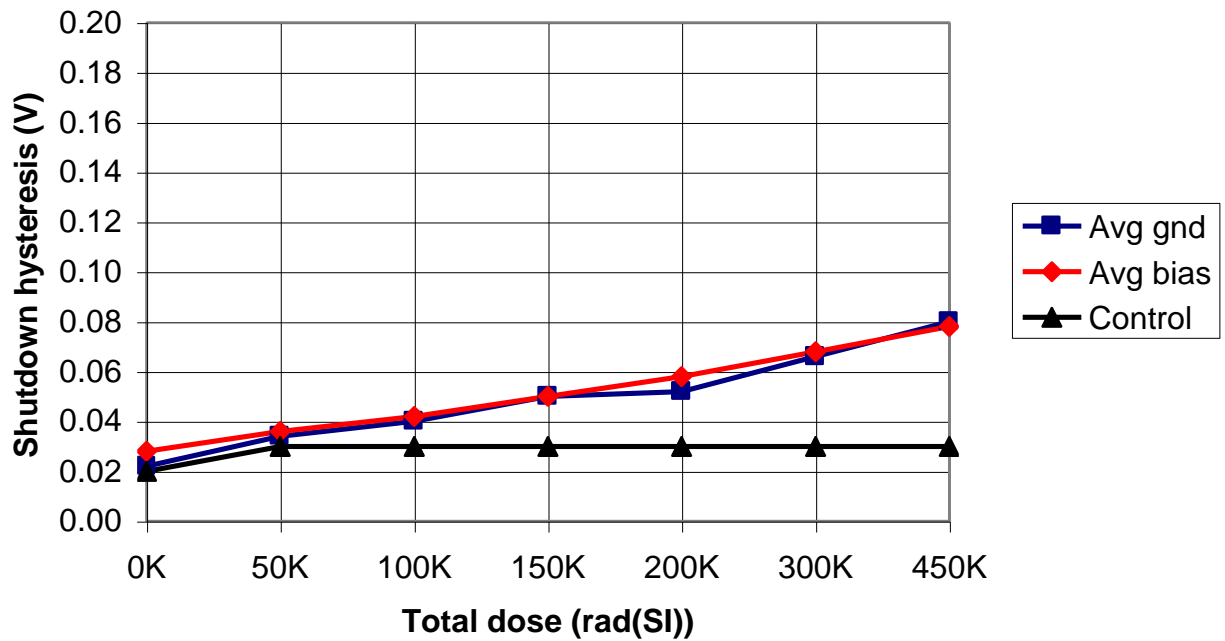


### MSK5810RH Load Regulation vs. Total Dose

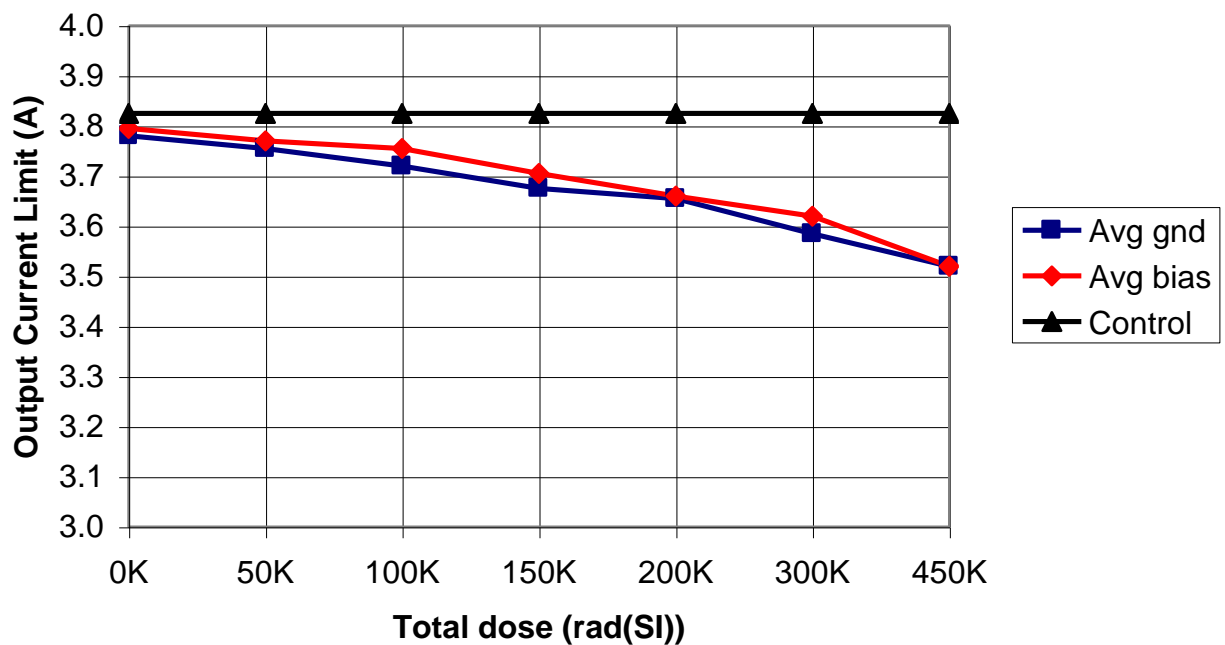




### MSK5810RH Shutdown Hysteresis vs. Total Dose



### MSK5810RH Output Current Limit vs. Total Dose



# MSK5810RH

## Dropout Voltage vs. Total Dose

